

R
302134

JPRS-CST-85-029

3 September 1985

China Report

SCIENCE AND TECHNOLOGY

DTIC QUALITY INSPECTED 4

19990426 059

FBIS FOREIGN BROADCAST INFORMATION SERVICE

REPRODUCED BY
NATIONAL TECHNICAL
INFORMATION SERVICE
U.S. DEPARTMENT OF COMMERCE
SPRINGFIELD, VA. 22161

2
171
A08

NOTE

JPRS publications contain information primarily from foreign newspapers, periodicals and books, but also from news agency transmissions and broadcasts. Materials from foreign-language sources are translated; those from English-language sources are transcribed or reprinted, with the original phrasing and other characteristics retained.

Headlines, editorial reports, and material enclosed in brackets [] are supplied by JPRS. Processing indicators such as [Text] or [Excerpt] in the first line of each item, or following the last line of a brief, indicate how the original information was processed. Where no processing indicator is given, the information was summarized or extracted.

Unfamiliar names rendered phonetically or transliterated are enclosed in parentheses. Words or names preceded by a question mark and enclosed in parentheses were not clear in the original but have been supplied as appropriate in context. Other unattributed parenthetical notes within the body of an item originate with the source. Times within items are as given by source.

The contents of this publication in no way represent the policies, views or attitudes of the U.S. Government.

PROCUREMENT OF PUBLICATIONS

JPRS publications may be ordered from the National Technical Information Service, Springfield, Virginia 22161. In ordering, it is recommended that the JPRS number, title, date and author, if applicable, of publication be cited.

Current JPRS publications are announced in Government Reports Announcements issued semi-monthly by the National Technical Information Service, and are listed in the Monthly Catalog of U.S. Government Publications issued by the Superintendent of Documents, U.S. Government Printing Office, Washington, D.C. 20402.

Correspondence pertaining to matters other than procurement may be addressed to Joint Publications Research Service, 1000 North Glebe Road, Arlington, Virginia 22201.

7

3 September 1985

CHINA REPORT SCIENCE AND TECHNOLOGY

CONTENTS

PEOPLE'S REPUBLIC OF CHINA

APPLIED SCIENCES

- Progress of Inertial Confinement Research Detailed
(Wang Ganchang; HE KEXUE YU GONGCHENG, No 4, Dec 84)..... 1
- On-Line Software Development System for TRS-80(I)/EG3200
(Li Benren, et al.; XIAOXING WEIXING JISUANJI XITONG,
No 1, 8 Jan 85)..... 18
- High-Speed General-Purpose EPROM Programmer
(Li Benren, et al.; XIAOXING WEIXING JISUANJI XITONG,
No 1, 8 Jan 85)..... 21
- Programmer for Single-Chip Microprocessor
(Li Benren, et al.; XIAOXING WEIXING JISUANJI XITONG,
No 1, 8 Jan 85)..... 29
- Digital Voltmeter Technology Acquisition
(Chen Qilin, Cui Jianping; GUOJI MAOYI, No 3, 1985)..... 41
- Suggestions for Further Applications of HFETR in China
(Zhang Zhaoyuan; HE DONGLI GONGCHENG, No 2, Apr 85)..... 45
- Wingtip Sails Tested on Y-5 Aircraft
(Yang Daxi; GUOJI HANGKONG, No 5, May 85)..... 49

LIFE SCIENCES

- Trends in Pharmacology Discussed
(Zhou Jinhuang; YAOXUE XUEBAO, No 2, 29 Feb 85)..... 54

Briefs

More Drug Inspectors Urged

61

PUBLICATIONS

Titles of Selected Papers From the Sixth National Conference on
Infrared Science and Technology

(HONGWAI YANJIU, No 2, Apr 85..... 62

ABSTRACTS

CHEMISTRY

YINGYONG HUAXUE [CHINESE JOURNAL OF APPLIED CHEMISTRY] No 4,
Sep 84..... 69

FENXI HUAXUE [ANALYTICAL CHEMISTRY] No 10, 20 Oct 84 74

FENXI HUAXUE [ANALYTICAL CHEMISTRY] No 12, 20 Dec 84..... 84

HE HUAXUE YU FANGSHE HUAXUE [JOURNAL OF NUCLEAR AND RADIO-
CHEMISTRY] No 2, May 85..... 89

COMPUTER APPLICATIONS

SHUZHJ JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL
METHODS AND COMPUTER APPLICATIONS] No 2, Jun 85..... 93

CRYOGENICS

DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] No 4,
Dec 84..... 97

ELECTRONICS

HANGZHOU DAXUE XUEBAO (ZIRAN KEXUE BAN) [JOURNAL OF HANGZHOU
UNIVERSITY (NATURAL SCIENCES EDITION)] No 3, Jul 84..... 109

ENGINEERING

ZHENKONG KEXUE YU JISHU [VACUUM SCIENCE AND TECHNOLOGY] No 5,
Sep 84..... 110

HUAGONG XUEBAO [JOURNAL OF CHEMICAL INDUSTRY AND ENGINEERING
(CHINA)] No 1, Mar 85)..... 115

LASERS

ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] No 6, 20 Jun 85..... 119

METEOROLOGY

- HANGZHOU DAXUE XUEBAO (ZIRAN KEXUE BAN) [JOURNAL OF HANGZHOU
UNIVERSITY (NATURAL SCIENCES EDITION)] No 3, Jul 84..... 124

NUMERICAL METHODS

- SHUZHJ JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL
METHODS AND COMPUTER APPLICATIONS] No 2, Jun 85..... 125

OPTICS

- ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] No 6, 20 Jun 85).... 127

PHYSICS

- GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA
NUCLEARIS] No 3, May 85..... 128

- WULI XUEBAO [ACTA PHYSICA SINICA] No 5, May 85..... 135

- ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] No 6, 20 Jun 85.... 143

- WULI XUEBAO [ACTA PHYSICA SINICA] No 6, Jun 85..... 144

- WULI XUEBAO [ACTA PHYSICA SINICA] No 7, Jul 85..... 147

RADIATION PROTECTION

- FUSHE FANGHU [RADIATION PROTECTION] No 3, 1985..... 152

SEMICONDUCTORS

- BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS] No 3,
May 85..... 155

APPLIED SCIENCES

PROGRESS OF INERTIAL CONFINEMENT RESEARCH DETAILED

Beijing HE KEXUE YU GONGCHENG [CHINESE JOURNAL OF NUCLEAR SCIENCE AND ENGINEERING] in Chinese Vol 4 No 4, Dec 84 pp 289-302

[Article by Wang Ganchang [3769 3227 2490] of the Institute of Atomic Energy; manuscript received 31 Aug 84]

[Text] Abstract

In this article we briefly describe the recent progress of inertial confinement fusion (ICF) research. Four topics considered to be the most important at the present time are selected for discussion. These are the "cannonball" target, the high power krypton fluoride (KrF) laser, the ion beam diode, and the imploding foil plasma.

The principle of the cannonball target and its advantages over ordinary ablation targets are given. It is particularly significant that Japanese researchers have obtained the highest neutron yield to date (4×10^{10} per pulse) using cannonball targets. The important problem of hole sealing of cannonball targets is also discussed.

The powerful KrF excimer lasers pumped by electron beams are discussed next. This type of laser is now generally regarded as one of the more promising drivers for ICF. Here we briefly describe the complex kinetics of pumping, quenching, radiation, and absorption of this very interesting laser. A compression of the KrF laser pulse length from about 100 nanoseconds to a few nanoseconds is required for ICF work. We describe three of the compression methods, namely, pulse splitting and stacking, Raman back-scattering, and a combination of the two.

For the third topic we discuss the present status of ion beam production, especially the diodes which produce the ion beams. Three types of diodes are discussed: the pinch reflex diode (PRD), the diode with an externally applied magnetic field, and the hybrid amphion diode. New results of the Reiden-IV studied by the Institute of Laser Engineering, Osaka and by Etigol in Nagaoka Technical University, Nagaoka are also reported.

Finally we discuss the imploding foil plasma. This technique produces plasmas of very high temperature and very intense soft X-rays which may either be used to produce an X-ray laser or as a new driver for ICF.

I. The Cannonball Target

The short-term goal of inertial confinement is ignition. Ignition is the spontaneous burning of the deuterium and tritium gas mixture in the target (not necessarily a sphere) when the gas reaches a sufficient density under the compression action of the driver which may be laser beams, particle beams or other beams. The key is the most efficient absorption of the driving energy and the maximum compression. In the common ablation compression scheme, the inward compression is produced by the reaction of the outward ablation of the high temperature plasma from the target surface caused by the driving beam. Obviously the energy utilization rate of this type of compression is relatively poor and part of the incident energy will be reflected back. A scheme based on the hohlraum principle was therefore proposed to improve the utilization rate of the incident light energy. The working principle is illustrated in Figure 1.

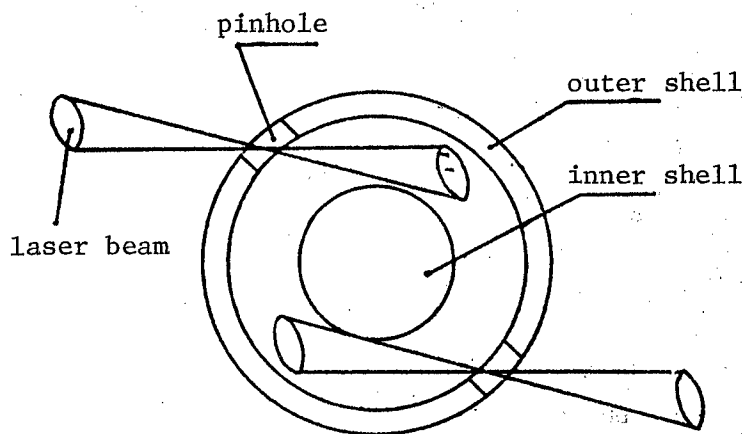


Fig. 1 The Hohlraum Target

In Figure 1, the diameter of the outer shell is 400-500 μm , the walls thickness is 4-6 μm , and the diameter of the pinhole is 40-100 μm . The incident laser is focused on the pinhole with lenses and almost all the light enters the target and is eventually absorbed. It has been said that the Japanese first proposed this type of target³ but it has also been claimed that the Americans conducted such experiments in the early 1970's as unpublished classified research. In any case, the Institute of Laser Engineering (ILE) of Osaka University, led by Professor Chiyoie Yamanaka, achieved the highest neutron yield of 4×10^{10} per pulse in laser inertial confinement using the hohlraum target (the Japanese call it the cannonball target) in late 1983. What allowed the Japanese to achieve the highest neutron yield in the world was their novel target design and the large laser energy and power available to them. The Japanese laser facility is given the name Gekko XII, which is the largest laser of ILE and also the largest in the world at the present time. The Gekko XII facility was completed at the end of 1983, and is being continuously improved and upgraded.

Table 1 shows all the lasers at ILE currently under operation. It shows that the Japanese are engaged in various basic research experiments in addition to target shooting with high-power lasers. They are part of the "King Kong Project" whose goal is the breakeven of the inertial confinement fusion. They expect to achieve this goal in 1987 with a total laser energy of 100 kJ, possibly from an upgraded Gekko XII.

Table 1. Lasers at the Institute of Laser Engineering

System	Material	Wavelength (μ m)	Beam number	Total energy (kJ)
Gekko II	Glass	0.355	2	0.3
Gekko IIM	Glass	1.05	2	1.6
Gekko IV	Glass	0.526	4	0.6
Gekko XII	Glass	1.05	12	20.0
Lekko II	CO ₂	10.6	2	1
Lekko VIII	CO ₂	10.6	8	10

We shall now elaborate on the hohlraum target.

1. Principle of the hohlraum target

The ball of the hohlraum target (referred to by the Japanese as the cannonball target) is the inner sphere containing the DT mixture. It works as follows⁴: when the laser passes through the pinhole, it is first absorbed by the inner surface of the outer shell and high temperature plasma and X-rays are produced and the space between the outer shell and the inner sphere is filled with plasma. The plasma becomes shock waves and reflection waves bounding between the two surfaces, which continuously compresses the inner sphere and raises its temperature. This is quite different from the previous ablative method.^{1,2} The hohlraum method is like a cannon and the ablation method is like a rocket. The former has a high efficiency and the latter has a low efficiency.

In addition to the efficient utilization of the laser energy, the cannonball target has another advantage, the surface finish and the uniformity requirements of the inner sphere are not as stringent as that of the ablative target. In the cannonball target, the X-ray and plasma shock waves produced by the laser undergo multiple reflections between the two surfaces of the cavity and result in very uniform compression. For the ablative target the compression is driven directly by the laser beams and can easily be nonuniform.

2. In the cannonball target (see Figure 1), the properties of the X-ray and plasma produced by the laser are determined by the properties of the inner surface of the outer shell. If the inner surface is made of a light material such as plastic or beryllium, the product is mainly a hot plasma converging toward the center of the target. If the inner surface is made of a heavy

material such as gold or tungsten, a great amount of soft X-rays (with an energy less than 1 keV) and plasma will be produced. The X-rays make multiple bounces in the cavity and homogenizes the space, thereby creating highly favorable conditions for centripetal compression. This is a very important effect and the final success of laser inertial confinement may rely on it.

The compression and heating of the inner sphere can also be enhanced by surrounding it with a light metallic foam. The foam may serve as new hot points for producing X-rays and greatly increase the X-ray intensity in the cavity and hence the compression.

3. The Institute of Laser Engineering of Osaka University is currently conducting a number of basic research on the energy injection coefficient η_E of the hohlraum target, the X-ray conversion coefficient η_x , the pinhole closing time t_c , and the cavity absorption coefficient η_a . The work on hole sealing and closing time t_c is particularly significant and may influence the success of the hohlraum target experiment. The magnitude of t_c depends on the size of the hole, the target material, the wall thickness of the outer shell and the width of the laser pulse. The relationship must be understood before any formal experiment can be done. Researchers at Osaka University have bombarded targets with 0.1-1.0 ns laser pulses. Using the HIMICO code, they have computed the energy injection rate $\eta_e = \frac{E_{LC}}{E_{LT}}$, where E_{LC} is the laser energy entering the

empty cavity and E_{LT} is the total incident laser energy. As a matter of fact, they have studied the transmissivity or injection rate of a 100 μm hole and found t_c to be generally in the 400-500 ps range. Pulses of 2-3 ns duration are evidently too long and a good deal of energy cannot enter the hole.⁵ These are, however, only preliminary results and more detailed results are expected.

4. One study that deserves our attention and continued research effort is the cannonball experiment using the Lekko VIII CO₂ laser conducted by Professor Sadao Nakai at the Institute of Laser Engineering. He found that a CO₂ laser at a wavelength of 10.6 μm also did very well on the cannonball target without the troublesome super-heated electrons produced by the ablative target. They found that the X-ray temperature produced by the laser energy in the target cavity may reach 30 keV. They are currently continuing the study of this very interesting problem.

Overall, the application of the cannonball target is indeed a promising new development in the research of laser fusion. No wonder people felt that although laser fusion has encountered some difficulties recently, the fabrication of the new cannonball target and some new theoretical interpretation have raised hope of success in laser fusion.⁶

II. KrF* Laser and Its Applications

2.1 General description of the KrF laser

Up to now lasers used in inertial confinement fusion are mostly neodymium glass lasers and only a few CO₂ gas lasers. The glass lasers are solid state lasers with a low efficiency (about 0.1 percent), the thermal conductivity is low,

the wavelength of $1.06 \mu\text{m}$ is somewhat too large and the cost is high. The CO_2 gas lasers have a higher efficiency (may reach 30 percent) but the wavelength of $10.6 \mu\text{m}$ is too large. Neither one is ideal as a driver for inertial confinement. Efforts are made to find a more suitable laser for inertial confinement and the most promising laser to date is the KrF^* laser. It is one of the excimer lasers and has a wavelength of $0.248 \mu\text{m}$. Of the excimer lasers, the KrF^* laser has the highest optical efficiency, its overall efficiency is close to 5 percent and it is more suitable for inertial confinement because it is a gas laser and has a high repetition rate.

There are two major excitation methods in the KrF^* laser: rapid discharge excitation and pulsed electron beam excitation. When the desired laser power is not great, rapid discharge pumping may be used. KrF^* lasers used in inertial confinement fusion are pumped with a pulsed electron beam. Figure 2 shows schematically the transverse pumping method,^{1,2} the most commonly used method for producing pulsed electron beams. The electron beam produced by such a device is often pinched by its own magnetic field. An externally applied axial magnetic field may be used to produce a more uniform electron beam distribution in a certain range. The electron energy is generally in the 200–2000 keV range.

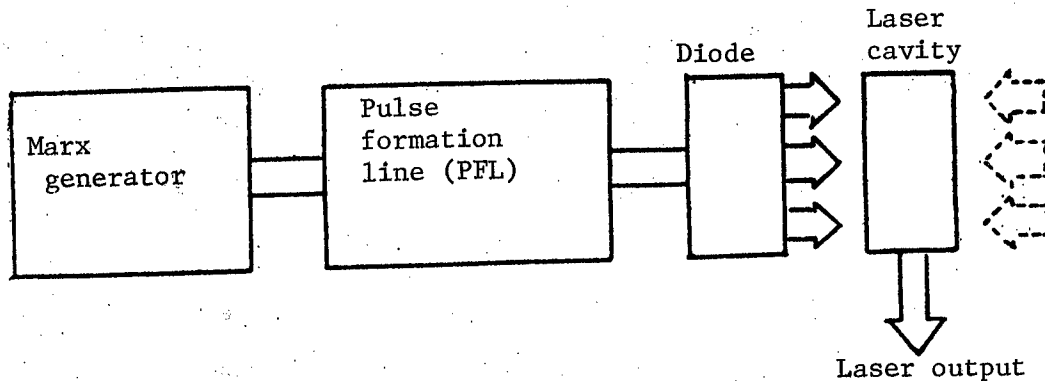


Fig. 2 Schematic Diagram Showing the Transverse Pumping by a Pulsed Electron Beam

The electron beams may be injected from the left side and from the right side to give a more uniform absorption of the electrons in the gas cell (also the laser cavity). The electron current density should be in the $50\text{--}200 \text{ A/cm}^2$ range. The composition of the gas in the cell (cavity) is $\text{Ar:Kr:F} = 1000:100:4$. The total pressure is between 1 and 3 atmospheres. The container must have a thin film window made of Ti, Al or stainless steel so that the electron beam may penetrate the wall without suffering a great loss in energy.

2.2 Experimental research of KrF^* lasers

When KrF^* lasers first came out in 1976 their pulse energy was in the 100 mJ range, but there have been rapid developments in recent years. In 1983 the "Sprite" laser built by the Rutherford Institute in the United Kingdom had an output pulse energy of 200 J and a pulse width of 40 ns. In June 1983 a new

excimer KrF* laser at Los Alamos began running at a pulse width of 500 ns and an output energy of 20 kJ. Although its pulse width is too large for laser fusion work, its development time was only 15 months at a cost of only \$US1 million.⁷ Today, 50 kJ KrF* lasers are said to be in the design stage.

2.3 Kinetic process of the KrF* laser

The strong current electron beam ionizes and excited the atoms and molecules in a gas mixture of Ar, Kr, and F₂. The interaction of the ionized and excited particles produces the KrF* excimer and under certain conditions emits a laser light via resonance.

In order to estimate the output energy, output power, and efficiency of the laser, we must investigate the kinetics of the KrF* laser. Such processes are very complex and we shall only consider five related aspects:

1. Formation of KrF* excimers

The KrF* excimers generally do not form under low pressure. Stable diatomic ground state molecules such as KrF are difficult to form in an inert gas and halide gas mixture (such as Ar, Kr, Xe and F₂, Cl₂ systems). Therefore, excimers such as KrF* cannot be obtained from the ground state molecules by direct pumping. They must be formed from an excited atom and other atoms when radiated. To obtain the desired (AB)* excited molecule, the following reaction must be used:



This is a three-body reaction. The presence of the third body C is necessary for satisfying momentum and energy conservation. In practice the third body is usually one of the atom species in the reaction. The probability for the three body interaction is usually small and the reaction must take place under a high pressure so that atomic collisions are frequent.

At present our interest is the production of the KrF* excimer by pumping the Ar:Kr:F₂ gaseous mixture (with a partial pressure ratio of 1000:100:4) with an electron beam. There are several reaction channels, we shall discuss the two principal ones.

The first reaction is



(M may be Ar or Kr)



For reaction (1), we have

$$S_{Ar^+} = \frac{j \times n_{Ar} \times \sigma(e_f, Ar^+)}{q_e}$$

where S_{Ar} is the Ar^+ rate of generation in $1/cm^3 \cdot s$,

j is the electron beam current density A/cm^2 ,

n_{Ar} is the number density of Ar in $1/cm^3$,

q_e is the electron charge (C),

e_f is the fast electron,

e_s is the slow electron,

and $\sigma(e_f, Ar^+)$ is the cross-section (in cm^2) for producing Ar^+ in the interaction between the fast electron and the Ar atom.

For reaction (2), we have

$$S_{F^-} = K_{e_s F_2} [e_s] [F_2]$$

where S_{F^-} - is the rate of generation of F^- in $1/cm^3 \cdot s$, $[e_s]$ is the number density of slow electrons in cm^{-3} , $[F_2]$ is the number density of F_2 molecules in cm^{-3} , and $K_{e_s F_2}$ is the rate coefficient of reaction (2) in cm^3/s .

For reaction (3), we have

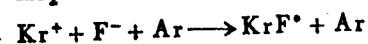
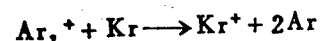
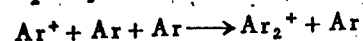
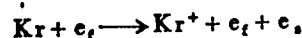
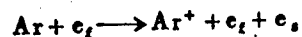
$$\frac{d[ArF^*]}{dt} = K_{Ar^+, F^-} [Ar^+] [F^-] - K_{ArF^*, Kr} [ArF^*] [Kr]$$

$$\text{and } \frac{d[Ar^+]}{dt} = S_{Ar^+} - K_{Ar^+, F^-} [Ar^+] [F^-]$$

For reaction (4), we have

$$\frac{d[KrF^*]}{dt} = K_{ArF^*, Kr} [ArF^*] [Kr]$$

The second channel of reaction is



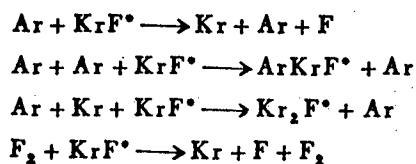
As in the above, we have

$$\begin{aligned}
 S_{Ar^+} &= \frac{j \times \eta_{Ar} \times \sigma(e_f, Ar^+)}{q_e} \\
 S_{F^-} &= K_{e, F_2}(e_f)(F_2) \\
 \frac{d[Ar_2^+]}{dt} &= K_{Ar^+, Ar^+}[Ar^+][Ar^+] - K_{Ar_2^+, Kr}[Ar_2^+][Kr] \\
 \frac{d[Kr^+]}{dt} &= S_{Kr^+} - K_{Kr^+, F^-}[Kr^+][F^-] + K_{Ar_2^+, Kr}[Ar_2^+][Kr]
 \end{aligned}$$

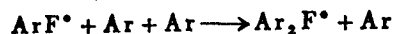
and other reactions may be neglected.

2. Quenching of KrF^* excimers

There are two principal quenching processes. Constituent molecules in the gas may collide with KrF^* excimers and cause dissociation. For example,



Since the concentration of KrF^* may reach a kinetic equilibrium, this type of quenching process is saturable. The other type of quenching is caused by the formation of intermediate species from gas molecules and KrF^* and thereby interrupts the reaction. This type of quenching has no saturation. For example



We can also write the differential equations for the reaction in a similar manner.

3. Radiation of the KrF^* excimer

The lifetime τ_{KrF^*} is very short, about 6 ns, and spontaneous radiative transition takes place quickly. The transition probability is

$$A = \frac{1}{\tau_{KrF^*}}$$

KrF^* may also undergo stimulated emission by the incident light and the cross-section is σ_{st} .

4. Absorption by the gas medium

The radiation is mainly absorbed by F^- , F_2 and Ar_2^+ and the corresponding absorption cross-sections are σ_F , σ_{F_2} , and $\sigma_{Ar_2^+}$. The number of photons per unit volume in the cavity is given by

$$\frac{d[h\nu]_{in}}{dt} = \frac{1}{C} \frac{dF}{dt} = \sigma_{KrF^*} I(KrF^*) + \frac{1}{\tau_{KrF^*}} (KrF^*) - \sigma_F I(F^-) - \sigma_{F_2} I(F_2) - \sigma_{Ar_2^+} I(Ar_2^+)$$

where $[h\nu]_{in}$ is the number of photons per unit volume, and I is the number of photons passing through a unit area in a unit time along the normal direction of the mirror in the cavity.

5. Laser output from the cavity

It is well known that an initial laser intensity I_0 in the cavity becomes $I = I_0 e^{\gamma_0 L}$ after a length L . From the derivation above, we have

$$\frac{d[h\nu]_{in}}{dt} = \gamma_0 L$$

where γ_0 is the net gain of the laser after absorptive losses. It can be

shown that when $\gamma_0 = -\frac{\ln T^2 R}{2L}$ the laser is operating at the threshold and

begins to have a gain. Here $T = t_1 t_2$ is the product of the transmissivity of the two windows and $R = r_1 r_2$ is the product of the reflectivity of the two cavity mirrors. The total output of the laser is

$$E_{laser} = \int \int \frac{d[h\nu]_{in}}{dt} dt dV = \int \int \gamma_0 I dt dV = \int \int \left(-\frac{\ln T^2 R}{2L}\right) I dt dV$$

In essence we can write down a simultaneous equation describing the entire kinetic process of the formation of the KrF^* laser, the quenching, radiation, absorption, and output of the laser and solve for the parameters of interest. Due to the limitation of space, the details will not be given here.

2.4 Compression of the KrF^* laser pulse

The advantages of the KrF^* laser are: the wavelength is in the infrared region, the light emitting efficiency is high, the medium is a gas and the heat dissipation is easy. But it has one drawback: its pulse width is large, from several tens to several hundred nanoseconds. This drawback is detrimental to the efficiency.

In order to eliminate this drawback, three methods have been employed so far to achieve pulse compression: the pulse stacking method, the Raman backscatter method, and a combination of the two methods above.

1. The pulse stacking method

The principle of the pulse stacking method is shown in Figure 3.

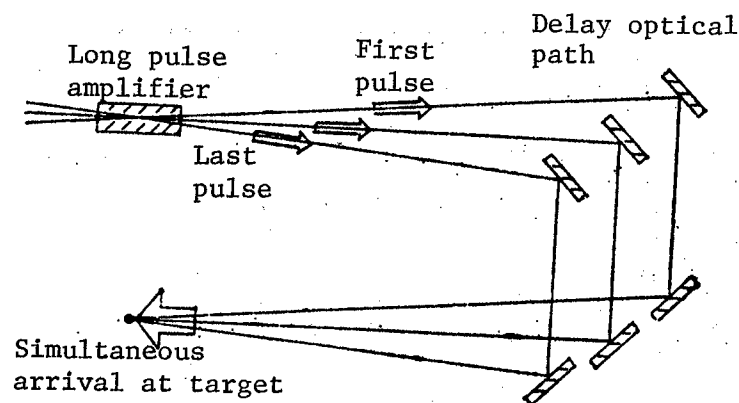


Fig. 3 Schematic Diagram Showing Simple Pulse Stacking

Temporally and spatially separated multiple pulses are produced by passing a long KrF^* laser pulse through a multibeam generator which has beam splitters and reflection mirrors. Incident pulses at various angles go through properly prescribed optical path and reflection and arrive at the target simultaneously, achieving the stacking of multiple pulses.

Using the multibeam generator, one pulse is split into N temporally and spatially separated pulses. The amplifier and the stacker accomplish the pulse compression and power amplification. However, N cannot be too large since difficulties are encountered when N is greater than 4 or 5. On the one hand the number of optical components becomes great and on the other hand long propagation distances will be required to separate the beams temporally and spatially.

2. The pulse compressor

The pulse compressor is actually a Raman amplifier which converts a long pulse into a short pulse using the principle of Raman backscattering and achieves power amplification. The action of a pulse compressor is shown in Figure 4. A KrF^* laser pulse of width τ_p and frequency ν_p passes from right to left through a gas cell containing CH_4 gas as the Raman medium. The CH_4 molecules are excited and Raman scattering takes place. This pulse is known as the pump pulse.

Let the transition frequency of the stimulated Raman medium be ν_r . When the pumping pulse propagates to the end of the Raman cell, a short pulse is injected from left to right. The short pulse is emitted from another Raman cell and is called the Stokes pulse. The frequency of the Stokes pulse ν_s satisfied the condition $\nu_s = \nu_p - \nu_r$. Due to stimulated Raman scattering, the Stokes pulse is amplified and the energy of the pumping pulse is dissipated in the Raman medium. The length of the Raman cell is made to be equal to the propagation distance of light in the time interval $\tau_p/2$. At $t = \tau_p/2$, the trailing edge of the pumping pulse meets the leading edge of the amplified Stokes pulse at the right-hand end of the Raman cell. In this arrangement the Stokes pulse is continuously amplified along the entire length of the Raman cell while maintaining the same pulse width. If the compression ratio of the Raman amplifier is K and the extraction efficiency is η_R , then the power gain after Raman amplification is $P/P_0 = K \eta_R$. Generally $K \approx 10$ and $\eta_R \approx 50$ percent, P/P_0 is therefore about 5.

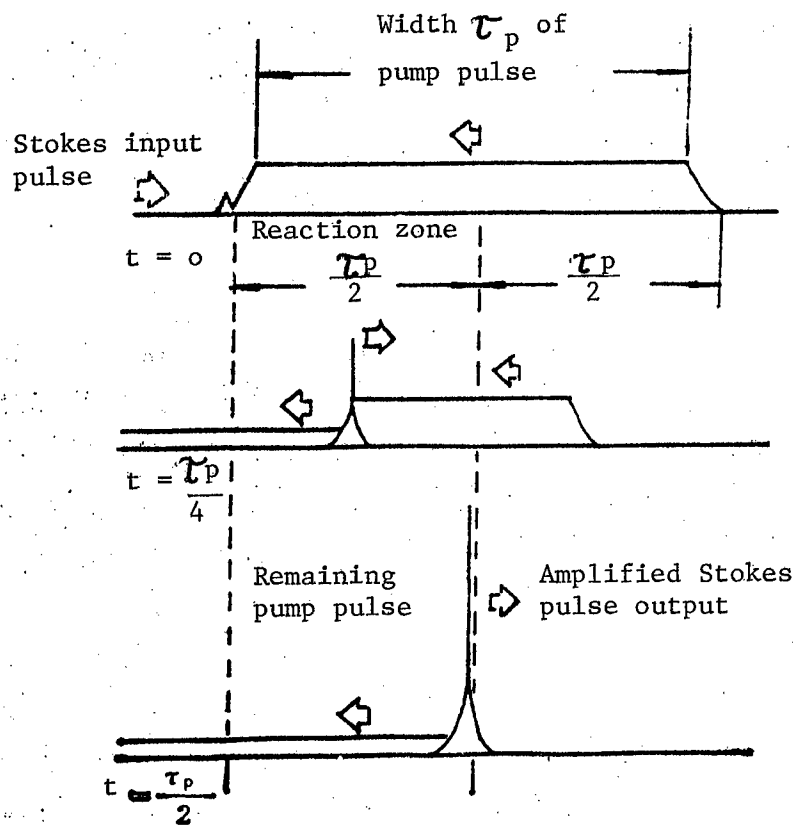


Fig. 4 Raman Scattering Stacking

3. Combination of stacking and compression

The configuration of this method may take various forms. Figure 5 shows a simple arrangement.

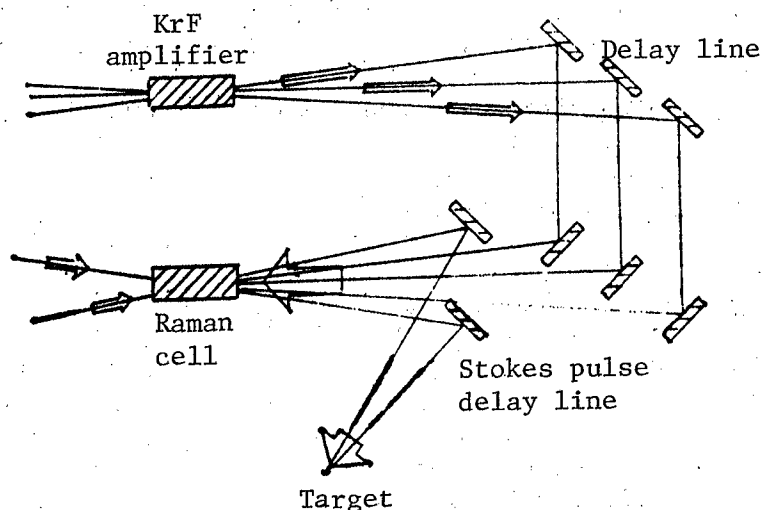


Fig. 5 Raman Scattering and Pulse Stacking Combination

Several long KrF* pulses (Figure 3 has three pulses) are amplified and go through different optical paths. After pulse stacking, they are directed to the Raman amplifier. One or two pulses enter the Raman cell from the opposite direction and produce an amplified pulse at the exit of the cell. After going through different optical paths, the pulses are stacked on the target. Using this method, it should not be difficult to compress a 60 ns 248 nm KrF* pulse to a 5 ns 268 nm Stokes pulse with 10 times the power. The Rutherford Institute in the United Kingdom is currently conducting the design to compress a 60 ns 300 J KrF* pulse to a 1 ns pulse and raise the power density from $6 \times 10^{13} \text{ W/cm}^2$ to $10^{14} \rightarrow 10^{15} \rightarrow 10^{16} \text{ W/cm}^2$.

As discussed above, the KrF* laser is a promising candidate for a high power source. There are no more insurmountable difficulties and the estimated cost is about one order of magnitude lower than that of Nd:glass laser. The prospects are good, but it is still hard to predict whether major difficulties will be encountered in building extremely high energy KrF* lasers in the 100 kJ or MJ range.

III. Light Ion Beam Fusion Research

Light ion beam as fusion drivers have the advantages of high efficiency (≥ 30 percent), low cost ($\leq \$50/\text{J}$), relatively simple energy deposit behavior on the target and in agreement with classical theoretical computation, and produce no preheating of the thermonuclear material at the center of the target by superheated electrons. The main difficulties of using light ion beams are the transport and focus of the beam, especially the latter. The efforts in

recent years are mostly concentrated on the temporal compression of the pulse power for a shorter pulse and higher peak power. The reduction of the spot size is achieved through improved beam intensity, suppressed divergence angle, and improved particle beam energy per unit area on the target surface.

The quality of a light ion beam is determined mainly by the beam brightness. The beam brightness is given by $B = \frac{J}{V \Delta \theta^2}$ where J is the current density

of the beam, V is the voltage between the cathode and the anode, and $\Delta \theta$ is the vertical or horizontal microscopic divergence angle when the ions are emitted from the anode. The brightness may be increased by raising the voltage V (i.e., increasing the ion energy) and increasing the current density. To reach ignition, B must in general exceed $10^{14} \text{ W.cm}^2.\text{rad}^2$.

The pinch reflex diode (PRD) of the Naval Research Laboratory in the United States has a current density of $3\text{--}30 \text{ kA/cm}^2$. The diode with an external magnetic field at Sandia Laboratory¹⁰ has a current density of $7\text{--}35 \text{ kA/cm}^2$. In both facilities it was observed that no apparent relationship exists between $\Delta \theta$ and J . The dependence of the brightness on the current density is basically a linear relationship. The dependence of the brightness on the voltage V is of particular interest because $\Delta \theta$ decreases as V increases. Based on limited available data so far, B depends on V^2 , as shown in Figure 6.

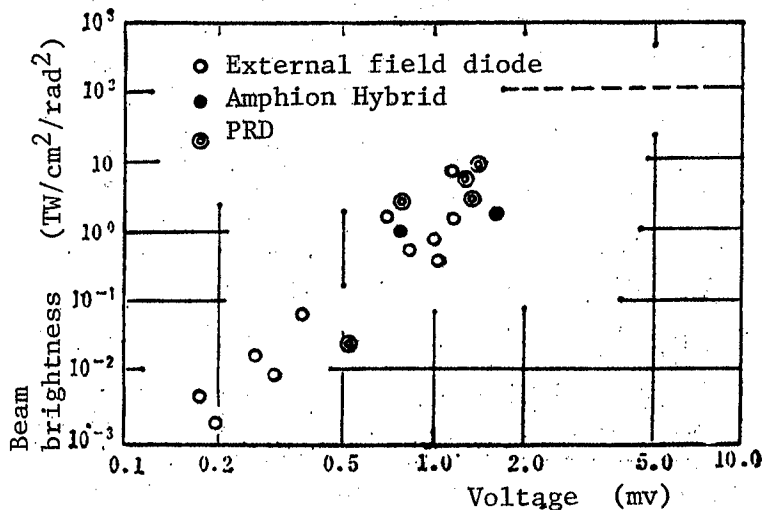


Fig. 6 Dependence of Beam Brightness on Voltage for Three Different Diodes

The vertical or horizontal microscopic divergence angle $\Delta \theta$ is determined principally by:

1. Deflection of the ion beam in the nonmagnetic neutral zone.
2. The filament instability when the ion beam passes through the gap between the cathode and the anode increases the divergence angle, which in turn affects the beam intensity.

3. Instability caused by the interaction between the ion beam and the cathode plasma when the beam passes through the electron cloud and effects of the background gas.

4. Nonuniformity of the anode plasma. The surface smoothness and homogeneity of the anode plasma directly affect the size of $\Delta \theta$.

In essence, the light ion beam driver must have the following characteristics: (1) a large accelerating voltage, (2) a high current density, (3) a large magnetic field in the accelerating gap, (4) a magnetically neutral beam transport, (5) a beam of light ions such as Li^{+2} or C^{+2} but not protons.

To improve the ion beam, Sandia Laboratory, the Naval Research Laboratory (NRL) and Cornell University¹ in the United States have each worked on one type of ion beam diode and the best one was used in PBFA-II. The ion beam diodes are respectively the PRD developed by NRL, the external field diode developed by Cornell and the Amphion-hybrid automatic injection plasma diode developed by Sandia Laboratory.

Japan started its research in the ion beam area later than the United States but has had rapid development. The Reiden VI at Osaka University has now been upgraded to Reiden VI-H, the output voltage has been increased from 1.7 MV to 3M and, like the Americans, the Japanese have also used the plasma erosion opening switch (POES) and achieved 1.5 times power amplification and 1 percent prepulse. They are also working on ion gun improvements, hoping to have a 4 times power amplification. The ETIGO-I at the Nagaoka Industrial University has a voltage of 1.5 MV and a current of 200 kA. The ETIGO-II is being actively developed to raise the voltage to 3 MV and the current to 300 kA. They have developed a medium mass atomic linear induction accelerator system (MALIA) to accelerate medium ions such as B^+ , C^+ and Ne^+ . Spontaneous focusing by the particle trajectory may eliminate the plasma channel and other complicated setup. The parameters of the medium mass ion beam are 420 kV, 6 kA, and 5 ns. This is of course a small prototype, but it is a good start.

The Japanese researchers have also worked extensively on the ion beam diode and their newest achievement is the inverse pinch diode (IPD). The improved model IPD has a small divergence angle $\Delta \theta$ and has reached a beam brightness of $4.3 \text{ TW/cm}^2 \cdot \text{rad}^2$ with a uniformity of 40 percent.

IV. Implosion Plasma Research

The research on implosion plasma began in the early 1970's. It did not receive much attention in the beginning but has attracted great attention recently. This research became even more significant along with the development of high power pulse accelerators. One of its possible applications is the inertial confinement. We now briefly describe the implosion process.

The mechanism of implosion has been reported in the literature.¹¹ A 2-3 cm long, a few centimeter radius metal foil cylinder, metal wire array or cylindrical shell is placed between the electrodes of a high-power accelerator as a load. A prepulse is first applied to cause ionization and then, under action of the main pulse, the great JxB centripetal force (J is the current and B is the self-generated magnetic field) leads to implosion.

Today there are at least six places in the United States that are conducting implosion research. France and Canada are also working on implosion research but on a smaller scale. Among the U.S. companies, Maxwell and Physical International (PI) produced the most prominent results. Table 2 lists the experimental parameters¹² of a typical test on the Blackjack-5 of the Maxwell Company. As can be seen, the plasma temperature has reached 1-2 keV and the electron density has reached $10^{21}/\text{cm}^3$ at a power less than 10 TW. In other experiments people have obtained several tens of kilojoules of X-rays (energy from a few eV to a few keV) and arrived at a method to eliminate the Rayleigh-Taylor instability.

Good results were also obtained on the Python facility--a joint effort of PI and LLNL. The high intensity soft and supersoft X-rays (40 eV-13 keV) are most interesting. When the stimulated medium is an argon gas, they obtained the quasi-Ne and quasi-FKr lines in the X-ray region and the vacuum ultraviolet (VUV) radiation emitted by the Kr plasma. Some of the spectral lines yet to be identified are believed to be Ne-like transitions including the expected laser transition. In the AFWL experiment, deuterium was used in the cylindrical jet, although the X-ray obtained was weaker than expected, considerable number of neutrons were obtained at a temperature of several tens of keV.

Based on the experimental results just described, the implosion plasma may be used as an X-ray laser light source and may also be used in inertial confinement. These are undoubtedly the two main reasons for the great amount of money and effort devoted to such research. The advantages are the simple testing procedure and the elimination of complicated and minute targets. More important, the product is of the centimeter length and 0.1 mm diameter. It is large in size and can be operated and handled more easily. Its output energy (5MJ) and power (15 TW) are also great, the energy is 50 times that of the current NOVA laser (100 kJ, 100 TW). Although the power is only 1/7 of that of NOVA, the average power density is $\sim 10^{14} \text{ W/cm}^2$, but it produces a great amount of soft X-ray (of the order of 10 kJ). In this respect, it serves better as an X-ray laser source than an inertial confinement source. Since it uses cylindrical compression and not spherical compression, the efficiency is not as good. Under the leadership of Professor (Lu-da-ke-fu) of the Kurchatov Institute in the USSR, there has been a continuous effort on the Angara-V (2 MV, 25 MA) to study implosion methods and strive for important inertial confinement results. Unfortunately, they have yet to release any of their research results and we cannot comment their finding on the advantages and disadvantages of implosion and inertial confinement methods.

In this paper we have briefly described four new and promising approaches to inertial confinement, they are the hohlraum (or cannonball target), also known as indirect driver, the KrF* laser, the light ion beam and the imploding confinement. The readers may refer to the paper by Yonas¹⁰ for an overview of the recent advances in inertial confinement. China has not begun its work on any of these four methods, at most some preliminary work on KrF* laser has been done. However, China has had a sound basis to embark on these researches.

Table 2. Typical Experimental Parameters of the Maxwell Implosion Test

Expt. conditions and results \ Type of load	6-wire array	Ar gas shell cylinder
Wire diameter (μm)	Al, Ca, Ti, Fe 30 50 20 65	--
Length	3.0	3.0
Ring diameter (cm)	1.5, 2.0 - 2.5, 2.0, 2.0	2.5
Ring thickness (cm)	--	0.5
Loop diameter (m)	4.0	4.0
Mass ($\mu\text{g/cm}$)	130, 90, 86	332
Voltage (MV)	3	3
Current (MA)	4.6	3-5
FWHM (ns)	~ 100	~ 100
Power (TW)	10	10
Implosion time	100 ns after main pulse	90 ns after main pulse
Implosion velocity (cm/s)	80 (Fe)	50
T_c (keV)	0.5 - 2	1
Ne	$5 \times 10^{20}/\text{cm}^3$	$10^{21}/\text{cm}^3$
K-line zone (FWHM)	1.2 - 3.0 mm	--
K-line pulse (FWHM)	20-25 ns	--

In the area of high power solid laser and gas laser the Shanghai Institute of Optics and Fine Mechanics has had 20 years of experience and an international reputation, they are also experienced in target fabrication. The pulsed high current electron accelerator is the basis for the other three methods, China has built and applied such accelerator for sometime, but the power is not high enough.

China is still a developing country with limited resources, we cannot copy the research approach of the United States, the Soviet Union or Japan. In China we should select the most assuring direction based on what we have and gradually work on higher power. So far there is no "sure-fire" direction. Chinese researchers should watch closely the research trend in other countries and do their best in a careful research based on what is available. Special efforts should be made on theoretical research to understand the physical mechanism more thoroughly and to train new people. Once the direction can be better defined, the preparation work and the national economy are expected to be in better shape by that time, then more money and effort can be devoted to it to produce results.

Inertial confinement fusion research is an interdisciplinary, highly technical and difficult frontier science and technology. As research progresses, it would undoubtedly promote other areas of science to achieve new advances in technology and material. The stake is high in inertial confinement, and success will eventually come as long as the scientists continue their effort with perseverance.

References

1. Wang Ganchang, "Current Research Status of Charged Particle Beam Inertial Confinement Fusion," Atomic Energy References, Vol 7, 1980.
2. Wang Ganchang, "International Research on Inertial Confinement Fusion and Recommendations for the Chinese Effort," Collected Papers on Inertial Confinement Fusion, September 1982.
3. T. Yabe, K. Nishihara, I. Mizui, Research Report of Institute of Plasma Physics, Nagoya University, No IPPJ-235 (1975).
4. S. Bardwell, Fusion Asia, October 51 (1983).
5. Private Communication.
6. H. Hora and G. H. Miley, Laser Focus, February 60 (1984).
7. Lasers and Applications, Vol 2 No 9, 38-40 (1983).
8. G. Cooperstein et. al., Proceedings of 4th Inteen. Topical Conf., On High Power Electron and Ion Beam Research and Technology, Palaiseau, France (1981).
9. G. Yonas, U.S.-Japan Seminar on Theory and Application of Multiply Ionized Plasma Produced by Laser and Particle, May 3-7 (1982).
10. G. Yonas, Nuclear Fusion, Vol 23, 505 (1984).
11. W. K. Baker, et. al., J.A.P. Vol 49, 4694 (1978).
12. Su Yi [5685 3015], Sun Xiaoyun [1327 2556 0061], and Lu Jingping [7627 2417 1627], Private communication.

9698

CSO: 4008/374

APPLIED SCIENCES

ON-LINE SOFTWARE DEVELOPMENT SYSTEM FOR TRS-80(I)/EG3200

Shenyang XIAOXING WEIXING JISUANJI XITONG [MINI-MICRO SYSTEMS] in Chinese No 1,
8 Jan 85 pp 1-2

[Article by Li Benren [2621 2609 1804], Gong Ganghua [7895 0474 5478] and Meng Qi [1322 1142], Shenyang Computer Institute, Chinese Academy of Sciences: "On-line Development System for TRS-80(I)/EG3200 Software"]

[Text] Abstract: This paper is a brief introduction to the configuration and development performance of this system. The operating principles and functions of the parts of the system will be discussed in detail in four special articles.

Currently, the number of TRS-80(I)/EG3200 microcomputer systems and various single board computers and single-chip microprocessors in China is very large and the range of applications is also becoming broader. However, there is a general lack of techniques for developing these single-board and single-chip microprocessors.

To resolve the problem of development tools, with the TRS-80(I)/EG3200, single-board and single-chip microprocessors as our object, we developed an on-line software development template, programmer and a set of development software so that the general user can upgrade his own TRS-80(I)/EG3200 microcomputer and single-board computer inexpensively to an on-line software development system, clearly improving the efficiency of software development and promoting the broad application of microcomputers (especially single-board computers and single-chip microprocessors).

The on-line software development template, programmer, and development software we developed is:

Hardware:

- TRS80(I)-Z80 on-line development template
- TRS80(I)-8080 on-line development template
- TRS80(I)-8085 on-line development template
- TRS80(I)-Z80, 8080, 8085 on-line development template
- 2716/2732/2764/27128 high-speed EPROM programmer (improving programming speed by six-fold)
- 8748/8741/8755 single-chip computer programmer (can use the Z80 single-board computer to control programming)

Software:

- 8080, 8085, MCS-48, UPI-41 cross-assembly editing language
- DSZ80, DS8080, DS8085 development debugging software
- DEPROM high-speed programming software
- DMUE single-chip microprocessor programming software
- ZMUE single-chip microprocessor (Z80 single-board computer controls programming) programming software

The TRS-80(I)/EG3200 on-line software development system forms of the above templates and software passed appraisal in September 1984 and has gone into small batch production.

As the appraisal conclusion pointed out: "With an inexpensive and practical template, this system connects the popular TRS-80(I) computer or EG3200 micro-computer to a single-board computer and programmer carrying out programming and software debugging of such microprocessors as the Z80, 8080 and 8085 and single-chip microprocessors such as the MCS-48 and UPI-41, expanding the TRS-80(I) or EG3200 into an on-line software development system. System operation is simple. Using it as a tool can improve efficiency of developing application of single-board computers and single-chip microprocessors. Especially in EPROM programmers such as the 2764/27128 using a smart programming algorithm it achieved advanced levels for similar products abroad. The programmer for many kinds of single-board computers has resolved an urgent need in scientific research and production in China."

The TRS-80(I)/EG3200 on-line software development system can be used to develop software for debugging Z80, 8080 and 8085 single-board computers and for writing programs for the MCS-48 and UPI-41.

The assembly language and cross-assembly editing language provided by the system can be used to write programs for the Z80, 8080, 8085, MCS-48 and UPI-41. This resolved the problem of writing single-board computer and single-chip microprocessor programs. Except for the instruction system mnemonics, the syntax and format used in the cross-assembly editing language is identical to the syntax and format used in editing TRS-80(I) assembly language and extremely easy for users to learn and master.

Development debugging software, disk object file oriented, carries out file transmission between the TRS-80(I)/EG3200 and single-board computer, resolving the single-board computer program or data I/O technique, but what is more important, it resolved the program debugging technique on the single-board computer. In addition to the DEBUG function on the TRS-80(I), the debugging functions include six debugging commands that were added, i.e., automatic continuous single-step tracing, jump type instruction tracing, call instruction tracing and interrupt program analog debugging functions, which greatly strengthen the debugging ability of the development software.

In sum, at the assembly language level, it makes use of Z80, 8080, and 8085 single-board computers (or prototypes) completely like a microcomputer system.

The programmer hardware and software took into consideration the problems of reset power drop and powering up or down under program control and guaranteeing the safety of the programming chip. Through a single easy insert/remove socket the high-speed programmer carries out programming of four kinds of compatible chips, 2716-27128, uses an intelligent programming algorithm to increase programming speed by six-fold, which has great significance for being able to greatly shorten the programming time for programming the large capacity 2764/27128 chip. The single-chip programmer (programming can be controlled with a Z80 single-board computer) resolves an urgent need in China's scientific research and production. It carries out programming of five types of compatible chips: 8747, 8749, 8741, 8742 and 8755. The programmer software is disk object file-oriented, it can write a disk object file directly to the EPROM chip, thus resolving the problem of the program floating to the EPROM address space without using the address to replace the real. The single-chip program programmer can use the Z80 single-board computer to control programming. This provides the many users who do not have a TRS-80(I)/EG3200 microcomputer system, but have only a Z80 single-board computer technique for using a Z80 single-board computer to control programming of a single-chip microprocessor. It provides units which use a single-chip microprocessor to develop small-scale control devices, intelligent instruments and computer peripherals, it provides a single-chip microprocessor programming technique geared to a variety of products.

In a situation in which the prices of development systems imported from abroad are very costly and lacking a domestic development system which is geared to a variety of types of microcomputers, the development of the TRS-80(I)/EG3200 on-line software development system solves, very inexpensively and very comprehensively, the problem of a software development technique for the domestic-ally commonly used Z80, 8080, 8085 8-bit microcomputer systems (especially single-board computers) and a programming technique for the MCS-48 and UPI-41. This will promote the development and application of microcomputers (especially single-board computers and single-chip microprocessors) and make user software development much more efficient and thus secure clear benefits.

For a detailed introduction to the relevant system working principles and performance, please refer to these four special articles:

- Single-board Computer Programmer
- High-speed General-purpose EPROM Programmer
- On-line Software Development Debugging System
- Design and Implementation of Software Cross-Development Technology

The first two of the articles have already been published. The latter two will be published in the next issue of this journal. Interested readers should consult the corresponding materials.

8226

CSO: 4008/1037

APPLIED SCIENCES

HIGH-SPEED GENERAL-PURPOSE EPROM PROGRAMMER

Shenyang XIAOXING WEIXING JISUANJI XITONG [MINI-MICRO SYSTEMS] in Chinese No 1,
8 Jan 85 pp 3-7

[Article by Li Benren [2621 2609 1804], Gong Ganghua [7895 0474 5478] and Meng
Qi [1322 1142], Shenyang Computer Institute, Chinese Academy of Sciences:
"High-Speed General-Purpose EPROM Programmer"]

[Text] Abstract: This paper introduces the intelligent programming algorithm and hardware design of a high-speed general-purpose EPROM programmer. The intelligent programming algorithm increases the EPROM programming speed six-fold over general programming methods. With the addition of disk object file programming software and a single easy insert/remove socket, carrying out program controlled power up/down functions for 2716-27128 chips provides the user with a new technique for programming EPROM's.

I. Introduction

With the rapid development of LSI technology, the capacity of EPROM's has leaped to 256K on a single chip (such as the INTEL 27256). Therefore, the industrial programming standard of the past of applying a standard 50ms programming pulse by EPROM byte has been increasingly revealed as imperfect. For example, the programming time of the INTEL EPROM chip by the above described programming standard is as illustrated in the following table:

Model	Bytes (K)	Programming time (min)
2716	2	1.75
2732	4	3.5
2764	8	7.0
27128	16	14.0
27256	32	28.0

From the table it can be seen that as the capacity of EPROM's has increased, the programming time has grown linearly. The programming time to program all the cells in the 27256 has grown to more than 28 minutes. Clearly, continuing to use this programming method is unacceptable. Thus, we adopted an intelligent programming algorithm and developed a high-speed general-purpose EPROM programmer.

In addition, in hardware design, insuring the safety and reliability of chip read/write is extremely important. Thus, the chip socket and the pins related to the power supply are entirely powered up and down under program control. The design insures that only during read/write do the chip's power supply pin sockets have appropriate voltages and signals, and at all other times, the pin sockets are grounded or floating empty. Thus the safety of the EPROM chip is assured.

Compared to multiple sockets, programming four kinds of chips using a single easy insert/remove socket, both lowers costs and is easier for the user.

II. Principles of Hardware Structure

Figure 1 shows completely the hardware structure principles of the high-speed general-purpose EPROM programmer.

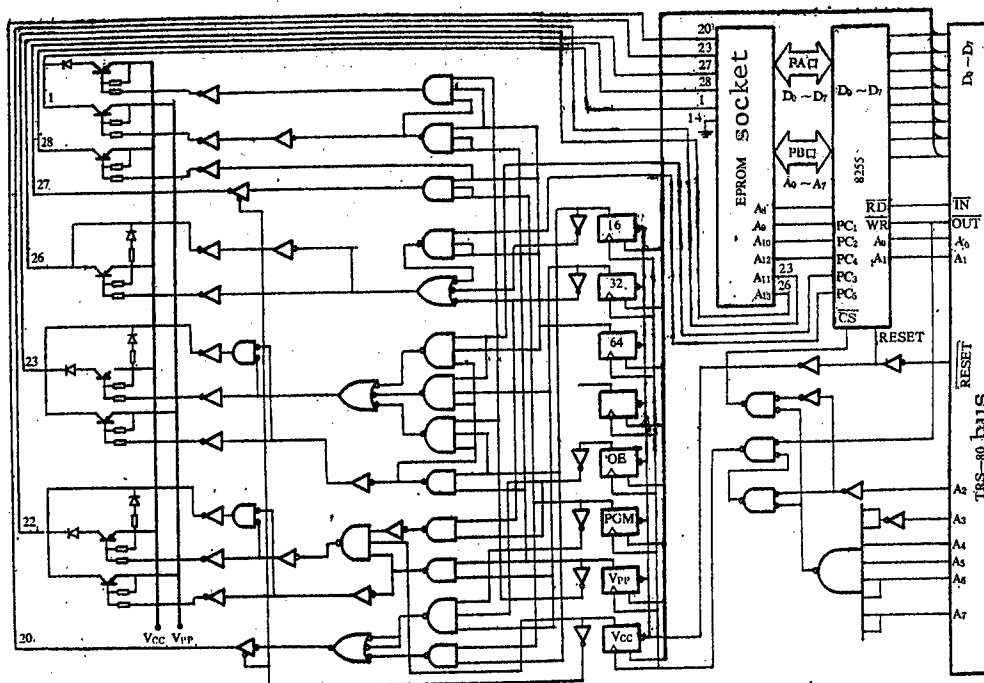


Figure 1. Principles of Programming Hardware Structure

The programmer's external lead connectors are completely compatible with the bus connector leads on the TRIS-80(I) microcomputer expansion interface. The Vpp voltage also can be self-adjusted by the user on the basis of EPROM chip demands.

Overall control of the programmer is realized by an 8255 programmable peripheral interface chip and a 74LS273 8-D flip-flop. The 8255's PA kou [0656] works under bidirectional mode and connects with the data line of the EPROM socket; the 14 positions of the PB kou and PC kou are the 16K EPROM space's address lines and address line connections of the EPROM socket (because the 4 types of chips use a single socket in common, some lines must be connected to the EPROM socket after undergoing combination decoding), PC₇ and PC₈ are for use in later expansion. Each position on the 74LS273 is under software control, allowing chip selection and for power up, programming, and readout control.

Because the four types of chips (2716-27128) read and write in the same socket, and their pins are not completely compatible, it is necessary to carry out decoding. The pins of the four types of chips are illustrated in Figure 2: using the ground pin as a reference point, all compatible pins are marked by their names on the EPROM socket. And those pins which are not compatible (or pins which are compatible in name but not in function, such as pin 20) are marked by their names on each type of chip.

The four types of chips share a single socket for read/write, therefore the level relationship of the pins which are not compatible is complex. For example, during read/write of 2716, pin 23 serves as V_{pp}/+5v, during read/write of 2732-27128, it serves as A₁₁ address line, thus there can be four levels, namely V_{pp}, +5v, logical "1" and logical "0." To simplify circuit design, we considered +5v and logical "1" as equivalents, and designed a special tristate circuit to carry out the work demands of noncompatible pins.

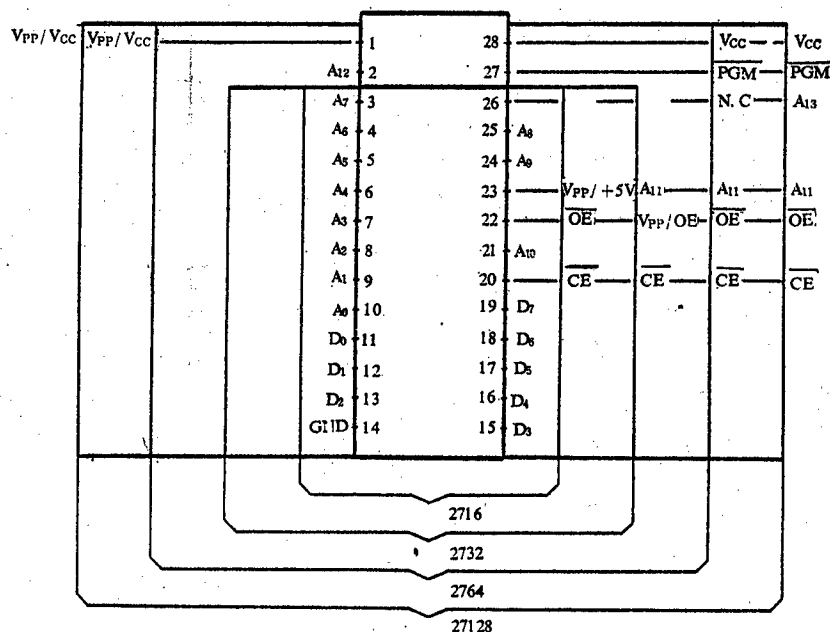
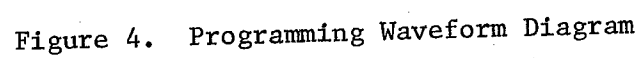
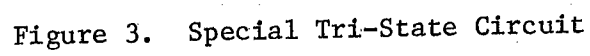


Figure 2. Chip Pin Identification



The special tri-state circuit is as illustrated in Figure 3. In the figure, V_{PPG} is the control signal of V_{PP} . When it is high, the V_{PP} voltage is open to V_{OUT} , and by the same principle, V_{CCG} is the control signal of V_{CC} (or logical "1") and when it is high, V_{CC} (or logical "1") is open to V_{OUT} ; V_{LG} is low level (logical "0") control signal, and when it is high, it makes the V_{OUT} output low level. Combination logic design guarantees that at any time, only when one of the three control signals V_{PPG} , V_{CCG} and V_{LG} is high can the normal operation of the tri-state circuit be guaranteed.

The wave-form diagrams of the four types of chips are as illustrated in Figure 4. One can see from the diagrams the incompatibility of their pins, thus in the 8 D-type flip-flops, there are 3 flip-flops 16, 32, 64/128 for chip type select. Because the V_{PP} , PGM and OE control potential is sometimes high and sometimes low, the V_{CC} is powered up only during read/write. There are four other flip-flops that can be used for control. In addition, there are differences in the chip descriptions of PGM and OE, thus here we uniformly define the waveform which is at A in the waveform as PGM and the waveform at B, as OE.

The definition of the control flip-flops is:

V_{CC}	V_{PP}	PGM	OE		64	32	16
----------	----------	-----	----	--	----	----	----

The control potential of the special tri-state circuit for controlling incompatible pins in the EPROM connector is decoded according to the demands of Figures 2 and 4 and the combine logical Boolean expression obtained is as follows:

$$\begin{aligned}
 \text{Pin 1 : } & V_{PPG1} = 64 \cdot V_{PP} \\
 & V_{CCG1} = \overline{V_{PPG1}} \cdot 64 \cdot \overline{V_{PP}} \\
 \text{Pin 20: } & V_{20} = [16 \cdot \text{PGM} + 32 \cdot \overline{\text{PGM}} \cdot \overline{\text{OE}}] \cdot V_{CC} \\
 \text{Pin 22: } & V_{PPG22} = 32 \cdot V_{PP} \\
 & V_{CCG22} = 32 \cdot \overline{\text{OE}} \cdot \overline{V_{PPG22}} \cdot V_{CC} \\
 & V_{LG22} = \overline{V_{CCG22}} \\
 \text{Pin 23: } & V_{PPG23} = 16 \cdot V_{PP} \\
 & V_{CCG23} = 16 \cdot \overline{V_{PP}} \cdot \overline{V_{PPG23}} + 32 \cdot A_{11} \cdot \overline{V_{PPG23}} + 64 \cdot A_{11} \\
 & \quad \cdot \overline{V_{PPG23}} \\
 & V_{LG23} = \overline{V_{PPG23}} \cdot \overline{V_{CCG23}} \\
 \text{Pin 26: } & V_{CCG26} = 16 + 32 + 64 \cdot A_{13} \\
 & V_{LG26} = \overline{V_{CCG26}} \\
 \text{Pin 27: } & V_{27} = 64 \cdot \text{PGM} \cdot V_{CC} \\
 \text{Pin 28: } & V_{CCG28} = 64
 \end{aligned}$$

According to the above Boolean expressions, the logic diagram is drawn as in Figure 1. The other parts of Figure 1 are of the 8255 program control chip and the address decoding of the 74LS273, but we will not go into detail about them here.

In short, combination logic decoding insures that during computer reset or software resetting 74LS273, pins which are incompatible with the power supply voltage are all in a grounded or free-floating state. When the software is only reading/writing the EPROM chip, it sends a definite content to the 8-bit control register. When read-write is finished, software immediately resets the control register to insure that the pins are grounded or in a floating free state to insure the safety of the chip.

III. The Intelligent Programming Algorithm

Using a general-purpose programming method (i.e., taking 50ms for each byte), the time necessary to program each byte is viewed as equal, and it requires only that it be executed according to a factory scale programming time to be able to achieve programming. In fact, the programming time demanded for each memory cell is unequal, the statistical curve of the programming time required by each cell is as illustrated in Figure 5: from this figure it can be seen that the overwhelming majority of EPROM cells can be programmed in 8ms and that only 2 percent of the cells requires 50ms to program. Clearly, programming the majority of the cells according to a standard in which the minority of cells takes longer to program is irrational. Thus, we propose the intelligent programming algorithm. The basic concept of the intelligent programming algorithm is to program each cell in actual programming time required (with the addition of a certain programming time factor to insure reliability).

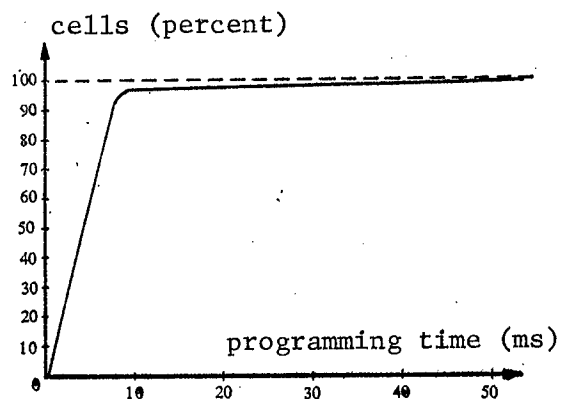


Figure 5. Programming Time Curve

The block diagram for the specific intelligent programming algorithm is illustrated in Figure 6.

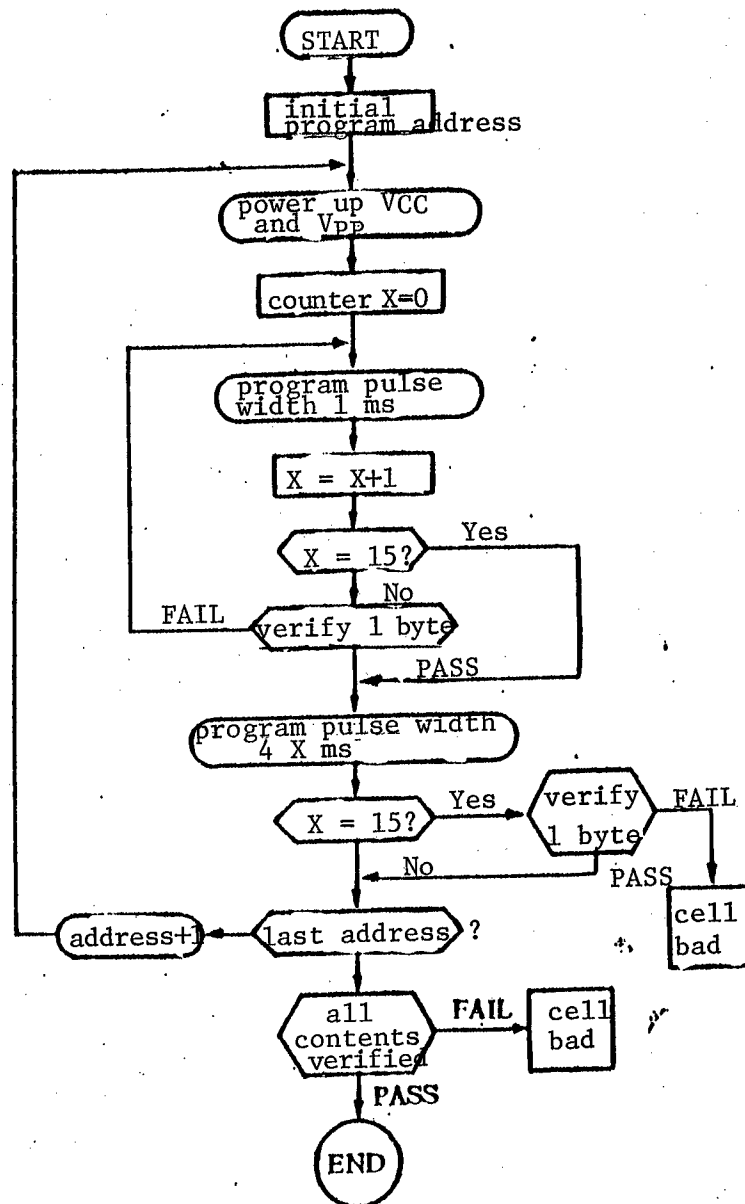


Figure 6. Intelligent Programming Algorithm Block Diagram

From the intelligent programming algorithm block diagram it can be seen that 1 ms after programming each cell, it is checked once, and the programming time for each cell X is clocked once, and this repeated programming and checking goes on until it checks out correctly or until X clock reaches 15 ms; finally, according to the value of X it is programmed again $4X$ -fold times in order to insure the reliability of the programming results. Thus, the overall programming time is $5X$ ms. In this way, the value of X is small for cells which are easy to program, and the total time required is also small, and the value of X is big for cells which are hard to program, and the total time required to program is also big. The programming time of each cell is distributed as

required but it is not all 50 ms saving on total programming time. From the algorithm block diagram it can also be seen that the greatest programming time is 75 ms. After certain cells have been programmed for 75 ms and a correct result has not been attained, the algorithm declares the cell defective (of course, when a component has not been erased clean, this phenomenon can also occur).

In short, the intelligent programming algorithm saves a great deal of time so that programming speed can be increased over 6-fold. This has special significance for programming large capacity EPROM chips.

IV. Disk Object File Programming Software

The applications software for the high-speed EPROM programmer runs on the TRS-80(I)/EG3200. This software is disk object file oriented, that is, in addition to having such functions as read, search, check and writing the contents of RAM to the EPROM chip, this programmer and the software also can directly write a disk target file directly to the EPROM chip, thus resolving the problem of the program being free floating because the address is not used to replace the true. In addition, the entire operation is carried out under the direction of complete and clear interactive dialogue of the software, requiring only that the operator carry out operations according to the prompt information to be able to achieve correct results. For detailed explanations and program block diagram related to this software, please refer to the article SINGLE-CHIP MICROPROCESSOR PROGRAMMER in this issue. If the dashed line part of the program block diagram is dropped, and replaced by the WRITE program part using the intelligent algorithm, the whole thing would be applicable here.

V. Conclusion

The design of this programmer and the software have already been finalized and spread and in September 1984 they passed appraisal. After technical testing by the experts at the meeting, they all felt that it had achieved advanced levels for similar products abroad, and that it had special significance for programming the high capacity 2764/27128 EPROM chips.

REFERENCES

1. Knowlton, Don, "Programming EPROM's With the Intelligent Programming Algorithm."
2. COMPONENT DATA BOOK, Intel Co.

8226

CSO: 4008/1037

APPLIED SCIENCES

PROGRAMMER FOR SINGLE-CHIP MICROPROCESSOR

Shenyang XIAOXING WEIXING JISUANJI XITONG [MINI-MICRO SYSTEMS] in Chinese No 1,
8 Jan 85 pp 8-15

[Article by Li Benren [2621 2609 1804], Gong Ganghua [7895 0474 5478] and Meng
Qi [1322 1142], Shenyang Computer Institute, Chinese Academy of Sciences:
"Programmer for Single-chip Microprocessor"]

[Text] Abstract: This paper introduces the 8748/8741/8755
single-chip microprocessor programming part of the TRS-80(I)/
EG3200 on-line software development system. This program can
read the internal ROM and program the internal EPROM of the
8748/8749, 8741/8742 and 8755 chips. It is a development tool
for single-chip microprocessors which is very convenient,
reliable and has powerful functions.

I. Introduction

A single-chip microprocessor integrates on a single chip the CPU, RAM, ROM
and I/O "components" and includes almost all the functions required by a
digital processing system. Because of its powerful and flexible processing
ability and excellent performance/price ratio and single power supply, it is
becoming increasingly used in small-scale control devices, intelligent instru-
ments, and computer peripherals and even as necessary spare parts for devices
that demand small size. Therefore, developing applications for single-chip
microprocessors is becoming more and more highly regarded and in scientific
research and production the problem of reading out the internal ROM and pro-
gramming the internal EPROM of single-chip microprocessors urgently requires
solution. Yet, the prices of the large-scale development systems for devel-
oping the functions of single-chip microprocessors are very high and they are
not things which all units developing single-chip microprocessor applications
have the wherewithall to import. Thus, to meet the urgent needs of the
majority of domestic scientific research and production units, we have devel-
oped and finalized design on an 8748/8741/8755 single-chip microprocessor
programmer which is easy to operate and has powerful functions for the TRS-80
(I)/EG3200 microcomputers and the Z80 single-board computer which have the
most users in China.

This programmer has MCS-48 cross assembly editing language, UPI cross assembly editing language and programming software. While programming the 8748/8741/8755 chips, it can also solve programming of the 8748/8749, 8741/8742 microprocessor programs. This programmer can be used with the TRS-80(I)/EG3200 microcomputers (including those with Z80 CPU bus, and other microcomputers that can run TRS-80(I) NEW DOS operating system) and can also be used with the Z80 single-board computer. Programmer design includes software and hardware reset, program controlled power up and down, the checking whether the single-chip microprocessor insertion is correct (except for the 8755) functions, thus insuring the safety of the single-chip microprocessor. In addition, while used on the TRS-80(I)/EG3200 microcomputers, the programming software is disk object file oriented, and it can write a disk object file directly to the internal EPROM of the single-chip microprocessor. When used with the Z80 single-board computer, the programmer operates under the control of the program software (on a 2716 EPROM chip) we provide, with parameters set by the single-board computer control program.

II. Design of Programming Circuit

The design of the programmer hardware circuit must satisfy the demands of the design task: i.e., to implement the read, write, check and verify functions of compatible 8784/8749, 8741/8742 and 8755 chips in a single socket and at the same time, to insure the absolute safety of the chip, it is necessary to have a software/hardware reset and the capability of controlling power up/down and checking whether or not the chip is seated correctly to insure that the pins received only the signal voltage demanded at the moment of read/write operations and at other times, all pins are floating empty or at low level, thus insuring the safety of chip insertion and removal and if an error in chip insertion is discovered, it can be promptly corrected.

To program a variety of kinds of chips in a single socket it is necessary to inspect the programming of each chip type and check the waveform, check the compatibility of the pins of each chip for the control signals demanded, and correctly process the control signals of incompatible pins. On inspection we discovered that the programming and checking waveforms of the 8748/8749 and 8741/8742 chips are uniform, illustrated in Figure 1, with the difference being EA, PROG (relative V_{DD} is low for about 4 diodes pressure drop) and there are differences in V_{DD} voltage for different chips. As illustrated in the table below, the V_{DD} demands for different chips are different.

Model	8748	8749	8741	8742	8755	8048 (read only)
$V_{DD}(V)$	21	20	25	21	25	12

Because the V_{DD} power supply is connected externally, when programming, the user can make adjustments as required. And EA and PROG are supplied after V_{DD} goes through four diodes. (See Figure 4) The programming waveform of the 8755 chip is entirely different from the two above-described chip types, as shown in Figure 3.

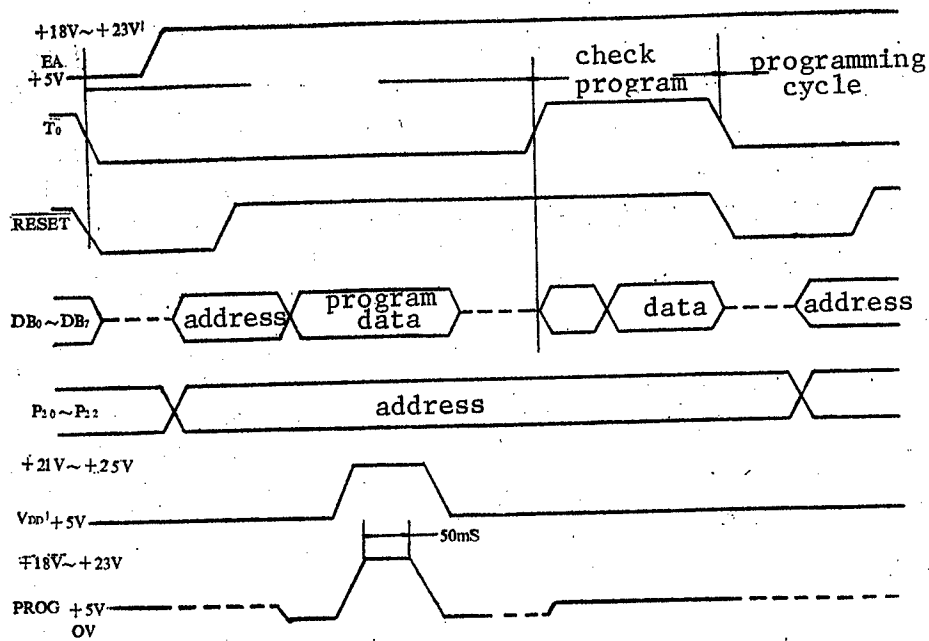


Figure 1. Diagram of 8748/8749, 8741/8742 Combined Programming Waveforms

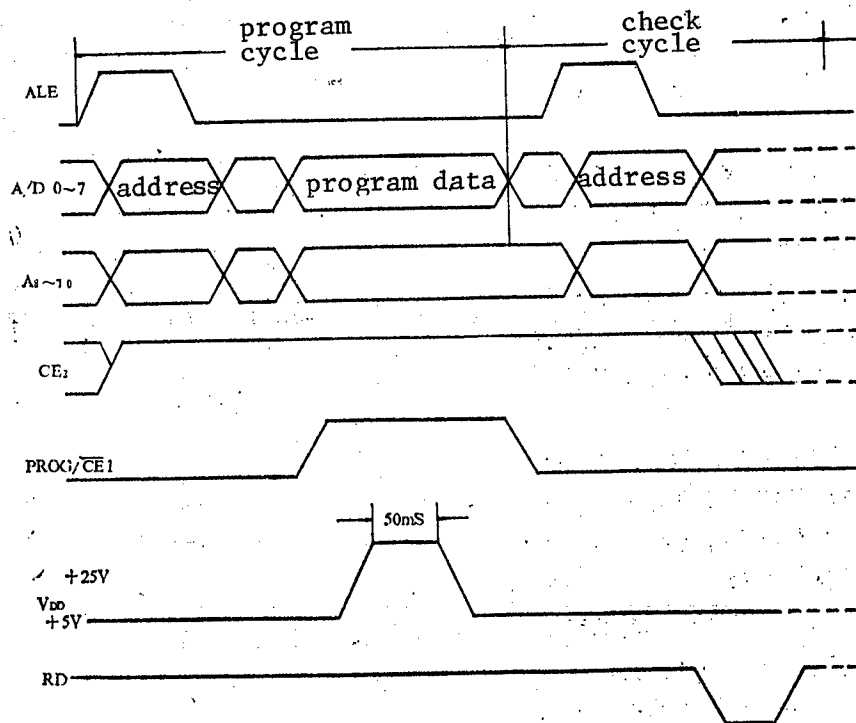


Figure 2: 8755 Programming Waveform Diagram

PROG/CEI		T ₀	2	40	V _{cc}	
CEI ₁		XTAL ₁	3	39	T ₁	
CLK		XTAL ₁	3	38	P ₁₇	P ₁₇ /DAC _K
RESET		RESET	4	17	P ₁₆	P ₁₆ /DR ₀
V _{ao}		SS	5	36	P ₁₅	P ₁₅ /IRF
READY	CS	INT	5	35	P ₁₄	P ₁₄ /OBF
IO/M		EA	7	34	P ₁₃	
TOR		RD	8	33	P ₁₂	
RD	A ₀	PSEN	9	32	P ₁₁	
LOW		WR	10	31	P ₁₀	
	SYNC	ALE	11	30	P ₉	
AD ₂₆		DB ₀	12	29	P ₈	
AD ₂₅		DB ₁	13	28	P ₇	
AD ₂₄		DB ₂	14	27	P ₆	
AD ₂₃		DB ₃	15	26	V _{ao}	
AD ₂₂		DB ₄	16	25	PROG	
AD ₂₁		DB ₅	17	24	P ₁₃	
AD ₂₀		DB ₆	18	23	P ₁₂	
AD ₁₉		DB ₇	19	22	P ₁₁	
AD ₁₈		V _{ss}	20	21	P ₁₀	

8748 8749

8741 8742

8755

32

Based on the demands of waveform diagram, pin function compatibility, software/hardware reset, program controlled power up/down, and checking the correctness of chip insertion, the diagram of the principles of overall design of the single-chip microprocessor programmer circuit are illustrated in Figure 4.

The 8748/8741/8755 single-chip microprocessor programmer is a part of the TRS-80(I)/EG3200 on-line software development system. From Figure 4 it can be seen that the hardware is actually a microprocessor external interface device. To make the hardware structure simple, we used few components. We selected the Intel Company's 8255 general purpose programmable parallel interface circuit as the main support logic, and used some other components and a programmable socket. The 8255 uses operations mode 2, and an ideal bidirectional bus is supplied by the PA kou [0656]. It is both a data bus and the address bus for the bottom 8 bits. The PA kou control signal $\overline{ACK}$, $\overline{STB}$ is supplied by PC_1 and PC_2 so as to control the PA kou to sent data (or addresses) or receive data. The PB_0 - PB_2 of PB kou is the HI address line. The other PB kou leads together with PC_0 - PC_2 of PC kou with the addition of 8 74LS273 D flip-flops and 2 74LS74 dual D flip-flops carry out control of the programming levels of the 8748/8741/8755 chips. Under the control of editing software, by means of the control signal which is provided through the decoder circuit and which corresponds to the programming waveform diagrams of the above described chips, when programming is completed and after the host computer reset and the software reset, the socket pins which are not compatible with the power supply are all grounded or in the floating free state so that when the chip is removed, its safety is insured.

For control signals for the incompatible pins, the control signal is realized in the close combination of hardware and software. For example, when programming the 8748, for pin 9 of the single-chip microprocessor (see Figures 1, 2, 3 and 4), programming software makes the 8255 chip's PB_5 and PC_0 high potential, so that pin 9 is in the floating free state; when programming the 8741, the software makes PB_5 high level and the PC_0 low level, so that pin 9 is a low level control signal; when programming the 8755, software makes PB_5 low level and PC_0 high level thus controlling the D_7 position of the flip-flop by means of the 8755 read signal ($\overline{RD}$) identification, directly applied to pin 9 and carrying out the changes under program control as in the demands of Figure 2.

Pins 7 and 25 of the single-chip microprocessor socket require a special level tri-state switch circuit to realize the demands of the programming waveforms. This special tri-state switch circuit is discussed in detail in the article HIGH-SPEED GENERAL-PURPOSE EPROM PROGRAMMER which appears in this issue; interested readers should consult this article as the description will not be repeated here.

From Figure 4 it can be seen that the circuit is equipped with a hardware reset. The software reset is a complete "0" message written to the control flip-flop. To test whether or not the 8748/8749 and 8741/8742 chips are socketed correctly, under software management, pin 11 of the single-chip microprocessor is constantly tested to determine whether or not there is a signal pulse output, and if there is no signal pulse output, it indicates that the chip is socketed incorrectly, and software will prompt resocketing

the chip (see Figure 5). From Figure 4 it can be seen that V_{DD} and other high pressure all are under program control, through the switch circuit added to the program socket, when the program is finished, software immediately resets, cuts off high pressure and insures the chip's safety.

From this it can be seen that the hardware design of this programmer takes the absolute safety of the chip into full consideration. At the same time, software and hardware also are closely combined together.

III. Programmer Functions and Program Block Diagram

The programming software which this programmer supplies has very powerful programming functions, in particular, this software is disk object file oriented and can write a disk object file directly to the program chip. The programmer has four functions: read, write, check and verify:

- READ -- reads the contents of the internal EPROM (or ROM) of the single-chip microprocessor to any RAM area.
- CHECK -- checks whether or not the single-chip microprocessor's internal ROM has been completely erased, and if not, software will list the EPROM addresses of the unclean cells on the screen.
- VERIFY -- verifies that the content of the program is correct. It compares the contents of the EPROM region being verified with the designated region of memory (where the information was originally) and if it encounters different cells, it lists on the screen the EPROM addresses of the incorrect (or different) cells.
- WRITE -- 1: writes the data from a region in memory to the EPROM in a single-chip microprocessor and verifies the results of writing.
2: writes an object file from disk directly to the EPROM in a single chip microprocessor and verifies the results of writing.

The above functions are all carried out through interactive dialogue, as illustrated in Figures 5 and 6. The program flow and the operational method are all clearly and completely indicated by the interactive dialogue prompts in the figures and no addition explanation is necessary to obtain correct results under the guidance of the interactive dialogue. When what you have keyed in is incorrect information, the computer will tell you, and let you key it in again (this is not indicated in the program flow chart). The execution process of the functions given in Figures 5 and 6, also portrays the dialogue information in the block diagrams at the same time in order to clarify the operational method and process. The English in the block diagram is the dialogue and prompt information provided by the software, the horizontal lines after the English indicate the information which the software demands the operator key in at this point.

When asked WHICH COMMAND?--, reply "B," then you will return to NEW DOS.

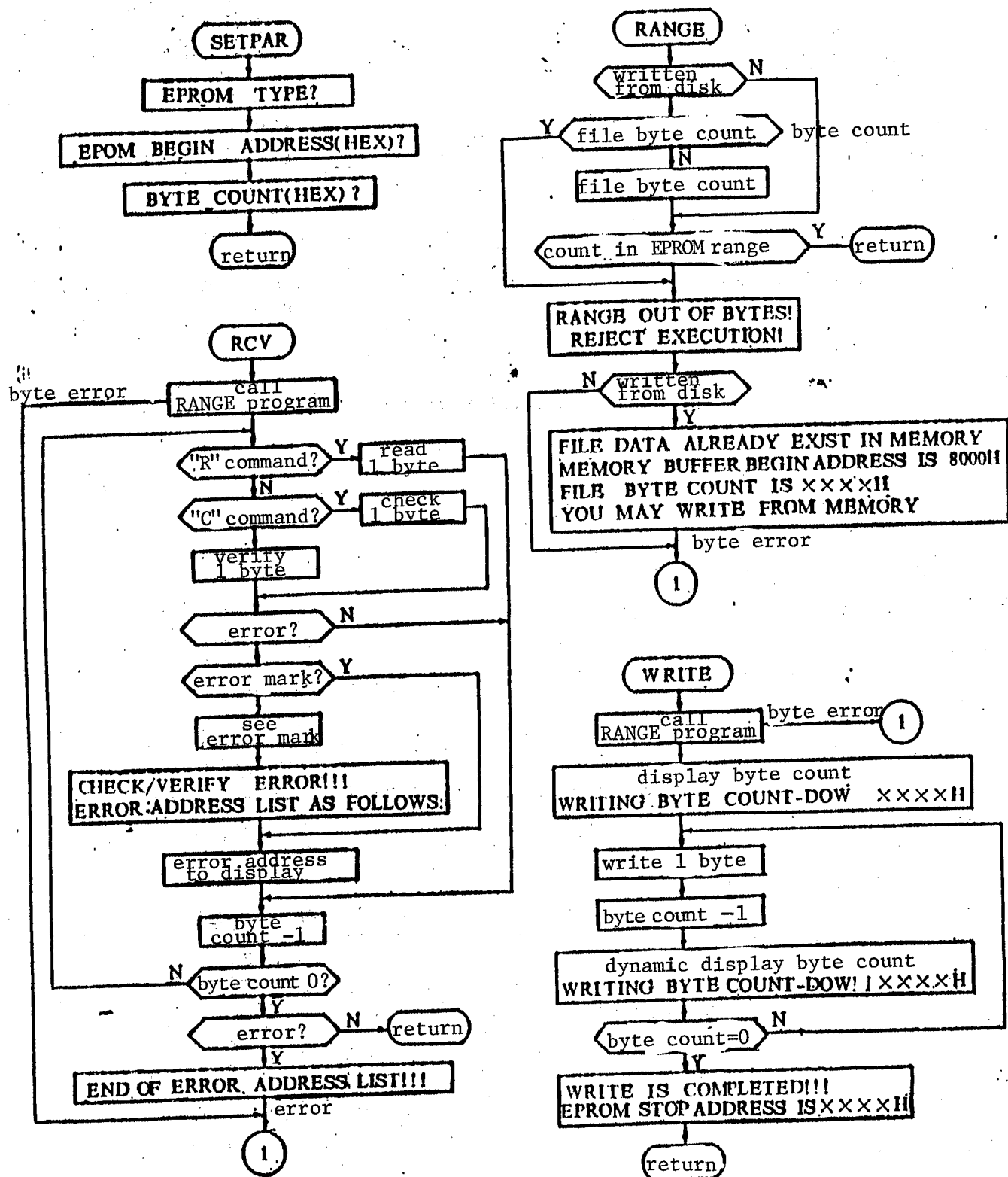


Figure 5. Programming Software Block Diagram

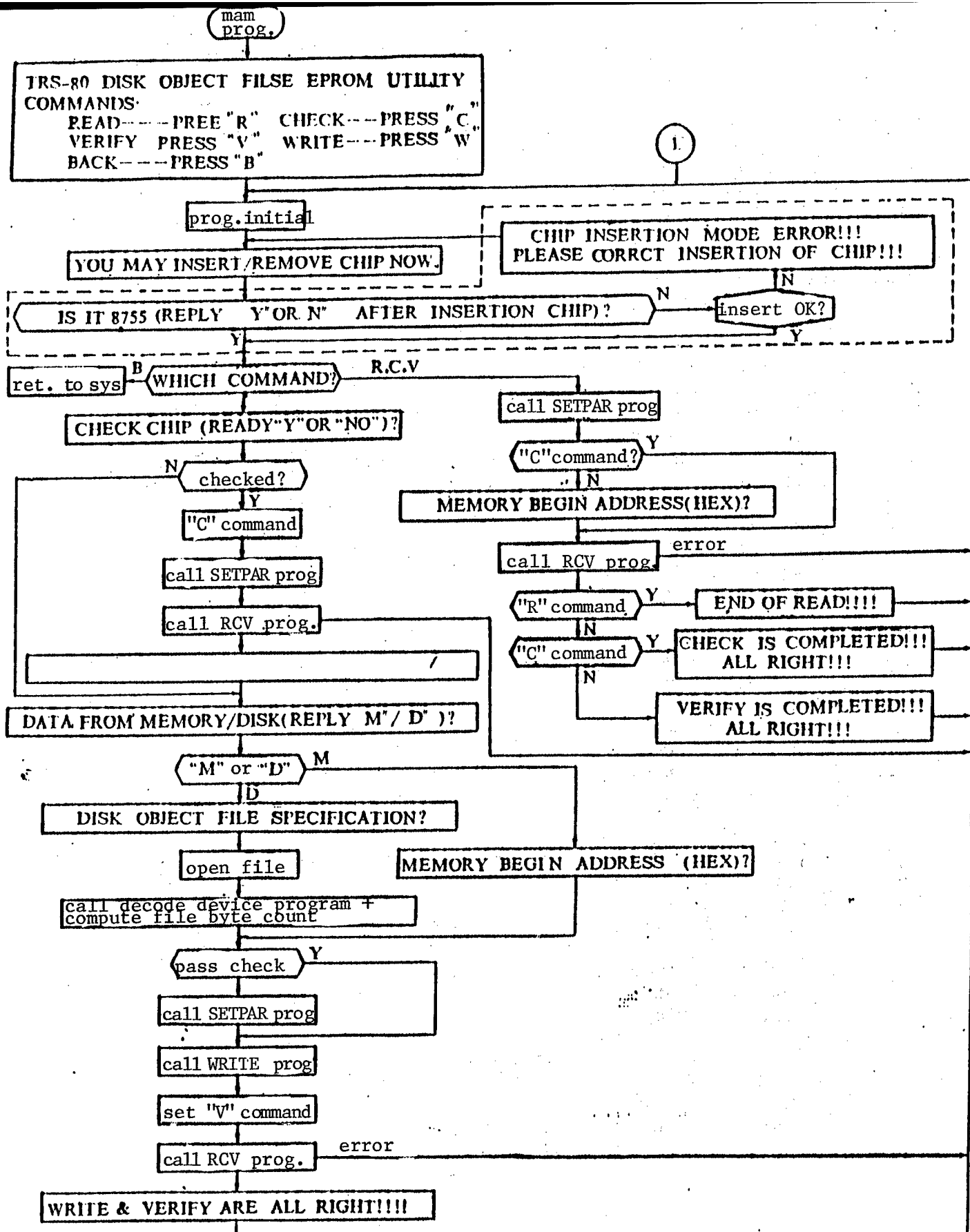


Figure 6. Subprogram Function Block Diagram

The programmer has a function (except for the 8755) which checks whether or not the single-chip microprocessor is inserted correctly. If the chip being programmed is not an 8755 (but is 8748/8749 or 8741/8742), and at IS IT 8755 (REPLY "Y" OR "N" AFTER INSERTION CHIP)?--you key in "N," the software will automatically check whether or not the chip is inserted correctly.

EPROM TYPE?--requires that you key in the model of the chip to be programmed (because dialogue principles similar to the high-speed general-purpose EPROM programmer were adopted, to make it easy to remember, here we did not use a single-chip microprocessor model dialogue indicator). When reading the ROM of a single-chip microprocessor, such as the 8048, the 8748 model compatible with the 8048 should be keyed in so that the read operation can be completed. EPROM BEGIN ADDRESS?--, BYTE COUNT?--, and MEMORY BEGIN ADDRESS?-- require that hexadecimal numbers be keyed in. Only the last four places of numerical values keyed in are accepted, and when there are not four places, zeros are automatically added to the front positions. The xxxx after the English indicates hexadecimal prompting information given by the program, of which EPROM STOP ADDRESS IS xxxxH, both indicates the stop address as well as the beginning address of the when writing next. At any time other than the programming process, by simultaneously pressing the keys, J, K and L, all the English dialogue displayed on the screen can be recorded on a printer.

When writing a disk object file, the object file extension must be /CMD or /CIM otherwise it will refuse acceptance; if the file bytes are too many (exceed the range determined by EPROM parameters), the program will refuse file writing and at the same time will present prompt information indicating the initial address of the file data loaded into the RAM buffer and the file length, and suggest that the data segments be taken from the RAM buffer and written to the internal EPROM of the single-chip microprocessor or expanded to the EPROM chip. The Chinese notes in the block diagram explain the internal flow of the software.

In the program block diagram, in addition to the main program, there are also several subprograms. They are: SETPAR, the set parameters program (SETPARAMETERS), RANGE, the program that checks the range of the EPROM's word length, RCV (READ, CHECK, VERIFY) program that executes reading, checking and verification, and the WRITE program which does the writing.

The program block diagram describes comprehensively the programming software's flow and functions. It is worth noting that if one carries out check checking under the write function, the number of bytes of the chip being checked is the number of bytes written, and the two must be the same; if the data written comes from disk, the number of bytes must be greater than the number of bytes of the disk object file, otherwise it will refuse to write, and will suggest a write method in the interactive dialogue. When the number of bytes is greater than the number of bytes of the object file, writing will be according to the number of bytes of the actual object file.

IV. Z80 Single-board Computer Controlled Single-chip Microprocessor Programmer

When linked with a Z80 single-board computer, in terms of hardware, it is only necessary to link the control signal required by the single-chip microprocessor programmer with the corresponding signal of the Z80 single-board computer.

When linked with a Z80 single-board computer, the programmer still has the four read, write, check and verify functions. Its programming software is on an EPROM chip. The software requires that before programming, the user uses the monitor program of the single-board computer itself to load the program and the operating parameters established. The specific functions and the definitions of related parameters are explained below.

When linked to a single-board computer, the programmer has the following four functions:

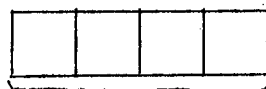
READ -- reads the contents of the single-board computer's internal EPROM or ROM to the RAM area with 2000H as the first address.

CHECK -- checks whether or not the chip's internal EPROM is erased. If cells which have not been erased clean are encountered, it displays the EPROM address of that cell and the check error indicator.

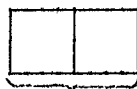
VERIFY -- verifies whether the content of the programming is correct. It compares the contents of the designated area in the chip with the contents of RAM at initial address 2000H. If a cell that doesn't conform is encountered, it displays the EPROM address of that cell and the check error indicator.

WRITE -- writes the data at initial address 2000H in RAM to the EPROM in the single-chip computer and checks the results. If there is an error, it displays the corresponding error indicator.

The format of the display information is as follows:



EPROM address



indicator

The indicator information and its meaning is listed below:

Indicator	Meaning
0 10000	chip insertion error (except for 8755)
1 H	chip reading finished
2 H	chip checking finished and correct
2 10000	chip checking error
3 H	chip verifying finished and correct
3 10000	chip verifying error
4 H	writing and verifying finished and correct
4 10000	post-writing verifying error
5 10000	chip capacity exceeded error

The Z80 single-board computer programmer software is all fixed in a 2716 EPROM chip. The address space occupied by the chip in the single-board computer is the EPROM socket with 0800H as the initial address. The software requires that the RAM parameters setting cells at 2F90H-2F95H thus the user address space is from 2000H to 2F8FH (when data being written is larger than this space, the data can be written in segments two or more times, thus each write can be any number of bytes). These parameter setting cell definitions are as follows:

Address	Meaning
2F90H	chip model number
2F91H	operation function
2492H	low byte of chip begin address
2F93H	high byte of chip begin address
2494H	low byte of number of operation bytes
2F95H	high byte of number of operation bytes

The parameter definitions of the chip model number cells and operation function cells are:

Model No	2490H value	Function	2F91H value
8748	1	READ	1
8749	2	CHECK	2
8741	3	VERIFY	3
8742	4	WRITE	4
8755	5		

The chip starting address and the number of bytes are set by the user in hexadecimal format.

Now we will explain the specific operation process:

After the hardware linkage of the programmer and the single-board computer, the 2716 EPROM software we provide is plugged into the EPROM socket at address 0800H, a +5V power supply is added, then V_{DD} is added, and the single-board computer is reset. Then the operation process of the single-board computer programmer is entered.

I. Setting parameters: After your data has been loaded using the single-board computer's monitor program (when verifying and writing), on the basis of the above-described set parameter cell definitions, the parameters are set in accordance with your operational demands. After the parameters have been set, the chip is inserted, and the programming software is started in monitor state (initial address is 0800H), and the programmer carries out the functions defined.

First the programming software checks to see if the program chip has been inserted correctly (except for the 8755). If it is incorrect, a "0 10000" will be displayed at the indicator position and you will have to reinsert the chip after reset. If it is correct, then it checks to see if the number of bytes is within the range of the chip's capacity. If there is a capacity range error, then the corresponding indicator is displayed; if it is within the capacity range, then it carries out the operations you defined. In the process of operation, if an error occurs, the corresponding error indicator described above is displayed. If it is correct, the corresponding indicator described above is also displayed. When the error indicator is displayed, the EPROM address display portion will display correspondingly the address of the cell in error.

In the programmer's write process, it dynamically displays the programmed EPROM address.

II. When each function operation is concluded (a correct conclusion or an incorrect conclusion), the program automatically resets the programmer (which can also be reset to monitor state by using the single-board computer's reset button). After reset, the chip can be removed. Then in monitor state, your operations can be redefined and started.

V. Conclusion

Summarizing the above, the 8748/8741/8755 single-chip microprocessor programmer software and hardware and the MCS-48, UPI-41 cross-editing assembly language, have resolved the problem of programming the 8748/8749 and 8741/8742 single-chip microprocessors and the 8755 EPROM's and a method of programmed programming, and have resolved an urgent need in domestic scientific research and production. It passed appraisal in September 1984 and went into small batch production.

Through the development of this programmer, we feel that based on China's national circumstances the development tool which has powerful functions, is inexpensive and makes things flexible and convenient for the user has very practical significance. Therefore, we are further intensifying development of single-chip microprocessor emulators matched with it to provide better debugging techniques for developing applications single-chip microprocessors.

REFERENCES

1. Component Data Catalog Corporation, 1982
2. "MCS-48 Microcomputer User's Manual"
3. "UPI-41 User's Manual"
4. Li Benren and Gong Ganghua, "Mianxiang Mubiao Wenjiande Tongyong EPROM Xieruqi" [Object-file Oriented General Purpose EPROM Writer], XIAOXING WEIXING JISUANJI XITONG [MINI-MICROCOMPUTER SYSTEMS], No 4, 1983.
5. Li Benren, "Intel Danpian Weichuliqui Piancheng Gongju Yanzhi" [Development of a Programming Tool for the INTEL Single-chip Microprocessor], May 1984.

APPLIED SCIENCES

DIGITAL VOLTMETER TECHNOLOGY ACQUISITION

Beijing GUOJI MAOYI [INTERTRADE] in Chinese No. 3, 1985 pp 33-34

[Article by Chen Qilin [7115 0796 2651] and Cui Jianping [1508 1696 1627]]

[Text] China began its development of digital voltmeter at a fairly early stage. In 1965, the Beijing Radio Technology Research Bureau had already built a 5-digit voltmeter whose technical performance was comparable to the international standards at that time. However, at the present time, of the more than 50 models of 5-digit voltmeters produced by State-designated factories, only 2 or 3 use the IEC-IB international standard interface and microcomputer technology; further-more, due to the limited capability in processing, equipment and testing, they cannot be mass-produced. As a result, the gap between the Chinese standard and international standard in digital voltmeter is further widened.

In order to change the stagnant condition in the development and production of digital voltmeters in China, an effort was initiated in 1980 jointly by the Ministry of Electronic Industry Component Administration Bureau, the National Materiale Bureau No 1 Electro-Mechanical Department, the China Electronic Technology Import-Export Company, and other organizations in Beijing to import foreign technology. Specifically, after careful analysis and repeated comparisons and inspection tours, the Beijing Radio Technology Institute prepared a plan to import the manufacturing technology of the 8520A digital system multimeters from the U.S. FLUKE Co by using foreign exchange funds designated for mechanical and electrical instruments under the joint technology and trade program. In September 1981, an official contract and an agreement for technology cooperation were signed.

The items imported in the 8520A technology and trade program can be divided into 3 stages:

1. Import automated test and standard systems which are built using advanced technologies of the 1980's. Train personnel and begin SKD production.
2. Import key production equipment to coordinate with China's existing facilities. Modify the production lines based on FLUKE's advanced technology and begin CKD production.

3. Use the results of imported technologies in other research projects to stimulate development in related technologies.

The U.S. FLUKE Co is devoted to the research and production of electronic instruments. With 2,700 employees, it has an annual sale of 170 million dollars, and has more than 170 product types. In the mid 1970's, the FLUKE Co. invented the principle of remainder-recycle A/D conversion, and developed a series of unique high-speed (500 times/sec) and high-precision (5 PPM) digital system multimeters. During the 1983-1984 period, FLUKE's products accounted for 55 percent of the 180 million-dollar digital voltmeter market world wide. The 8520A is a product first marketed in the early 1980's. Its analog and digital sections are controlled by the 280A and 8048 microcomputers respectively, and its software is written in structural programming language. Its production process is under strict quality control, and its overall performance is considered to be the best of all the multimeters available today.

Being a late comer in dealing with this country and very anxious to get into the Chinese market, the FLUKE Co was willing to enter into a technology cooperation agreement, and transfer to us its manufacturing procedures and advanced technologies. This is the reason we chose FLUKE to be our technology trade partner and decided on the 8520A as our prototype product. Through the technology cooperation agreement, FLUKE's sale in China had multiplied; in 1984, it exceeded 5 million dollars, half of which was attributed to technology-trade products. On the other hand, as a result of the technology and trade cooperation effort, Chinese personnel have gained a much better understanding of the technical characteristics of FLUKE's products, and greatly enhanced FLUKE's reputation in China through advertisement of the cooperative products. Such introductions are much more effective than commercial advertisement or technical description of product performance.

In the interest of mutual benefits, the Beijing Radio Technology Institute and the FLUKE Co entered into a 4-year technology and trade cooperation agreement. During this period, the technologies of four different types of digital voltmeters have been imported, which resulted in significant technical, economic and social benefits.

1. Technical Benefits

During the period of the cooperative effort, 17 engineers from this Institute have received training at the FLUKE facility located in Everett, Washington; the FLUKE Co has assigned 7 engineers in 4 different groups to provide technical assistance at our Institute. Through training and personnel exchange, we have acquired nearly 200 documents on key technologies, advanced processes, and management procedures. This allows us to accomplish the following:

(1) quickly become proficient in the principle of remainder-recycle A/D conversion, the design of dual microcomputer systems, structural programming languages, and computer-controlled automatic tuning and testing procedures, thus raise our design standards into the age of the 1980's.

(2) solve the lingering problem of China's electronic industry. Through imported technology, we not only have mastered a complete set of FLUKE's advanced procedures and installed first-class equipment, but also have made significant progress in conceptual and theoretical understanding. For example, we have implemented quality-control measures such as static electricity prevention, cleaning of print boards, cyclic shock tests at high and low temperatures in order to effectively eliminate early component failures and improve the reliability of the overall product. These are problems which previously have not been studied in depth either in theory or in practice.

2. Economic Benefits

Under the 8520A technology and trade import agreement, and with the assistance from FLUKE, we had established plans for technological renovation. We spent only 460,000 dollars to import 133 units of sophisticated production equipment; at the same time, by making use of existing facilities, we spent only 125,000 yuan in factory remodeling, and built the first state-of-the-art digital volt-meter production line in China's electronic industry.

This production line was completed and began operation in August 1983. By 30 September 1984, it has produced 470 8520A units which met FLUKE's quality standards. Its customers are distributed over 19 provinces and cities, and it has been cited by the State for making important contributions to many engineering projects. Since production began a year ago, the acceptance rate of the 8520A unit has been maintained at 85 percent, and the number of units returned for repair has been less than 4 percent; new units and equipment have been 100 percent free of defects. Today the investments on imported equipment and renovation of domestic facilities have been totally recovered, and annual profits have reached 1 million yuan.

Furthermore, since the performance of Chinese-made digital meters failed to satisfy user requirements, each year the State had to spend large amounts of foreign exchange funds to import entire units. Now we are importing manufacturing technologies and CKS's of advanced products under the technology and trade cooperation agreement; based on the number of imported CKD's alone, the State can save nearly 1 million dollars. Also, the users are now protected by reliable maintenance and repair services and technical support, they no longer have to suffer the problems associated with the imported "Wan Guo" products.

3. Social Benefits

Importing the manufacturing technology of 8520A not only changed the backward status of technologies and procedures of this Institute but also promote the development of a series of related items such as welding aids, resistance welding flux, cleaning agent for wave peak welding machines, and foam materials used for packaging. By using the information and data provided by FLUKE, we have conducted tests of many chemical processes, 5 of which were successful, and two have been transferred to factories for use in actual production.

In an effort to familiarize the users with the operation of 8520A, we have conducted technical seminars around the country, invited users to visit our production line, and designed operating procedures for the users. These efforts have promoted technical advances in the areas of automated measurement and automatic control techniques for a variety of industries.

During the several years of cooperative efforts with FLUKE, we have learned the following:

The electronic instrument industry is a highly technology-oriented industry. It has a great variety of products which are relatively small in size but undergo rapid changes. To develop new products requires a large amount of investment and appropriate talents and policies; it also requires good foundation in chemical and metallurgical engineering. Therefore, by identifying a partner who is technologically advanced and willing to cooperate, by focusing on a prototype product which has the potential of bringing along other products, and by establishing the partner's confidence with large quantities of unit orders, we can enter into an agreement of technology and trade cooperation for the purpose of importing advanced technologies, advanced processes, and advanced equipment. This is a shortcut to building up China's electronic instrument industry; the success of importing 8520A is a very good example.

We also learned from the experiences and lessons over the past few years that technology and trade cooperation should not stop at the level of imported products, because what was originally advanced technology may become obsolete very quickly. On the basis of the imported 8520A technology, we have developed the baseline 8050A and the mid-line 8840A products; we are also planning to import the top-line 8506A. But these efforts only brought us close to the current world standards. To take the next step, we must rely on our own conviction and on the talents and intelligence of our own technical personnel; by seeking international technology cooperation on an even higher level, we can raise the standards of China's electronic instrument industry to the ranks of the developed countries.

3012

CSO: 4008/346

APPLIED SCIENCES

SUGGESTIONS FOR FURTHER APPLICATIONS OF HFETR IN CHINA

Chengdu HE DONGLI GONGCHENG [NUCLEAR POWER ENGINEERING] in Chinese Vol 6,
No 2, Apr 85 pp 44-49, inside back cover

[Article by Zhang Zhaoyuan [1728 5128 3293]]

[Excerpt] The main purpose of building HFETR in China is to develop power reactor fuel and material, and also to promote isotope production. Since the start of operation it has made significant contributions toward the above objectives. However, the current status of material and fuel research is less than satisfactory, and the high costs of fuel and operation adversely affect the production of urgently-needed isotopes. For this reason, we propose the following suggestions:

1. Concentrate on the Development of Irradiation Equipment and Circuits and Increase Efforts in Fuel and Material Testing.

The 500 kW high-temperature (350°C) and high-pressure (150 atmospheres) water circuit of the HFETR will be completed in the near future; it will provide an effective means for testing Chinese-built, small power plant components. This work is highly significant in the sense that it represents an independent effort by this country to surpass the advanced standards of other countries. China already has a large team of trained personnel in the design, manufacturing, testing, and inspection of fuel elements. Past accomplishments and technical expertise have demonstrated China's capability in producing components for nuclear power plants. As mentioned earlier, current efforts in other countries are concentrated on both circuits and equipment; because of the high cost of testing and the long testing time, there is a limit to the number of circuits that can be added, hence irradiation equipment appear to play a more important role. It is suggested that in HFETR, efforts be devoted to test irradiation equipment with respect to fuel power circulation, abrupt power surge, and transient power excess conditions. Work in this area is receiving a great deal of attention in other countries because it is closely related to the efficient operation of power plants. As the proportion of nuclear power plants increases, the power will increasingly fluctuate with load conditions. For example, it may operate at full load during the day, but only 40 percent of full load at night; in many instances it is during the change-over period that single-rod failures occur. Therefore, this research is highly significant in terms of establishing safety limits, developing the potential of fuel elements, and improving technical design.

Satisfactory results have been obtained in applying HFETR irradiation testing procedure to prototypes of pressurized containers used in China's power plants. Future efforts should be concentrated on extending the depth and breadth of this research; this implies developing irradiation tests based on fracture mechanics, which requires developing irradiation techniques inside the reactor and inspection procedures outside the reactor. In addition, activities abroad in developing new products of steel should be closely monitored so that a limited research and test effort can be carried out based on China's available resources.

2. Increase the Utilization Rate of Reactors by Alternating High-Power and Low-Power Operations.

Today, China's HFETR only operates 50-75 days under high-power conditions; the average consumption rate of fuel elements is around 40 percent. According to the results of nondestructive inspection of irradiated elements, they can be further exploited to raise the consumption rate to 45 percent under low-power conditions (e.g., at 3500 kW). Preliminary estimates indicate that these elements can continue to operate for an additional 3 months under low-power conditions; therefore, it is quite feasible to consider alternating high-power and low-power operations for HFETR.

Currently, many jobs can be done under low power. For example, in the production of isotope ^{99}Mo - ^{99}Tc "cow" for medical use, the half life period of ^{99}Mo is only 67 hours; therefore, the reactor must be operating continuously to provide a continuous supply of ^{99}Mo . In both the United States and Japan, ^{99}Mo is the number one isotope used in medicine. At present, we have successfully produced the ^{99}Mo - ^{99}Tc cow with a height ratio of 2 curie/g on the HFETR; this fills a void in China's current needs and builds the foundation for a promising future. Alternating high-power and low-power operations can also reduce the decay of height ratio C^{60} after the reactor is shut down. After several years of small-scale production of single-crystal with neutron mixing, it has established a good reputation with users; larger scale production can also be accomplished under low power. Of course, to implement alternating high and lower power operation in the same reactor will lead to difficulties because of the complicated targets or irradiation equipment and inverted positions. But these problems can be solved by a balanced approach; for example, high-power operation may be in effect during the first few months of the year, and low-power operation will be in effect the remainder of the year.

3. Explore Our Potential Resources to Increase the Production of C^{60} .

With the HFETR in operation, a matching production line of C^{60} with annual productivity of 1 million curie has been constructed; it includes two large rooms with a capability of producing 100,000 curie, and a modular laboratory with a 100,000-curie inverted source. These facilities have provided a large number of high-quality products for China's medical, industrial, agricultural, and scientific applications in recent years. To satisfy the needs of the four modernization program, C^{60} is being used extensively in

such areas medicine, food processing and preservation, polymer modification, and industrial inspection of defects; as a result, the current supply of cobalt cannot meet the demand. One may ask why not install additional cobalt targets in HEFTR? The answer is simply that additional cobalt targets require additional uranium fuel elements which are very expensive. Therefore, a balanced approach must be taken.

The Osiris Reactor of France has six compensation rods and its backup reactivity is 15.6 percent. The compensation rods are made of small cobalt plates packed in a metal container; the cobalt plates can be retrieved after certain period. The HEFTR in this country operate mostly under small load conditions without reactor circuits. The reactors also have six compensation rods and the backup reactivity is also around 15 percent; the useful neutrons are absorbed by the Ag-In-Cd compensation rods. Based on the operation of these reactors, two of the rods remain in the active region 75 percent of the time; therefore, these two rods can be converted to cobalt rods.

4. Promote Research on Low Concentration Fuel for HEFTR.

There is currently a wide-spread trend in other countries to study the use of low-concentration uranium as the primary source of reactor elements. It is predicted that by 1986, most reactors will be modified to use low-concentration uranium. In this country, the high cost of fuel elements is the main limitation for further utilization of reactors; therefore, future efforts must be centered around reducing costs. However, whether it is possible to achieve cost reduction is a controversial issue; [the table below] shows a comparison of the operating costs between high-concentration and low-concentration uranium. The calculation took into account such factors as the price of high and low concentration uranium, the manufacturing cost, the transportation cost of needed components, and the post-treatment cost (for instance, more complete burning of the elements can reduce the number of times of post treatment).

Table. Comparison of the Economy of High-Concentration and Low-Concentration Uranium Cores for a 10 Megawatt Research Reactor.

Type of fuel	U-Al Alloy	UAl _x -Al	U ₃ O ₈ -Al	U ₃ Si-Al	U-ZrHx	UO ₂ plate
Concentration %	93	20	20	20	20	6.5
Geometric Shape of Element	Plate	Plate	Plate	Plate	Rod	Plate
Operating cost (per MW, in 1000 U.S. dollars)	155	176	133	114	128	172-287

It can be seen from the table that an outstanding fuel type is the aluminum base uranium silica, whose operating cost may be reduced by a factor of 30 percent. Some organizations in this country are already doing research in the manufacturing technology of uranium-aluminum base diffuse fuel plates; they indicate that such technology has already reached a mature level. As mentioned in the previous section, in the process of changing to low-concentration elements in other countries, the geometric shape of the elements essentially remains the same. Thus, the problem is considerably simplified because all the tools used in reactor physics, thermal hydraulics, control, and operation remain unchanged. However, the HFETR in this country uses tubular type elements. Therefore, it is suggested that research efforts be initiated to study the manufacturing of tubular type U_3Si-Al elements; Also, radiation experiments should be carried out and economic analysis based on China's current conditions should be performed. Furthermore, the current fuel element technology is to use joint-pressed ribbed tubes; each tube has three positioning ribs. The presence of ribs lowers the productivity of the elements (raises the cost), and leads to increased core thickness beneath the ribs. The current trend in other countries is to build joint-pressed rib-less tubes. It is suggested that this new technology should be considered as part of the effort of switching to low-concentration uranium elements.

3012

CSO: 4008/368

APPLIED SCIENCES

WINGTIP SAILS TESTED ON Y-5 AIRCRAFT

Beijing GUOJI HANGKONG [INTERNATIONAL AVIATION] in Chinese No 5, May 85 pp 2-3

[Article by Yang Daxi [2799 1129 8408]]

[Text] In recent years, much attention has been given to the use of wingtip ailerons or wingtip sails to reduce induced drag because for most transport airplanes, the induced drag at cruising speed is approximately 30 percent of the total drag; at lower speeds the ratio is even higher. For the Y-5 bi-plane, the induced drag to total drag ratio is approximately 55.6 percent, at cruising speed the ratio is approximately 33 percent, and during climb it is 58 percent. Therefore, wingtip ailerons or wingtip sails potentially can be very effective in reducing the overall drag of the aircraft. Since a large number of Y-5 airplanes are used in this country for a variety of applications, a research program was initiated in August 1982 to install and test wingtip sails on the Y-5 aircraft.

Design and Installation of Wingtip Sails

Based on foreign wind tunnel and flight test results, and taking into consideration the design features of the Y-5 aircraft, we have designed a sail with the geometric shape shown in Figure 1. The length of the sail is 24.5 percent c (wing chord), the base chord length is 16 percent c , and the leading edge backsweep is 21° . In order to delay flow separation at the base, the forward section of the sail has a large camber and twist, so that the flow along the entire chord length of the base gradually turns in the free stream direction, thereby minimizing the peak value of the pressure distribution. Therefore, the mean chord of each cross section of the sail is a circular arc; and when the angle of attack of the wing is positive, the tangent to each mean chord at the leading edge of the sail approaches the local flow direction. Based on results of experimental optimization, we have selected the subtended angle between the tangent lines of the leading edge and trailing edge at the base to be 20° . This angle decreases sharply with increasing distance from the base (for an increase in distance corresponding to 6 percent of the wingtip chord length, the angle decreases by approximately one half); thus, the camber and twist of each cross section of the sail decreases from the base toward the tip. The airfoil type of the sail is NACA 0012. Test results show that best results of induced drag reduction are obtained by using three pieces of sails; increasing the number of sails further provide very little additional

advantage, and lead to higher structural weight. Therefore, on each of the wingtips of the Y-5 aircraft are installed three sails. The leading edge of the forward sail is located at 36 percent c from the leading edge of the wing. Relative to the plane of the wing chord, the forward sail has a dihedral of 30° , the mid sail has a dihedral of 15° , and the aft sail has an angle of 0° . Such a configuration can change the local flow direction, straighten the vortex flow around the wingtip into nearly straight stream lines, and generate a thrust component. The sails are rigidly attached to a 2.18m long cylinder; the tail end of the cylinder is tapered in the form of a parabola. The cylinder is attached to the wingtip in a "glove" configuration; its axis is parallel to the wing chord, and 63 mm higher than the wingtip chord line. The layout of the sails on the aircraft wing is shown in Figure 2. The wing configuration with the sails installed is shown in Figure 3.

Flight Test Results

Since October 1982, we have conducted flight tests on the No 8077 Y-5 aircraft with and without the wingtip sails. They included tests under the following conditions: take-off, climb, high-speed level flight, cruise, 45° -slope flight, drift, loss of speed, side slip, glide, low altitude pull-up, and landing. To evaluate the fuel savings, we also conducted repeated flight tests between Shanghai and Hefei. Considering the fact that the reduced strength of the wingtip vortices may improve the uniformity of the sprayed materials and reduce the scattering area, we have also conducted numerous tests of powder and liquid sprays.

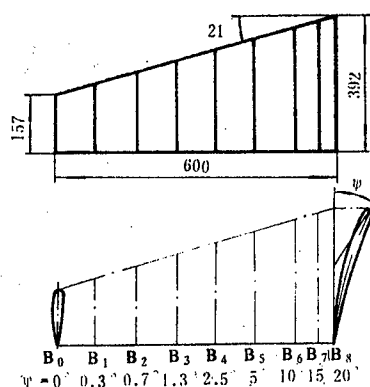


Figure 1. Geometric Features of the Wingtip Sails

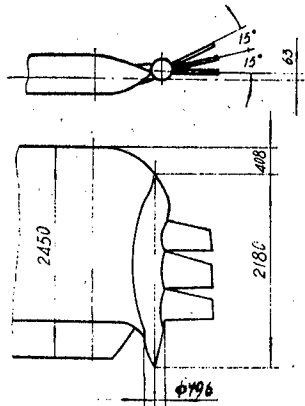


Figure 2. Layout of the Sails on the Aircraft Wing
(units are in millimeters)



Figure 3. The Y-5 Aircraft Equipped With Wingtip Sails

The results show that the use of wingtip sails indeed improved the performance of the Y-5 aircraft. Under the conditions of a gross weight of 4,740 kg, cruising speed of 200 km/hr, and lift coefficient of 0.3436, the wingtip sails reduced the total drag by 4.31 percent, and the induced drag by 22.8 percent.

In the following table, flight test results are presented by converting the data to standard atmospheric conditions. It shows that under full load conditions (5,250 kg), the climb rate is increased by 29 percent, a significant improvement.

Table. Improvement in the Performance of the Y-5 No 8077 Aircraft Equipped With Wingtip Sails

Aircraft 8077	W = 4000 kg		W = 5250 kg	
	Degree of improvement		Degree of improvement	
	Increase (%)	Decrease (%)	Increase (%)	Decrease (%)
Maximum level-flight speed	1.8		1.9	
Cruising speed	2		2.4	
Rate of climb	8.7		29	
Climb time		8		22.5
Glide rate		11.1		8.3
Glide time	12.4		9.1	

Flight test results also show that the ceiling of the aircraft increased by approximately 1,000 m after installation of wingtip sails. This is very important for operation over high elevation terrains. According to performance calculations, under cruise conditions, if the horse power parameters are kept unchanged (i.e., engine speed 1,700 rpm, intake pressure 700 mm Hg), the use of wingtip sails can result in a fuel saving of 2.0 percent; if the cruising speed is kept unchanged, a fuel saving of 4.58 percent can be achieved. Flight test results show that the former is 2.5 percent and the latter is 5.1 percent, both of which exceed predicted values. The spray tests also show that with wingtip sails installed, the area of coverage is increased and the sprayed materials are lower and more uniform. Figure 4 shows the measured overall uniformity of sprayed particles during three spray tests with and without wingtip sails.

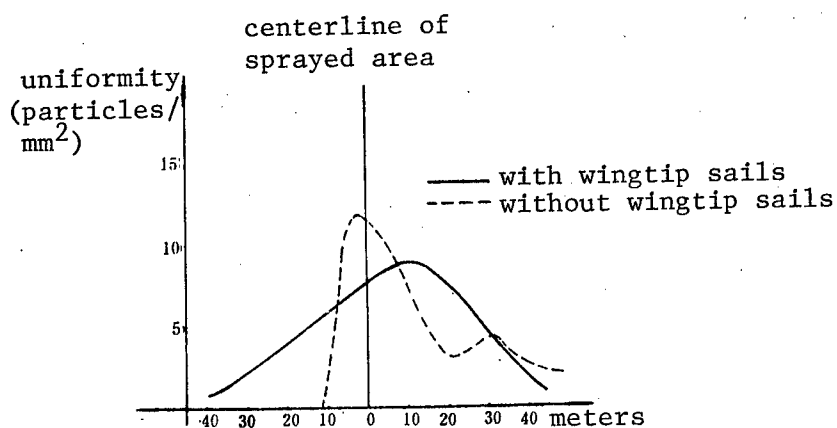


Figure 4. Overall Particle Uniformity During Three Spray Tests With and Without Wingtip Sails on the No 8077 Aircraft

In addition, according to reports from the test pilots, the aircraft equipped with wingtip sails is easier to maneuver, more responsive, and is more stable and easier to control during steep glide or sideslip flight. Since April 1983, the No 8077 aircraft equipped with wingtip sails has flown over 320 hours during routine flights, training flights, and actual operations. It has been shown that the improvement in flight performance is in agreement with flight test results. In November 1984, wingtip sails were installed on another Y-5 aircraft, No 8242, which had passed the certification flight tests of the Civil Aviation Bureau, and thus convincingly proved the effectiveness of wingtip sails.

3012

CSO: 4008/367

TRENDS IN PHARMACOLOGY DISCUSSED

Beijing YAOXUE XUEBAO [ACTA PHARMACEUTICA SINICA] in Chinese No 2, 29 Feb 85
pp 81-83

[Article by Zhou Jinhuang [0719 6855 7806], of the Institute of Pharmacological and Toxicological Research, the Military Academy of Medical Sciences, Beijing: "Trends in the Development of Pharmacology in China"]

[Text] I. Characteristics of Pharmacological Development in China

China is a nation with an ancient cultural tradition that has made many major pioneering contributions to human civilization and progress. Our study of medicine and pharmacy is one of these. For several millenia traditional Chinese medicine and pharmacy formed an independent, integrated philosophical and ideological system of their own that guided the clinical practice of medicine and pharmacy in China. Over a very long period of time traditional Chinese medicine and pharmacy continued to advance and develop, absorbing a great quantity of drugs from abroad in its international contacts. These supplemented our drug sources and enriched our traditions. Particularly in the past few decades, traditional Chinese medicine and pharmacy has coexisted with modern medicine and pharmacy, each permeating the other, and this has brought progress to traditional Chinese medicine and pharmacy. This is the developmental foundation and background of modern pharmacology in China.

Since Western medicine was brought into China it has produced an enormous transformation in the development of medicine in China. Western medicine and pharmacy occupy a distinctly dominant position in China's medical, pharmaceutical and health facilities. In the wake of the growth of modern natural sciences, medicine and pharmacy, we should continue to strengthen and pay close attention to the development of modern pharmacology.

The state of development of traditional Chinese medicine and pharmacy facilities has obviously progressed since the initial period after the founding of the People's Republic of China, but generally speaking our development has been slow, manpower has been weak and the level has been low. Compared with Western medical and pharmaceutical facilities, there is a definite disparity. From a historical and background perspective there have been extremely advantageous conditions for pharmacological research into traditional Chinese medicine, but, following from the complex demands of modern

science, there have also been many more difficulties by comparison with pharmacological research into synthetic medicines. Consequently, pharmacological workers in China bear dual responsibilities: on the one hand they must catch up to the level of contemporary international pharmacology, and at the same time they must strive to improve the level of traditional Chinese pharmacology. This will allow pharmacological development in China to have a Chinese character, and it will form a consistent and integrated Chinese and Western pharmacology.

II. Major Progress in Modern Pharmacology

From the perspective of pharmacological development, 20th century pharmacology can be divided into two stages. The prominent development in the first half of the century was the growing independence of pharmacology from clinical medicine and therapeutics and its establishment as one major branch of basic experimental medical science. Physiology, pharmacology and pathology helped each other forward and laid a foundation for modern medicine. They developed the new substance of microbiological medicine and by degrees intensified into a new molecular-level discipline. However, they correspondingly neglected the whole, complete nature of the human being and the integrated functions of his various systems, so that experimental pharmacology and clinical therapeutics nearly lost touch with each other. Since the 1950's the prominent development in pharmacology has been a new stage of integration with clinical medicine and the emergence of clinical pharmacology. In the past 30 years clinical pharmacology has grown rapidly and an intimate relationship has grown up between basic pharmacology and clinical applications. In addition the mutual integration of clinical pharmacokinetics and clinical pharmacodynamics has guided the program for clinical drug use. This turning point in the history of pharmacological development points out that we should re-appraise China's pharmacological education and scientific research program so that pharmacology will further develop toward clinical application. In order to spur the development of clinical pharmacology, pharmacological education is imperative. Pharmacology should be divided into basic pharmacology and clinical pharmacology, and there should be a further differentiation between educational grades so that the pharmacological contingent in China will be further specialized.

1. The Integration of Clinical Pharmacokinetics and Clinical Pharmacodynamics

Within pharmacological research in China, work in pharmaceutical metabolic dynamics was launched rather late and there are not many pharmacological personnel engaged in work in this area. At present the emphasis is on studying drug distribution, absorption, excretion and blood concentration within the bodies of animals, whereas clinical pharmacokinetic research is very meager. There is quite an obvious difference between animals and human beings in terms of pharmacodynamics; yet some regular patterns of pharmaceutical effects in humans have already been worked out by inference from animal experimentation. Drugs with different types of chemical structures have different patterns that they may follow, but ultimately they must still undergo clinical pharmacodynamic research and observation. In pharmacokinetic work the differences between animals and human beings are even more obvious. At present

we have not yet accumulated sufficient data from animal experimentation to infer regular pharmacokinetic patterns for human beings. Consequently, the development of clinical pharmacokinetic research should be the major order of the day in clinical pharmacology.

Pharmacokinetic research should be integrated with pharmacodynamic analysis because pharmacokinetics is one of the major foundations aiding clinical physicians in their assessments of pharmacodynamics. The determination of drug concentrations in a patient's blood is significant for guiding the use of drugs in clinical treatment. Right now this is considered to be an indispensable index.

2. New Drug Discovery and Evaluation

In this century, pharmacology and pharmacchemistry have cooperated closely and developed hundreds of specific drugs. This has made an enormous contribution to clinical medicine and experimental research, and is one of the most prominent achievements of modern pharmacology. Pharmacology has already developed away from studies of the active mechanisms of known drugs, toward a new phase of emphasis on research into new, unknown drugs. Development of a new drug begins with laboratory research, develops into preclinical research and later proceeds to clinical trial studies. Finally, it undergoes a new drug assay, observation of clinical application is expanded, experimental data is supplemented and long-term clinical safety and curative effects are evaluated. New drug development is a burgeoning enterprise association of the chemical industry and medicine. According to statistics from outside of China, development of a single new drug of clinical value requires a great deal of manpower, technical equipment, scientific supervision and economic information. In addition, it costs 10 million yuan and must undergo many years of study before it can be selected from among a large number of chemical compound candidates. In capitalist nations the discovery of new drugs is already undertaken primarily by pharmaceutical plant research institutes, with university pharmacological and pharmacochemical teaching and research sections and clinical hospitals playing supporting roles.

The source of new drugs is primarily synthetic drugs: thousands of new compounds can be synthesized annually. Pharmacology labs in pharmaceutical plant research institutes conduct all sorts of biofunction screening studies on new chemical compounds in an attempt to discover prominent new functions among them. According to many years of experience in England, the United States and other nations, of 5,000 to 10,000 new chemical compounds, pharmacological screening and initial toxicity determinations weed out all but maybe 10 of them that reach the trial candidate phase and are immediately entered into preclinical research. Of these 10, there may be 1 that is selected which achieves the safety requirements and curative appraisal level for a new clinical drug and can be put into production and tried out in applications on an expanded scale. In Europe, the United States and other nations there may be tens of new drugs each year. According to recent statistics from England (from the early 1980's) there are 15-20 new drugs that can be marketed each year. From initial research to establishment as a new drug that is advantageous to pursue, each drug costs an average of 17 million

pounds (approximately 35 million dollars). The pharmaceutical plant must make a great effort at publicity if it seeks to reap high profits within the patent period (generally 10 to 15 years). Otherwise, there is strong competition in the market for new drugs, the rate of competitive elimination is high, the new drug cycle is short and there are circumstances like the fashionability of competitive development to consider.

Our pharmacological workers should not pursue new drugs blindly; they must both acquaint themselves with reports on pharmacological functions and clinical effectiveness in various areas, and they must also analyze defects to make an objective and reasonable appraisal. The number of good, truly tenable new drugs is quite small, and each without exception has its own characteristics.

Based on our own reported experiences and literature, research into new drugs demands coordination among many areas. Abroad, pharmaceutical sources come from many areas. In addition to synthetic drugs, in recent years there has also been a great emphasis on botanical and biological drug sources, including active peptides, polysaccharides, bacteria and vaccines. Purposes differ for the development of Chinese traditional medicines abroad. Japan attaches significant importance to traditional Chinese medical prescriptions and tends to vie strongly with China in the international market for them. Some nations study Chinese drugs as natural botanical products, and their achievements have not been at all prominent. China's development of traditional medicines embodies both the aspect of inheritance and that of the development of new drugs. According to reports, in the past 35 years an average of 2 to 5 kinds of new drugs have been marketed annually. This is vastly inferior to the success rates abroad, yet these achievements have not come easily. In the wake of an increase in China's scientific research personnel and a gradual improvement in their level, our new drugs, particularly those developed from traditional Chinese medicines, will proliferate.

The supply of drug sources depends upon pharmacochemistry (synthetic chemistry), phytochemistry (for extracting generally effective components and monomers) and analytical chemistry (to determine component specifications). At the same time, new pharmaceutical trends, intelligence data and analysis, market news and patent information on similar drugs must be taken into consideration in order to decide whether to invest in research and set up a research program. In large, modern pharmaceutical plants experimental pharmacological research is conducted separately in certain research labs. For example, general studies of pharmacological effects, toxicology and pharmacodynamics; pathologic model studies; and specialized research into such areas as antibiotics, antiparasitics and immunity are conducted separately. Some pharmacological studies of new synthetic drugs follow a set screening plan and some screen for similar universal properties and apply tens of indices to the task. Directed screening and extensive screening both require a search for new types of compositions that are low in toxicity, strong-acting and have concentrated curative effects. Generally speaking, new drugs must possess certain outstanding properties such as low toxicity and low production costs. When compared with known drugs, if the new drugs

can be used as substitutes they can become candidate drugs. New drugs that lack obvious advantages can all be eliminated.

If a new drug indicates a transitional nature in preclinical studies, it is both plunged into substantial experimental research and preparatory clinical research is launched simultaneously. This stage may be long or short, but gradually develops toward clinical applications. Now every nation has various rules and restrictions concerning new drugs. We believe that we should have new-drug development stipulations that conform to China's realities. There should be differences between the requirements for synthetic drugs and for traditional Chinese medicines.

3. Progress in Combined Chinese and Western Medical Research on Traditional Chinese Medicine

Research into traditional Chinese medicine has a distinctive style by comparison with research into synthetic drugs or Western medicine. Traditional Chinese medicine is good medicine that has undergone repeated screenings and comparisons by skilled clinical doctors and apothecaries through many years and successive dynasties and has been retained and passed down to us by our forefathers. Although China boasts many varieties of traditional prescriptions, they are without exception classically renowned for their originality: this is the precious heritage of our nation. The clinical curative effects and usefulness of traditional Chinese medicine has long been confirmed. This is a favorable factor that is not shared by research in synthetic drugs or bioactivated natural drugs. The study of Chinese medicines can neither disregard traditional experience nor should it be constrained thereby. Our research goals are to develop traditional Chinese medicine, make it more beneficial to the national economy and the people's livelihood, improve its curative effects, expand the objects and range of its uses and improve the modern scientific level of Chinese medicine and pharmacy. In the past few years we have achieved many notable successes, and some of the experiences are worth expanding upon. The example of the traditional Chinese medicine cattail pollen and prescription laughing powder will illustrate the advantages of combining Chinese and Western medicine to study traditional Chinese medicines:

Chinese laughing powder is an effective prescription composed of two medicinal ingredients, cattail pollen and *Trogopterus* dung, used for invigorating vital energy and blood circulation, as well as for curtailing various pains. Since the Tang and Song dynasties it has been recorded by skilled doctors and scholars of Chinese materia medica (in the "Hejiju Fang" [Dispensary Prescriptions] of the Yuan dynasty and the "Bencao Gangmu" [Compendium of Materia Medica] of the Ming dynasty). The 1977 edition of the "Zhongguo Yaodian" [Pharmacopoeia of China] also lists it as a commonly used prescription. The most recent edition (1983) of the "Zhongyao Yaoli Yu Yingyong" [The Pharmacology and Applications of Traditional Chinese Medicine] enumerates in detail the multifaceted pharmacological actions and clinical curative effects of cattail pollen and laughing powder.

Since the 1970's the extensive nationwide development of research into prescriptions for drugs to prevent and treat coronary heart disease and hypertension has achieved great success. The theoretical basis for this is the holistic diagnosis by traditional Chinese medicine that angina pectoris in coronary heart disease belongs to the category of "chest obstructions" and "heart pains," usually arising from "blood stasis due to stagnation of vital energy" and treated according to the principle of "vital energy normalization and blood invigoration." In clinical practice at various locales workers in combined Chinese and Western medicine separately compounded many new complex prescriptions that had relatively high curative effects. Step by step they refined various monomers with excellent effects, such as Radix Salviae Miltorrhizae ketones, Rhizoma Ligustici Chuanxiong piperazines, Radix Salviae Miltorrhizae elements and so forth. Some units (in Shanghai and Changsha) separately studied laughing powder and cattail pollen, discovered that they are distinctly effective against cardiovascular disease and verified their pharmacological effects on animal pathologic models. The Hunan Institute of Traditional Chinese Medicine continued the probe and discovered a component in cattail pollen extract that lowers plasma cholesterol and reduces triglycerides, as well as a component that protects the blood vessels of the heart and prevents zhouyanghua bingbian [4728 2876 0553 4016 6239]. These research achievements (of which a corresponding portion have not yet been reported, as some still require continued intensive research) have brought Chinese pharmacology, pharmacochemistry and biochemical pharmacology, as well as clinical pharmacology and clinical therapeutics, to an advanced international level in the field of anti-hyperlipoidemia research. They are highly effective, low in adverse reactions, convenient and easy to use. These achievements have relatively numerous advantages when compared with the Western drugs niacin and clofibrate ethyl p-chlorophenoxyisobutyrate (atromid-S) that are now being appraised in the literature abroad.

In addition to lowering blood-fat, cattail pollen also increases the quantity of blood flow in the coronary artery, augments anti-myocardial ischemia and anoxia endurance functions, lowers blood pressure, lowers peripheral vascular resistance and improves circulation. These effects are beneficial in the treatment of coronary heart disease and other cardiac vascular diseases. The effects of cattail pollen are multifaceted: it has an antioncotic effect on experimental arthritis, and it also has the effect of suppressing the immune functions, lowering the rates of thrombocytic adherence, lengthening the clotting time and so forth. This supplies a pharmacological foundation for traditional Chinese medicine with respect to "blood normalization and blood stasis." Thus it can be seen that traditional Chinese medicine has come to recognize the properties of Chinese drugs through a long period of clinical practice. These "medical properties" embody the concept of pharmacology. The ancients were good at summarizing and inducing medical properties and holistic clinical diagnoses, and modern medicine verifies on many fronts that their generalities are scientific.

To sum up, through research in combined Chinese and Western medicine, experimental pharmacology and clinical pharmacology and therapeutics are integrated together, phytochemistry is integrated with pharmacochemistry and pharmacology and studies of compound prescriptions are integrated with studies of

single ingredient drugs. In particular, the simultaneous implementation of research in traditional Chinese pharmacology and in clinical effects is the most efficacious research path. This path has not only been completely positive with respect to research on cattail pollen, but it has also been affirmed in studies of many traditional Chinese drugs in recent years and in its adherence to the process of integrating traditional Chinese and Western medicine. Hereafter, in our research on traditional Chinese medicine we will see a new phase of mutual permeation between it and research on new drugs. The background for this is vast, and China's pharmacological workers can carry on and continue to enhance the precious intellectual wealth of our ancestors. This is an undertaking which makes us proud.

12510

CSO: 4008/332

BRIEFS

MORE DRUG INSPECTORS URGED--Beijing, July 1 (XINHUA)--Public Health Minister Cui Yueli has called on all local authorities to set up inspection agencies to implement strictly the new pharmaceutical management law which takes effect from today. At present, only 800 of China's 2,100 county authorities have such inspection teams. In an article in Sunday's "Health News" daily, Cui said the establishment of agencies at various government levels was vital if the new law was to be effective in protecting the public from poor medicines. He also called on the industrial and commercial administrative, legislative, and trade departments to monitor the implementation of the law. Meanwhile, the XINHUA commentator commented that the quality of pharmaceuticals must be guaranteed, and anyone making or selling shoddy medicines must be punished. [Text] [Beijing XINHUA in English 0819 GMT 1 Jul 85]

5300/12

TITLES OF SELECTED PAPERS FROM THE SIXTH NATIONAL CONFERENCE ON INFRARED
SCIENCE AND TECHNOLOGY

Shanghai HONGWAI YANJIU [CHINESE JOURNAL OF INFRARED RESEARCH] in Chinese
Vol 4, No 2, Apr 85

[Text] A. Searching and Tracking (16 papers):

- A1 Development of Modulating Frequency Infrared Tracking and Sounding System
by Shi Meiyao [0670 5019 5069]
- A2 Analysis of Phase Frequency Characteristics in Intermediate Links of
Modulated Amplitude Type Infrared Angle Tracking System
by Hu Gongxian [5170 0501 6902]
- A3 Study of Interference Noise of Optical Tracking Gyroscope System
by Chen Zujin [7115 4371 6855]
- A4 Interference and Restraint on Infrared Search System
by Sun Shaoyou [1327 1421 0645]
- A5 Design and Application of Mangin Mirror in Infrared Tracking Optical Sys-
tem
by Yu Yanfang [0827 1177 5364]
- A6 Selection of Spectral Wave-Band of Middle Infrared Guidance Head
by Lu Mingyi [0712 2494 5030]
- A7 Characterization Parameters of Single-Channel Infrared Guidance System
by Zhou Xiaodong [0719 2556 2639]
- A8 Testing of Static Parameters of Infrared Tracking Device
by Xu Zhongren [6079 0112 0088]
- A9 Infrared Simulation System
by Wang Jianji [3769 1696 1015]
- A10 Characteristics of Simulation, AGC and Phase-Amplitude of Infrared Sig-
nals--Application of Integrated Multiplier in Infrared Tracking System
by Zhong Junyi [6945 0193 5030]

- A11 Consideration of False Alarm Rate and Wave Form Conversion Coefficient in Infrared Tracking System by Ye Feng [5509 2800], Xue Tianzhu [5641 1131 2691] and Jiang Yanfa [1203 1693 4099]
- A12 Development of Low Noise Amplifier in Infrared Tracking Device by Gui Yonghua [2710 3057 5478]
- A13 Principle and Application of Automatic Search by Gyroscope Guidance Head by Yang Jisheng [2799 0679 5116]
- A14 Problems in Image Guidance by Yang Yihe [2799 1355 4421] and He Bin [0149 3453]
- A15 Interference and Suppression of Noise in Small Infrared Guidance Head by Li Jinze [2621 6855 3419] and Liu Guizhi [0491 2710 2655]
- A16 Study on Enhancing Error Characteristics of Infrared Conical Scan System by Jin Tongluo [6855 2717 2867] and Kang Dajing [1660 1129 4842]
- B. Infrared Imaging (21 papers):
- B1 Determination of Parameters of Probe in Infrared Optical Device Scanning System by Zhang Dexin [1728 1795 2946]
- B2 Consideration in Design of Infrared Thermal Imagery System by Zhang Ronghua [1728 2837 5478]
- B3 New Application of Optical Computation Program of Nonspherical Noncoaxial System by Zhao Xiuli [6392 4423 7787]
- B4 A Frame Raster of Optical Thermal Imagery Instrument by Li Yi'an [2621 5030 1344]
- B5 Analysis of Reference Bandwidth and Sensitivity of Parallel Scan Infrared Imagery System by Zhang Xiaolin [1728 1321 7207] and Shu Yuwen [5289 6735 3429]
- B6 Development of Microcomputer System of Thermal Imagery Instrument by Yu Qihua [6735 0796 5478]
- B7 Simulation Real-Time Processing of Images by Thermal Imagery System by Zhang Wensen [1728 2429 2773] and Zhang Xiaolin [1728 1321 7207]
- B8 Linear, Nonaxial Out-of-Focus Convergent Beam Scanner by Zhao Jiaqi [6392 1367 3825]
- B9 Theoretical Calculations of Optical Scan System in Infrared Thermal Imagery Instrument by Hu Yuxin [5170 5148 2946]

- B10 Digital Display of Temperature Measurement of Sampling Points of Thermal Imagery Instrument by Kong Musheng [1313 3092 3932] and Du Fang [2629 5364]
- B11 Automatic Polarizing Circuit by Cai Dezhong [5591 1795 1813] and Ye Xiulan [5509 4423 5695]
- B12 Multi-Field Averaging Technique of Thermal Relief Electric Sampling Signal by Lu Yimin [4151 4135 3046]
- B13 PEV Alarm With Microcomputer Processing by Ye Xiulan [5509 4423 5695], Shi Xiaoyang [4258 2556 7122], Wang Zuxi [3769 4371 0823], and Wang Yongkang [3769 3057 1660]
- B14 Analysis on Conversion Method and Accuracy of Temperature Measuring Signals in Infrared Television by Wu Kangyin [0702 1660 1377] and Lu Yimin [4151 4135 3046]
- B15 Study of Thermal Image of Stainless Steel in Its Deform Process by Huang Yi [7806 3015], Li Shouxi [2621 1343 2450] and Shi Changxu [1597 2490 4872]
- B16 Application of Infrared Thermal Imagery in Nondestructive Inspection by Kong Youlin [1313 2589 2651]
- B17 Study on Adjustment and Testing of Thermal Imagery of Large Black Body Isothermal Belt of Earth Simulator by Xu Jun [1776 6511], Lin Xuerong [2651 7185 2837] and Huang Yi [7806 3015]
- B18 Analysis of Modulation Transfer Function of Electric Charge Coupling Imagery Device by Zhang Hegang [1728 6378 6921]
- B19 Simulation on Study of Target Energy and Temperature Characteristic With Application of AGA-780 Thermal Imagery Instrument and Computer Processing Method by Guo Baoshan [6753 1405 1472] and Wang Tinghui [3769 0080 1979]
- B20 Thermal Image Study of Strain Process of Plastics and Fiber Reinforced Plastics by Hu Wenyou [5170 2429 0645], Guo Baoshan [6753 1405 1472], Hou Qiuping [0186 4428 1627], Wang Xun [3769 6598], Lu Xinian [4151 6932 1628] and Jiang Canxing [5592 3503 5281]
- B21 Discussion on Overscan Technique as Applied in Infrared Imagery System by Yang Yinghuai [2799 2019 2849]

- C. Infrared and Multispectral Remote Sensing (19 papers):
- C1 Application of Multispectrum Scan Images in Remote Sensing Test at Tou River Reservoir
by Li Chengzun [2621 2052 1415], Wang Zhimin [3769 1807 3046] and Li Jinghua [2621 2529 5478]
 - C2 DGS-1 Type Aviation Multispectrum Scanner
by Xue Yongqi [5641 3057 3825], Sun Jixiu [1327 4480 0208] and Wu Changyong [0702 1603 3144]
 - C3 Small Multispectrum Scanner
by Zhang Renchu [1728 0088 0443]
 - C4 Reception Sensitivity and Orbit Selection of Satellite-Borne Multispectrum Scanner
by Gu Yonghua [7357 0516 5478]
 - C5 Satellite-Borne Multichannel Infrared Radiometer
by Chen Yuewu [7115 6460 2976], Xiang Shaojun [0686 4801 0689], Ma Yanhua [7456 1693 5478], Nan Jiafu [0589 1367 4395], Xu Xiujuan [1776 4423 1227] and Li Jihong [2621 4949 4767]
 - C6 10.6 μ m Astronomical Heterodyne Spectrometer
by Yu Yinshan [0151 0692 1472]
 - C7 Design of Simulation Circuit in Infrared Spectrometer
by Wang Mochang [3769 2307 2490]
 - C8 Data Collection and Control System for Radiation Target Acquisition of Satellite-Borne Infrared Remote Sensing Instrument
by Gong Huixing [7895 1920 1472], Zhang Jianxin [1728 1696 2450] and Li Liangxin [2621 5328 2450]
 - C9 Application of Single-Board Microcomputer on Infrared Spectrometer
by Wang Mochang [3769 2307 2490]
 - C10 Design of Oscillating Mirror in Satellite-Borne Multispectrum Scanner
by Qian Honglin [6929 7703 7792], Ji Meidi [1323 5019 1229] and Liu Zhengxing [0491 2973 5281]
 - C11 Design and Adjustment of Dynamic Equilibrium of 45° Rotating Scanning Mirror
by Wang Genbao [3769 2704 1405] and Hao Jingyu [6787 2529 3842]
 - C12 Determination of Characteristic Parameters of Infrared Multispectrum Row Scanning Imagery System
by Huang Keyi [7806 0344 5030] and Chu Jiadong [5969 1367 2767]

- C13 Infrared Modulator as a Testing Device for Studying Characteristics of Infrared Data Processing System
by Lu Xuerong [6424 1331 2837]
- C14 OTF Determination of Infrared Optical System
by Chu Jiadong [5969 1367 2767] and Huang Keyi [7806 0344 5030]
- C15 Design Features of VHRR Signal Processing Device
by Weng Chuijun [5040 0987 0193]
- C16 Processing and Effect of Digital Images of Infrared Message
by Shi Jiyuan [4258 3444 0337]
- C17 Application of Fourier Transform Infrared Spectrograph in High Altitude Sounding
by Dong Junyi [5516 7165 6654] and Li Zhengzhi [2621 2973 4160]
- C18 Use of Accumulation Method for Enhancing Discriminability in Infrared Remote Sensing System
by Lu Jiachang [7120 1367 2490] and Li Zhengzhi [2621 2973 4160]
- C19 Analysis on Characteristics of Joint Installation Scheme of Multispectrum Remote Sensing and Frequency Spectrum Analysis
by Shan Zijuan [0830 1311 1227] and Li Zhengzhi [2621 2973 4160]
- D. Infrared Radiation and Its Measurement (16 papers):
- D1 Long Wave Infrared Radiation and Heat Treatment of Metals
by Cai Jiamin [5591 1367 2404]
- D2 Determination of Near Infrared Background Radiation in Earth Atmosphere
by Wang Yingjian [3769 5391 7002], Chen Ji [7115 3444], Ren Xiaoquan [0117 1321 3123] and Guan Fengjun [4619 7685 0689]
- D3 Study of Determination Method of Emissivity and Surface Temperature of Ground Features at Room Temperature
by Li Chunhuai [2621 2504 2849]
- D4 Discussion on Relationship Between Soil Emissivity and Surface Moisture Content
by Li Chunhuai [2621 2504 2849], Wang Yang [3769 2799] and Li Songling [2621 2646 0134]
- D5 Infrared Spectrometer for Ground Features
by Wang Tieming [3769 6993 6900], Chen Baoshu [7115 1405 2885], Yang Yaoming [2799 5069 2494], Xiao Jincai [5618 6855 2088], Xu Yinhao [1776 1377 6275] and Wang Hongxi [3769 7703 4406]

- D6 Analysis of Determination Method of Infrared Emissivity of Ordinary Objects
by Liao Yunhe [1675 0061 0735]
- D7 On-Site Testing Study of Surface Heat Loss of Heat Transfer Pipeline by Use of Infrared Radiation Thermometer
by Zhang Caigen [1728 2088 2704], Wang Hongxi [3769 7703 4406], Wu Yingsheng [0702 2019 3932] and Ying Yuefen [2019 2588 5358]
- D8 Design of Optical System of a Radiation Thermometer
by Wu Futian [0702 4395 3944]
- D9 Design Principle of Infrared Thermometer
by Kang Lunhua [1660 0243 5478]
- D10 Design Consideration of Temperature Control Thermometer for Silicon Extension Sheet Furnace
by Chen Lixin [7115 4539 0207]
- D11 HWS-B Type Infrared Hygrometer and Its Industrial Application
by Wang Jinshan [3769 6855 1472], Ding Zhihua [0002 1807 5478], Fang Xiuqin [2455 4423 3830], Cheng Ertong [4453 1422 0681], Yang Xudong [2799 2485 2639] and Wu Yunchu [0702 0061 0443]
- D12 Inspection of Void Welding in Printed Circuit Board With Heat Scan Non-destructive Inspection by Use of CO₂ Infrared Laser
by Dai Yongjiang [2071 3057 3068] and Nan Jingda [0589 0079 6671]
- D13 Use of Thermal Scan Infrared Nondestructive Inspection Technique on Boundary Adhesion Quality of Powder Column in Solid Fuel Rocket Engine
by Tian Enrui [3944 1869 3843], Wu Jie [0702 2638] and Pi Mingjia [4122 0682 0857]
- D14 Development and Application of HT-1 Type Thermal Scan Infrared Nondestructive Inspection Device
by Wu Jie [0702 2638], Tian Enrui [3944 1867 3843], Pi Mingjia [4122 0682 0857], Xue Hongfu [5641 3163 4395], Li Jinrong [2621 6855 2837], Chen Zhongxian [7115 6945 6343], Yang Qingyi [2799 1987 5030] and Liang Junxue [2733 6511 1331]
- D15 Study on TNDT Method on Adhesion Defect of Nonmetal Materials
by Lin Xuerong [2651 7185 2837], Xu Jun [1776 6511] and Huang Yi [7806 3015]
- D16 Design of Infrared Radiation and Infrared Target
by Shi Changqing [0670 7022 3237]

E. Others (11 papers):

- E1 Radioactivity Calibration of Absolute Spectrum of Visible Light--Near Infrared Integrating Sphere by Ye Jiafu [5509 1367 4395]
- E2 Digital High Precision Dynamic Micrometry System by Liu Shang'gan [0491 0006 0051] and Li Kun [2621 3824]
- E3 Study of Infrared Heterodyne Characteristic of N^+-P Type HgCdTe Photoelectric Diode by Fang Hubao [2455 3275 1405], Zhang Xianchi [1728 7359 3589] and Cai Shidong [5591 1709 2639]
- E4 Discussion on Problems in Low-Impedance Amplifier by Jin Zhiyu [6855 1807 3558]
- E5 Computing Amplifiers Used in Infrared Primary Amplifier by Bai Shuhua [4101 3219 5478]
- E6 Design of High-Order Multiresonator Bandpass Filter by Kong Musheng [1313 3092 3932]
- E7 Zero Frequency Normalization of Infrared Transfer Function Instrument by Feng Zhuoxiang [7458 0587 4382] and Liu Zhongben [0491 0022 2609]
- E8 Comments on "Revision on Sensitivity Equations of Various Infrared Systems" by Chen Lixin [7115 4539 0207]
- E9 Spectrum Testing System of Infrared Wave Segment by Zhou Zuoping [0719 0146 1627], Zhang Xiaomin [4545 1420 3046] and Li Wenhong [2621 2429 4767]
- E10 $10\mu m$ Near-Earth Atmospheric Communication System by Use of Thermal Relief Electric Sounding Device by Hu Yu [5170 3254]
- E11 Frequency Compensation in Noise Analysis for $LiTaO_3$ Device in High Frequency Wideband High Power System by Hu Yu [5170 3254]

10424

CSO: 4008/376

JPRS-CST-85-029
3 September 1985

AUTHOR: YANG Jihua [2799 4949 5478]
PANG Shufen [6614 2631 5358]
SUN Tao [1327 3447]
et al.

ORG: Changchun Institute of Applied Chemistry, Chinese Academy of Sciences

TITLE: "Stereospecific Polymerization of Butadiene Catalyzed by
 $\text{NdCl}_3 \cdot 2\text{Phen-HAl}(\text{i-Bu})_2$ System"

SOURCE: Changchun YINGYONG HUAXUE [CHINESE JOURNAL OF APPLIED CHEMISTRY]
in Chinese Vol 1 No 4, Sep 84 pp 11-18

TEXT OF ENGLISH ABSTRACT: A new binary rare earth chloride catalyst composed of $\text{NdCl}_3 \cdot 2\text{Phen}$ (Phen = 1, 10-phenanthroline) and $\text{HAl}(\text{i-Bu})_2$ for stereospecific polymerization of butadiene is presented. In contrast to other types of rare earth chloride catalysts, the present system is characterized by its ability to control the molecular weight of the product and its specific mode of formation. The general rule of butadiene polymerization with the catalyst was studied. It was found that $\text{HAl}(\text{i-Bu})_2$ is mainly the chain transfer agent in the reaction and the $\text{HAl}(\text{i-Bu})_2/\text{monomer}$ ratio is a key parameter controlling the molecular weight of the polybutadiene obtained. The possible role of the phen molecule in molecular weight controlling is discussed.

AUTHOR: NI Yushan [0242 3768 1472]
XU Jiping [1776 4764 1627]

ORG: Changchun Institute of Applied Chemistry, Chinese Academy of Sciences

TITLE: "Synthesis of Azoxybisbenzocrown Ethers"

SOURCE: Changchun YINGYONG HUAXUE [CHINESE JOURNAL OF APPLIED CHEMISTRY]
in Chinese Vol 1 No 4, Sep 84 pp 30-33

TEXT OF ENGLISH ABSTRACT: Two new azoxybisbenzocrown ethers were synthesized. The preparative method of azoxybisbenzo-15-crown-5 has been improved, with a yield of up to 65.3 percent. It was observed that the degree of dissociation of the electron-transfer agent plays an important role in the product yield. The results were interpreted in terms of solvent polarity. Photo- and thermo-isomerization of azoxybisbenzocrown ethers have been studied preliminarily.

AUTHOR: ZHAO Xingfa [6392 5281 4099]
YANG Dezheng [2799 1795 2973]
ZHANG Li [1728 0500]
CHEN Xiuhua [7115 4423 5478]
et al.

ORG: ZHAO, YANG, et al., of the Institute of Dalian No 7 Petroleum Refinery; ZHANG, CHEN, et al., of Dalian Institute of Chemical Physics, Chinese Academy of Sciences

TITLE: "A Viscosity Index Improver for Lubricating Oil from Ethylene-Propylene Copolymer"

SOURCE: Changchun YINGYONG HUAXUE [CHINESE JOURNAL OF APPLIED CHEMISTRY] in Chinese Vol 1 No 4, Sep 84 pp 41-46

TEXT OF ENGLISH ABSTRACT: A highly active supported catalyst ($\text{TiCl}_4\text{-PCl}_3$)/ $\text{MgCl}_2\text{-AlEt}_3$ for ethylene-propylene copolymerization is reported. An ethylene-propylene copolymer with low molecular weight and narrow molecular weight distribution has been obtained through the addition of PCl_3 ligand in the catalyst system and the hydrogen regulation during the reaction. The copolymer is suitable for improving the viscosity index of lubricating oil, since it has rather good overall properties, such as viscosity index, thickness, low temperature viscosity, and is stable against shearing, oxidation, heat, etc.

AUTHOR: HU Ninghai [5170 1337 3189]
LIN Yonghua [2651 3057 5478]
ZHOU Qinglian [0719 3237 1670]
et al.

ORG: Changchun Institute of Applied Chemistry, Chinese Academy of Sciences

TITLE: "Crystal Structure of Potassium Europium Metaphosphate"

SOURCE: Changchun YINGYONG HUAXUE [CHINESE JOURNAL OF APPLIED CHEMISTRY]
in Chinese Vol 1 No 4, Sep 84 pp 47-50

TEXT OF ENGLISH ABSTRACT: The potassium europium metaphosphate crystal $\text{KEu}(\text{PO}_3)_4$ belongs to the monoclinic space group $P2_1$ with unit cell parameters $a = 7.932(4)\text{\AA}$, $b = 8.375(1)\text{\AA}$, $c = 7.261(3)\text{\AA}$, $\beta = 92.05(4)^\circ$, $V = 482.0\text{\AA}^3$, $Z = 2$. The intensities of 979 independent reflections were collected by the PW-1100 four-circle diffractometer. The structure was solved by the heavy-atom method and the final $R = 0.084$ after refining by the full-matrix least-squares method. The basic structural units are helical ribbons, $(\text{PO}_3)_n$, formed by corner sharing tetrahedra of PO_4 . The coordination of the europium anion by oxygen atoms is eight-fold with the geometry of dodecahedra. The shortest Eu-Eu distance is $6.93\text{\AA}$.

AUTHOR: XU Yang [1776 3152]
YU Fusheng [0151 6346 3932]
ZHOU Enle [0719 1869 2867]
et al.

ORG: Changchun Institute of Applied Chemistry, Chinese Academy of Sciences

TITLE: "On the Relationship of Molecular Weight and Temperature with the Crystallization Behavior of cis-Polybutadiene"*

SOURCE: Changchun YINGYONG HUAXUE [CHINESE JOURNAL OF APPLIED CHEMISTRY]
in Chinese Vol 1 No 4, Sep 84 pp 51-56

TEXT OF ENGLISH ABSTRACT: It has been shown that cis-1,4-polybutadiene obtained by a rare earth catalyst (Ln-PB) possesses a cis-1,4-content higher than 98 percent, and can be crystallized rapidly at low temperatures. This paper presents our study on the relationship of molecular weight and temperature with the crystallization behavior of Ln-PB using a dilatometer and electron microscope.

A set of crystallization rate curves of Ln-PB is given in this paper. It is seen that the minimum rate of crystallization occurs in the range of $\langle M \rangle_{\eta} = 4.6 - 6.7 \times 10^5$, while the maximum rate is in the range of $\langle M \rangle_{\eta} = 3.0 - 3.8 \times 10^6$. The results are interpreted in terms of the nucleus theory of crystallization.

It is also shown that, for Ln-PB, there is a transition at about -20°C from regime I to regime II as the crystallization temperature decreases. The interfacial free energy of Ln-PB, σ_e , is about 17 erg/cm^2 when $\langle M \rangle_{\eta} < 10^6$, which increases with increasing molecular weight when $\langle M \rangle_{\eta} > 10^6$.

*Model TQ-16 computer was used for all calculations.

9717

CSO: 4009/1049

JPRS-CST-85-029
3 September 1985

AUTHOR: LIN Junmi [2621 0689/33055 1378]
GAO Mingxia [7559 2494 0204]
LIU Hengchuan [0491 1854 2976]

ORG: Department of Chemistry, East China Normal University

TITLE: "Studies on the Spectrophotometric Determination of Thorium with a New Chromogenic Reagent Nitrophosphonazo-mN (NPA-mN)"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10, 20 Oct 84 pp 900-904

TEXT OF ENGLISH ABSTRACT: Nitrophosphonazo-mN 2-(4-nitro-2-phosphonophenylazo)-7-(3-nitrophenylazo)-1, 8-dihydroxy 3,6-naphthalene disulfonic acid is a new chromogenic reagent which forms a stable complex with thorium instantaneously in a strong acidic medium. The color reaction between them takes place rapidly, having fine contrast and high sensitivity. The value of molar absorptivity at 665 nm is found to be $1.17 \times 10^5 \text{ l mol}^{-1}\text{cm}^{-1}$ and $1.62 \times 10^5 \text{ l mol}^{-1}\text{cm}^{-1}$ (dual wavelength method). Beer's law is obeyed for 0-30 μg and 0-35 μg of Th in 25 ml on single and dual wavelength determination respectively. Twelve parallel determinations of 10 μg of Th give a relative standard deviation of 2.59×10^{-3} and a coefficient of variation of 0.787 percent.

The outstanding advantage of NPA-mN is its excellent selectivity. The tolerance of most metallic ions, including Zr(IV), V(V), etc., may reach the milligram level. The tolerance of those often seriously interferential elements such as U(VI), RE(IV) and Ti(IV) exceeds that using other analogous reagents.

A procedure has been worked out for determining Th in tap or river water, urine and extracting technological waste water of Zr and Hf (without preparation) with good results. The latter has to be separated preliminarily by ion-exchange in determination with Arsenazo-III. (Paper received on 27 August 1983.)

AUTHOR: SHI Huiming [0670 1979 2494]
ZHANG Guizhu [1728 6311 3796]
AN Zemin [1344 3419 2404]

ORG: Department of Chemistry, Nankai University

TITLE: "Formation of the Mixed Micelle and Its Analytical Application in the Multicomponent Complex-Fe-CAS System"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10, 20 Oct 84 pp 904-909

TEXT OF ENGLISH ABSTRACT: An effective method for increasing the sensitivity and selectivity of color reaction of Fe (III) has been studied because of the excess amount of Triton X-100 added to the system Fe-CAS-DDMAA (HDMMA).

The addition of Triton X-100 would greatly increase the molar absorptivity, widen the useful pH range and allow the presence of many masking agents.

A new method has been successfully developed for the rapid determination of trace amounts of Fe in samples of pure Co, pure Al, pure RE_2O_3 , Al alloy, Ni alloy and Cu alloy.

AUTHOR: WANG Changfa [3769 7022 4099]
LU Jixin [4151 4949 2450]

ORG: Tianjin Institute of Geology and Mineral Resources

TITLE: "Spectrophotometry with Vanadium Phosphomolybdate-Nile Blue Multi-component Complex and Determination of Vanadium in Monomineral Silicate"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10, 20 Oct 84 pp 909-912

TEXT OF ENGLISH ABSTRACT: The properties and application of the vanadium phosphomolybdate-nile blue ion-associated complex are studied. Its color is blue in 2.3 N sulfuric acid. It is more stable in the presence of polyvinyl alcohol. The constituent ratio of vanadium phosphomolybdate to nile blue is 1:4. The complex and reagent have maximum absorption at 570 nm and 630 nm respectively. The complex has a molar absorptivity of 1.3×10^5 . Beer's law is obeyed for vanadium in the concentration of 0 to 10 $\mu\text{g}/50 \text{ ml}$. In order to eliminate the interference of titanium and silicon, the acidity and the amount of phosphor should be increased when heteropoly acid is formed, and phosphoric acid should be added when the excess of phosphomolybdate is being dissociated by an oxalic acid-tartaric acid-sulfuric acid mixture. Macro amounts of titanium and silicon may exist as tolerable. This method has a high sensitivity and good selectivity. In the analysis of iron or silicate minerals of small amounts, 0.X to 0.00X percent of vanadium can be determined without separation. RSD ranges from 3 to 8 percent. (Paper received on 23 September 1983.)

AUTHOR: CHEN Siqin [7115 1835 2953]
PENG Shanshan [1756 3790 3790]
RUAN Dawen [7086 1129 2429]

ORG: Department of Chemistry, Jiangxi University

TITLE: "Spectrophotometric Determination of Trace Amounts of Selenium (IV)
by a New Catalytic Reaction"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10,
20 Oct 84 pp 913-915

TEXT OF ENGLISH ABSTRACT: A new catalytic-spectrophotometric method for determining selenium (IV) is proposed. Selenium catalyzes the oxidation of phenylhydrazine by potassium chlorate to diazobenzene-diazonium ion, through which a violet-red azo dye is obtained by coupling with H-acid. Optimum conditions for determining selenium have been established. The sensitivity presented as apparent molar absorptivity equals 1.2×10^6 . Trace amounts of selenium in human hair have been determined with satisfactory results. (Paper received on 3 May 1983.)

AUTHOR: FAN Cunzhong [5400 1317 1813]

ORG: Metallurgical Project and Research Institute of Guizhou Province

TITLE: "Spectrophotometric Determination of Gold Based on the Formation of Ternary Complex Au-2, 4, 5, 7-Tetrabromofluorescein-I-Pyrrolidinedithiocarboxylic Acid Sodium Salt"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10, 20 Oct 84 pp 919-921

TEXT OF ENGLISH ABSTRACT: A spectrophotometric method has been developed for the determination of gold based on the formation of ternary complexes of Au(III) with TBF and PDDTC in an aqueous solution in the presence of polyvinyl alcohol. The complex absorbance is measured at 545 nm and the molar absorptivity is 2.56×10^4 . Beer's law is obeyed in the range of 0 to 3.2 μg for Au(III) in 1 ml. The composition ratio of Au to ligand is 1:2:2. The color reactions can be applied to spectrophotometric determination of gold in mineral ores or in some other samples. (Paper received on 18 May 1983.)

AUTHOR: WU Runshen [0702 3387 6500]

ORG: Central Laboratory, Huabei Prospecting Company of Metallurgy and Geology

TITLE: "Spectrophotometric Determination of Micro Antimony with the System Antimony-Potassium Iodide-Salicyl Fluorone-Emulsifying Agent After Hydride Separation"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10, 20 Oct 84 pp 921-923

TEXT OF ENGLISH ABSTRACT: A method which combines separation technology and the formation of a multicomponent complex has been drawn up for the determination of Sb in the aqueous phase without organic solvent. Antimony could be separated as hydride from matrix elements in bulk. The complex turned orange in the medium of 0.25 N to 0.38 N HCl, and had maximum absorptivity at 510 nm, with molar absorptivity being $7.1 \times 10^4 \text{ l mol}^{-1} \text{ cm}^{-1}$. The content of antimony (0 to 15 $\mu\text{g}/10 \text{ ml}$) adhered to Beer's law. The interferences were eliminated with a suitable masking agent and a specific absorbent. The complex would remain stable for three hours at room temperature. This method can be used directly to determine micro antimony in rock and soil in the aqueous phase. (Paper received on 18 May 1983.)

AUTHOR: XUE Guang [5641 0342]

ORG: PLA Unit 00524

TITLE: "Color Reaction of Ternary Complex of Thorium-Semixylenol Orange-Cetyltrimethylammonium Bromide"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10, 20 Oct 84 pp 928-930

TEXT OF ENGLISH ABSTRACT: A color reaction of thorium with semixylenol orange (HXO) and cetyltrimethylammonium bromide (CTMAB) has been investigated, and a successful determination of micro thorium in uranic ores has been accomplished. The composition of $\text{Th}^{4+}/\text{HXO}$ is 1:2 at pH 1.5-4.0. The apparent molar absorptivity is $\epsilon = 5.6 \times 10^4 \text{ l mol}^{-1}\text{cm}^{-1}$ at 550 nm. Beer's law is obeyed in the range of 0-20 $\mu\text{g}/25 \text{ ml}$ for thorium. (Paper received on 22 June 1983.)

AUTHOR: SHEN Hao [3088 3185]
CHEN Defeng [7115 1795 5364]
YE Lei [0673 5623]
et al.

ORG: Department of Chemistry, Nanjing University

TITLE: "Application of Carbon Mat Electrodes to the Collection of Trace Metallic Ions"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10,
20 Oct 84 pp 940-942

TEXT OF ENGLISH ABSTRACT: A new method of electrochemical collection of trace metallic ions with the carbon mat electrodes (CME) is reported. A lot of trace metallic ions can be collected on the CME. The collecting efficiency of the CME for Cd^{2+} , Cr^{3+} , Cu^{2+} , Co^{2+} , Ag^+ , Ni^{2+} and Zn^{2+} ($5 \times 10^{-8} - 10^{-6}$ g/ml) is approximately 98 percent in a single collection. The instrumentation is very simple and easy to use. (Paper received on 9 June 1983.)

AUTHOR: WANG Xianke [3769 3759 4430]

ORG: Lanzhou Steel Plant

TITLE: "The Color Reaction of Multicomponent Complex of Chromium (III) with 2-(5-Br-2-Pyridylazo)-5-Diethylaminophenol"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY $\frac{1}{2}$ in Chinese Vol 12 No 10, 20 Oct 84 pp 943-945

TEXT OF ENGLISH ABSTRACT: The complex of Chromium (III) with 5-Br-PADAP is studied in the presence of hydrogen peroxide and zephiramine, and is used for the determination of trace chromium. This method is characterized by high sensitivity and good selectivity, and has been successfully applied to the determination of trace chromium in water, industrial waste water, iron, steel and soil. (Paper received on 9 June 1983.)

AUTHOR: DENG Mingtao [6772 2494 1718]
ZHANG Huaixi [1728 2037 3305]
SHU Shilan [5289 0099 5695]

ORG: Chengdu University of Science and Technology

TITLE: "Automatic Monitoring of Trace Fluorides in Atmosphere with an Ion-Selective Electrode"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 10, 20 Oct 84 pp 946-950

TEXT OF ENGLISH ABSTRACT: An ion-selective electrode method for the determination of trace soluble fluorides in the atmosphere is investigated. A micro-computer is used to control the analytical procedure. The air sample (20 to 30 l/min) and the absorbent (TISAB, 0.5 ml/min) pass through a coiled glass tube in the same direction, ensuring complete absorption for the method is completed satisfactorily. A single determination takes 6 minutes. The determination limit is less than $1 \mu\text{g}/\text{m}^3$ (calculated as F). (Paper received on 14 July 1983.)

9717

CSO: 4009/1056

JPRS-CST-85-029
3 September 1985

AUTHOR: YE Shuaiguan [0673 3764 1351]
SHAN Shang [0810 1424]
WANG Jie [3769 2638]

ORG: Department of Chemistry, Zhejiang University

TITLE: "Photometric Determination of Micro Silicon in Fine Vanadium Pentoxide with Multicomponent Complex of Silicovanadomolybdate Blue-Butyl Rhodamine B"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol. 12 No. 12, 20 Dec 84 pp 1047-1052

TEXT OF ENGLISH ABSTRACT: Fine vanadium pentoxide (V_2O_5 > 98 percent) contains micro amounts of silicon (about 10^{-2} - 10^{-3} percent). Because of the large quantity of vanadium in the determined system, a discussion of spectrophotometric method is made for the determination of micro quantities of silicon by the formation of silicovanadomolybdate blue-butyl rhodamine B complex in the aqueous phase. The maximum absorption wavelength of the complex is at 568 nm, and Beer's law is obeyed for 0-15 μg of SiO_2 in 100 ml. The value of the molar absorption coefficient is 1.4×10^5 . The sensitivity of this method is raised obviously in contrast with that of the usual method of silicomolybdate blue. (Paper received on 10 October 1983.)

References

- [1] Е.Н.Дорохова и др., ЖАХ, 29, 2014(1974).
- [2] 冯渝清、郭春山, 理化检验 (化学分册), 17, 11(1981).
- [3] 许生杰, 分析化学, 11, 312(1983).
- [4] 奚干卿、张乃熾, 分析化学, 9, 6(1981).

AUTHOR: YANG Yuan [2799 0337]
CHEN Yuanhui [7115 6678 1979]

ORG: YANG of the Epidemic Prevention Station, Qingbaijiang District,
Chengdu Municipality; CHEN of the Epidemic Prevention Station, Jintang County

TITLE: "Spectrophotometric Study of Magnesium-Chromazurol S-Surfactant
System"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 12,
20 Dec 84 pp 1052-1054

TEXT OF ENGLISH ABSTRACT: In a buffer solution of KCl-NaOH at pH 12.5, magnesium forms a blue complex with chromazurol S (CAS) and cetylpyridinium bromide (CPB). The maximum absorbance of the Mg-CAS=CPB is measured at 650 nm, and its molar absorptivity is $1.14 \times 10^5 \text{ l} \cdot \text{mol}^{-1} \cdot \text{cm}^{-1}$. The molar ratio of magnesium to CAS is 1:4. Beer's law is obeyed in the magnesium concentration range of 0 to 10 $\mu\text{g}/50 \text{ ml}$. The method has been applied to the microdetermination of magnesium in nodular cast iron with reliable results. (Paper received on 17 October 1983.)

References

- [1] Zygmunt Marczenko, "Spectrophotometric Determination of Elements", 329-337, Ellis Horwood Ltd., 1978.
- [2] 肖满田等, 理化检验, (6).27(1978).

AUTHOR: ZENG Xianjin [2582 2009 3160]
MIAO Xiuzhen [4924 4423 3791]
GUAN Shengli [7070 0524 0448]
HUANG Benli [7806 2609 4539]

ORG: Changchun Institute of Applied Chemistry, Chinese Academy of Sciences

TITLE: "Determination of Major, Minor and Trace Elements in Coal Fly Ash by Inductively Coupled Plasma Atomic Emission Spectroscopy"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 12, 20 Dec 84 pp 1062-1066

TEXT OF ENGLISH ABSTRACT: A method for simultaneous multielement analysis of coal fly ash with a multichannel ICP spectrometer has been developed. The sample was first digested with mixed nitric, hydrofluoric and perchloric acids in a Teflon-lined bomb at 180°C, and then the residue was filtered and fused with sodium hydroxide. Solutions containing pure matrix elements and the sample solution were used to investigate spectral interferences with the system's Polychromator Scan Software. For several trace elements interference correction was indispensable. Results for 17 elements (Al, Ca, Fe, K, Mg, Na, Ti, Ba, Be, Co, Cr, Cu, Mn, Ni, Sr, V and Zn) in the 82201 coal fly ash sample agreed well with those obtained with volumetric, colorimetric, AAS, ICF-AES, NAA and XRF techniques in other laboratories. (Paper received on 2 December 1983.)

References

- [1] J.C.Mills and C.B.Belcher, *Prog.Anal.Atom.Spectrosc.*, 4, 49(1931).
- [2] R.A.Nadkarni, *Anal.Chem.*, 52, 929(1980).
- [3] A.F.Ward and L.Marciollo, *Jarrell Ash Plasma Newsl.*, 1(3), 10(1978).
- [4] K.I.Botto, *Jarrell Ash Plasma Newsl.*, 2(2), 4(1979).
- [5] T.L.Drenski, *ASTM Spec.Tech.Publ.*, 760, 225(1982).
- [6] D.Yates, *ICP Inform Newsl.*, 6, 217(1980).
- [7] 黄本立, 曾宪津、孙雅茹、关胜利、刘春兰、缪秀珍, 084号报告, 中日分析化学双边讨论会, 1983年9月14—17日, 长春; 分析化学, 12(7), 586(1984).
- [8] M.L.Parsons; T.A.Anderson, R.S.Lyon and D.A.Park, *ICP Inform.Newsl.*, 9(3), 154(1983).
- [9] G.F.Larson and U.A.Fassel, *Appl.Spectrosc.*, 33, 592(1979).

AUTHOR: REN Shangxue [0117 1424 1331]
ZHANG Aimin [1728 1947 2404]

ORG: REN of Northwestern Institute of Soil and Water Conservation, Chinese Academy of Sciences; ZHANG of the Prevention and Cure Institute of Endemic Diseases, Luoyang

TITLE: "An Accurate Fluorescence Method for Determination of Selenium in Drinking Water"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 12, 20 Dec 84 pp 1079-1081

TEXT OF ENGLISH ABSTRACT: As soon as water samples are collected, they should be acidized and stored in a plastic bottle sopped in 10 percent nitric acid within 30 days for determination. A certain amount of Se^{6+} must be reduced to Se^{4+} by hydrochloric acid in concentration over 4N. The rate of Se recoveries is 90-106 percent, and the relative standard deviation is less than 5 percent. (Paper received on 22 June 1983.)

References

- [1] 环境保护检验, 上海市卫生防疫站, 上海人民出版社, 98, 1976..
- [2] Standards methods for the examination of water and waste-water, 14 edition, American public Health Association, Washington, 1979.
- [3] A.O.A.C., 81(1), 48 (1978) .
- [4] A.O.A.C., 81(4), 927 (1978) .

AUTHOR: YU Suqing [0151 4790 3237]
FU Xiaochun [0265 2556 2504]

ORG: Department of Chemistry, Nankai University

TITLE: "Spectrographic Determination of Rare Earth Impurities in Erbium Oxide"

SOURCE: Changchun FENXI HUAXUE [ANALYTICAL CHEMISTRY] in Chinese Vol 12 No 12, 30 Dec 84 pp 1081-1084

TEXT OF ENGLISH ABSTRACT: A simple and sensitive spectrographic method for the determination of rare earth impurities in erbium oxide is proposed. Carbon powder (S.P) is used as the buffer which is mixed with the sample in the ratio of 1:1 by weight and a DC arc is used as the excitation source. The sensitivities are: 1.5 ppm (europium), 5 ppm (yttrium), 6 ppm (thulium), 10 ppm (lanthanum holmium), 15 ppm (dysprosium, ytterbium), 20 ppm (lutetium), 30 ppm (cerium, neodymium), 50 ppm (samarium) and 60 ppm (praseodymium, gadolinium, terbium). The standard deviations are 2.94 percent to 16.18 percent respectively. (Paper received on 30 June 1983.)

References

- [1] K. Swamy, S.V; Grampurohit; C.A., 74, 82724d (1971) .
- [2] Г.И. Штаненков, Зав. Лаб., 47 (9) , 15 (1981) .
- [3] 湖南冶金研究所等, «稀土冶金分析», 1973年11月版, 486页.
- [4] 余素清、林进等; 分析化学, 11 (4) , 273 (1983) .

9717

CSO: 4009/1077

JPRS-CST-85-029
3 September 1985

AUTHOR: WEN Ximeng [2429 1585 1322]
GAO Xiuqing [7559 4423 3237]
CHEN Bingxian [7115 3521 6343]
et al.

ORG: Institute of Atomic Energy, Beijing

TITLE: "Determination of the Depth Profile of Gold in Silicon Wafers by Masking, Etching Layers Removal-Neutron Activation Analysis"

SOURCE: Beijing HE HUAXUE YU FANGSHE HUAXUE [JOURNAL OF NUCLEAR AND RADIOCHEMISTRY] in Chinese Vol 7 No 2, May 85 pp 90-95

TEXT OF ENGLISH ABSTRACT: This paper presents the techniques of masking and removing layers of silicon wafers coupled with neutron activation analysis, and the method for the determination of the depth profile of gold in silicon wafers. Reliable and convenient masking can be made by means of a homemade mold which has good corrosion resistance. The mold is particularly suitable for radioactive samples. The effects of the composition of the etchant, etching temperature and etching time on the etching rate are also investigated. By means of this method each thin layer removed can reach 5-20 μm in thickness. The total deviation of the removed layer thickness is about ± 3 percent.

AUTHOR: MA Jiayu [7456 1367 3768]
SUN Xiurong [1327 4423 2837]
et al.

ORG: Institute of Modern Physics, Chinese Academy of Sciences, Lanzhou

TITLE: "The On-line Rapid Chemical Separation of Ge Isotopes from Heavy Ion Reaction Products"

SOURCE: Beijing HE HUAXUE YU FANGSHE HUAXUE [JOURNAL OF NUCLEAR AND RADIOCHEMISTRY] in Chinese Vol 7 No 2, May 85 pp 96-100

TEXT OF ENGLISH ABSTRACT: $^{66,67}\text{Ge}$ isotopes are produced by bombarding a natural Ni target with ^{12}C ions at 72.5 MeV. The nuclear reaction products are transported as far as 8 m with a He-jet system and separated in the gaseous phase. The separating conditions of the Ge isotopes are studied in detail with AgCl at 600°C as an additive and with He as the carrier gas at 1.2 atm.

The experimental results show that the Ge isotopes are separated satisfactorily from the nuclear reaction products within 10 minutes and their adsorption yields are above 60 percent. The decontamination factors of As and Ga are $(8.21 \pm 3.53) \times 10^2$ and $(1.52 \pm 0.27) \times 10^2$ respectively.

AUTHOR: ZHANG Tianmei [1728 1131 2734]
FU Min [0102 3046]
WU Dingqing [0702 1353 3237]

ORG: Institute of Modern Physics, Chinese Academy of Sciences, Lanzhou

TITLE: "Fast Chemical Separation and Identification of Neutron-Deficient Iodine Isotopes"

SOURCE: Beijing HE HUAXUE YU FANGSHE HUAXUE [JOURNAL OF NUCLEAR AND RADIOCHEMISTRY] in Chinese Vol 7 No 2, May 85 pp 101-107

TEXT OF ENGLISH ABSTRACT: A combination of rapid chemical separation and a gas-jet transport system is used to investigate the decay properties of iodine obtained from $\text{Ag}(^{12}\text{C}, \text{xn})\text{I}$ by bombarding natural Ag with a beam of ^{12}C at 67.4 MeV. The separation of I from Te and Sb is completed by solvent extraction within 25 to 40 seconds. The decontamination factors obtained are 60 for ^{113}Sb and 101 for ^{115}Te . However, the decontamination for ^{117}Te is only 17 because of decay from its precursor ^{117}I .

Sixteen γ -rays of I with rather high intensity are obtained, the partial decay properties of $^{117}, ^{118}, ^{119}\text{I}$ are investigated and the charge number of the product is assigned. Furthermore, seven γ -peaks that have not been obtained in the physical experiments are obtained distinctly, among which four γ -peaks (447.5 keV, 858.5 keV, 1303 keV and 1233 keV) have not been reported before. These four γ -peaks could well be the γ -rays of I, but further study in more detail needs to be done.

AUTHOR: ZHAO Hugen [6392 3337 2704]
YANG Xuexian [2799 1331 0341]

ORG: Institute of Atomic Energy, Beijing

TITLE: "Studies of the Extraction of Np(IV) with Bidentate Organophosphorus Extractant DHDECMP"

SOURCE: Beijing HE HUAXUE YU FANGSHE HUAXUE [JOURNAL OF NUCLEAR AND RADIOCHEMISTRY] in Chinese Vol 7 No 2, May 85 pp 116-119

TEXT OF ENGLISH ABSTRACT: The extraction of Np(IV) and separation of Am(III) from Np(IV) by DHDECMP-DEB in a nitric acid medium is described.

Experimental results show that equilibrium for Np(IV) is reached in 30 s. The distribution ratio of Np(IV) decreases with an increase in temperature and increases with the concentration of nitric acid and DHDECMP. The enthalpy change $\Delta H_{\text{Np(IV)}}^{\text{DNP(IV)}}$ is estimated to be 15 kJ/mol. The logarithmic plot of $\text{DNP(IV)} \sim [\text{DHDECMP}]$ is a straight line with a slope of 2.0. Therefore, the extraction reaction for Np(IV) with DHDECMP can be expressed as $\text{Np}^{4+} + 4\text{NO}_3^- + 2\text{DHDECMP} \rightleftharpoons \text{Np}(\text{NO}_3)_4 \cdot 2\text{DHDECMP}$.

The separation of Am from Np can be achieved by means of nitric acid stripping with a separation factor of higher than 50.

9717

CSO: 4009/266

JPRS-CST-85-029
3 September 1985

AUTHOR: LEI Qichun [7191 0796 4783]
CHEN Tianyu [7115 1131 5280]

ORG: LEI of Jilin University of Technology
CHEN of Changchun Geological Institute

TITLE: "On Computer The Multidimensional Fast Haar Transform"

SOURCE: Beijing SHUZHJ JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL METHODS AND COMPUTER APPLICATIONS] in Chinese Vol 6, No 2, Jun 85 pp 88-97

TEXT OF ENGLISH ABSTRACT: An efficient fast algorithm based on a particular organization of data and matrix kronecker products is described for computing the multidimensional Haar transform. It not only maintains the advantages of the fast transform by reducing the numbers of storage elements and of arithmetic operations, but can provide a visual aid for the computational procedure. (Paper received on 6 Oct 82)

References

- [1] J. L. Hammond, R. S. Johnson, A review of orthogonal Square-wave functions and their application to linear networks, J. Franklin Inst. 273, (1962), 211-25.
- [2] L. A. Gerardin, J. Flanent, Geometrical Pattern feature extraction by projection of Haar orthogonal basis. International Joint Conference on Artificial Intelligence (1969).
- [3] D. Gubbins, I. Scollar and P. Wisskirchen, Two-dimensional digital filtering with Haar and walsh transforms. Annales de Géophysique 27, 2, (1971), 85-104.
- [4] A. Rosenfield, M. Thurston, Edge and curve detection for Visual Scene analysis, I.E.E.E. Trans. Computers C20, (1971), 562-9.
- [5] D. W. Thomas, Burst detection using the Haar Spectrum. 1973 Proceedings: Theory and Applications of walsh functions, Hatfield polytechnic, England (1973).
- [6] N. Ahmed, T. Natarajan, K. R. Rao, Cooley-Tukey type Algorithm for the Haar Transform. Electronics letters 9 (1973), 276-278.
- [7] D. K. Cheng, J. J. Liu, A. Generalized Orthogonal Transformation Matrix, I.E.E.E. Trans. Comput. Vol. C-28 (1979), 147-150.
- [8] 徐中信, 雷启纯, 陈天与, 多维快速 Fourier 变换的计算, 石油物探, 1(1980)1-25.
- [9] 徐中信, 陈天与, 多维快速沃希变换的计算, 石油地球物理勘探, 2(1980)1-14.
- [10] 陈天与, 雷启纯, 罗秉忠, 多维快速 Hadamard 变换的计算, 数值计算与计算机应用 3: 3(1982)135-141.

12949

CSO: 4009/1084

Computer Applications

AUTHOR: TONG Chengren [0157 2052 0088]
HUANG Chengshi [7806 6134 1193]

ORG: Computer Center, Bohai Oil Incorporation

TITLE: "A Practical Method For Solving Interaction Between The Upper Structure And The Nonlinear Piles Of A Steel Offshore Platform"

SOURCE: Beijing SHUZHJ JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL METHODS AND COMPUTER APPLICATIONS] in Chinese Vol 6, No 2, Jun 85 pp 113-114

TEXT OF ENGLISH ABSTRACT: This paper presents a practical method for the calculation of the interaction between the upper structure of an offshore platform and the nonlinear piles. The method enables simple and easy calculations for the overall structure of the offshore platform, including nonlinear piles. By using an equivalent composite beam set-up to choose parameters and to simulate appropriately the action of pile bases bearing nonlinear retroactive soil forces, the continuity and coordination of all displacements and stresses on the top of the piles are guaranteed. Calculation shows that this method requires only a few iterative calculations to achieve an error of 1 to 3 percent. Moreover, there is also a clear advantage to the speed of calculation, owing to the use of sub-structure technology and the simplicity and speed of single pile calculations. Furthermore, this method has taken into account the case of the 3-dimensional action of piles, thus making the results even more compatible with engineering practice. This method has been used with the DASOS-S offshore platform program. (Paper received on 8 Nov 82)

References

- [1] a. Matlock, Hudson, Correlations for Design of Laterally Loaded piles in Soft Clay, preprints, 1970 offshore Technology Conference, Houston, Texas, OTC 1204, pp 577-594.
b. Matlock, Hudson and Dewaine Bogard, "A Computer Program for the Analysis of Beam-Columns Under Static Axial and Lateral Loads", Proceedings, 1977 offshore Technology Conference, Houston, Texas, OTC 2953.
- [2] 大连工学院, 石油部海洋石油勘探局研究院, DASOS 程序.
- [3] OTC 1971 年 1484 号论文 "海上平台的结构与桩基的相互作用", 天津大学边启光译, 载 "海洋石油" 1978 年第 1 期.
- [4] Larry M. Bryant and Hudson Matlock, "Three-Dimensional Analysis of Framed Structures with nonlinear pile foundations" 1977 offshore Technology Conference, OTC 2955.

12949

CSO: 4009/1084

AUTHOR: GU Jingwen [7357 2529 2429]

ORG: Jiangsu Computer Installation

TITLE: "On Estimating The Slopes Or The Tangential Vectors In Curve Fitting"

SOURCE: Beijing SHUZHJ JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL METHODS AND COMPUTER APPLICATIONS] in Chinese Vol 6, No 2, Jun 85 pp 106-112

TEXT OF ENGLISH ABSTRACT: First the approximating accuracy of the interpolating function based on Akima's method of estimating the slopes at data points in single-valued cases is discussed. A method of estimating the tangential vectors at data points is then presented. Its major advantages are: the computation is simple and the amount of operations is small and the curve generated by using the parametric cubic interpolation based on this technique is good. It can be applied to computer curve output, especially to such applications as tracing and drawing contour maps. (Paper received on 30 Oct 82)

References

- [1] H. Akima, A new method of interpolation and smooth curve fitting based on local procedures, J. ACM, 17:4(1970).
- [2] T. M. R. Ellis, D. H. McLain, Algorithm 514: A new method of cubic curve fitting using local data, ACM Trans. Math. Software, 3 (1977).
- [3] 杨学平, 弧长估计在曲线拟合中的应用, 未发表.
- [4] 龚天蔚, 用于曲线拟合的一个一阶导数估计方法, 数值计算与计算机应用, 3: 1(1982).
- [5] J. E. Midgley, Isotropic four-point interpolation, Computer Graphics and Image Processing, 11:2(1979).
- [6] 杨学平, 计算机绘图, 电力工业出版社, 北京, 1980.
- [7] 苏步青, 刘鼎元, 计算几何, 上海科技出版社, 1981.
- [8] I. D. Faux, M. J. Pratt, Computational geometry for design and manufacture, Halsted Press, 1979.
- [9] 顾景文, 一种绘等值线图的高精度算法, 数值计算与计算机应用, 3: 3(1982).

12949

CSO: 4009/1084

Computer Applications

AUTHOR: LI Yinghong [2621 2019 1347]

ORG: Qinghai Institute of Meteorological Science

TITLE: "Application Of Power Transformation To Programming Source Programs"

SOURCE: Beijing SHUZHI JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL METHODS AND COMPUTER APPLICATIONS] in Chinese Vol 6, No 2, Jun 85 pp 72-81

TEXT OF ENGLISH ABSTRACT: The power transformation is introduced into data processing by source program in order to directly expand the range of the computer adaptability for real numbers, so that the computer capacity is enhanced. (Paper received on 15 Sep 82)

12949

CSO: 4009/1084

AUTHOR: D. K. Finnemore
J. D. Verhoeven
ZHAO Zhongxian [6392 1813 6343]
CUI Changgeng [1508 7022 1649]
GUO Shuquan [6753 2885 2938]

ORG: FINNEMORE and VERHOEVEN of Ames Laboratory-USDOE*, Department of Physics and Department of Materials Science and Engineering, Iowa State University, Ames, Iowa; ZHAO, CUI and GUO of the Institute of Physics, Academy of Science, Beijing

TITLE: "Anisotropic Superconducting Critical Currents for in Situ Composites Cu-Nb"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 247-252

TEXT OF ENGLISH ABSTRACT:

Highly oriented Cu-Nb in situ composites have been studied to determine the changes in superconducting critical current which occur as the relative orientation of the magnetic field, transport current and filament direction are changed. Samples having Cu barrier thickness in the range from 5 to 500 nm show J_c values about a factor of 40 higher for the current parallel to the long axis of the filaments than for the current perpendicular to the long axis. Where the flux line lattice moves perpendicular to the filament direction, the data show that the shear modulus, C_{ss} , governs the flux pinning. Where the flux line lattice moves parallel to the long axis of the filaments the fall in critical current with field is much more rapid.

References

- [1] C. C. Tsuei, *IEEE Trans. Magn.*, MAG-11 (1975), 272.
- [2] J. P. Harbisan and J. Bevk, *J. Appl. Phys.*, 48 (1977), 5180.
- [3] S. Foner, E. J. McNiff, Jr., B. B. Schwartz, R. Roberge, and J. L. Fihey, *Appl. Phys. Lett.*, 31 (1977), 853.

*Operated for the U.S. Department of Energy by Iowa State University under contract No W-7405-Eng-82. This research was supported by the Director for Energy Research, Office of Basic Energy Sciences.

12949
CSO: 4009/1090

Cryogenics

AUTHOR: YAO Xixian [1202 1585 6343]
SUN Yuanshan [1327 0337 0810]

ORG: Department of Physics, Nanjing University

TITLE: "The Current-Phase Relation of the Superconductive Tunnel Junction in Nonstationary Process"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 241-246

TEXT OF ENGLISH ABSTRACT:

The current-phase relation of the superconductive tunnel junction can be derived from the TDGL equations with definite boundary conditions by using a perturbation treatment. The nonstationary process has been investigated. The total amount of current through the junction can be calculated by giving a fixed voltage at the sides. Moreover, when a given current goes through the tunnel junction, an equation which satisfies the phase difference can be obtained. It is noticeable that this equation is different from that as suggested by the RSJ model.

References

- [1] B. D. Josephson, *Adv. Phys.*, 14(1965), 419; V. Ambegaokar and A. Baratoff, *Phys. Rev. Lett.*, 10 (1963), 486.
- [2] K. Hida and Y. Ono, *J. Low Temp. Phys.*, 29(1977), 355.
- [3] P. G. de Gennes, *Phys. Lett.*, 5(1963), 22.
- [4] A. F. Volkov and A. L. Kasatkin, *Sov. Phys. JETP*, 40(1975), 760.
- [5] 姚希贤、肖婉如、孙元善, 低温物理, 4(4)1982, 275.
- [6] L. P. Gorkov and G. M. Eliashberg, *ЖЭТФ*, 27(1968), 328.
- [7] P. G. de Gennes, *Superconductivity of Metals and Alloys* (Benjamin, New York), 1966.

12949

CSO: 4009/1090

AUTHOR: SHEN Baogen [3088 0202 2704]
 ZHAN Wenshan [6124 2429 1472]
 ZHAO Jiangao [6392 6015 7559]
 et al.

ORG: Institute of Physics, Academia Sinica, Beijing

TITLE: "Magnetic Properties and Spin Wave Excitation at Low Temperature for Amorphous $(\text{Fe}_{1-x}\text{Nb}_x)_{84.5}\text{B}_{15.5}$ Alloys"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 253-258

TEXT OF ENGLISH ABSTRACT:

The ribbons of amorphous $(\text{Fe}_{1-x}\text{Nb}_x)_{84.5}\text{B}_{15.5}$ ($0 \leq x \leq 0.1$) alloys are produced by melt quenching using a rotating drum apparatus. The magnetization is measured with an extracting sample magnetometer between 1.5 and 90K in fields up to 70 kOe, and with a magnetic balance between 77 and 300 K in fields 12 kOe. It shows that the spontaneous magnetization decreases almost linearly with the increasing Nb content. The calculated average magnetic moment is $2.05 \mu_B$ for per Fe atom and $-2.57 \mu_B$ for per Nb atom. The spin wave stiffness constant D decreases from $71.3 \text{ MeV } \text{\AA}^2$ ($x=0$) to $59.8 \text{ MeV } \text{\AA}^2$ ($x=0.1$), which is calculated from the relation $\sigma(T)/\sigma(0) = 1 - BT^{3/2} - CT^{5/2}$ but D/T_0 almost independent with Nb content. The mean-square range of the exchange interaction $\langle r^2 \rangle$ is between $11.8 \text{\AA}^2$ and $13.6 \text{\AA}^2$ for $x=0$ and 0.1.

References

- [1] T. Mizoguchi, K. Yamauchi and H. Miyajima, in "Amorphous Magnetism" ed. Hooper and de Graaf, P. 325, Plenum Press (1973).
- [2] S. Dey, U. Gorres, H. J. V. Nielsen, M. Rosenberg and M. Sostarich, *J. De Physique*, **41**(1980), C8-678.
- [3] H. J. V. Nielsen, *J. Magn. Magn. Mater.*, **12** (1979), 187.
- [4] H. J. V. Nielsen, *Solid State Commun.*, **30**(1979), 239.
- [5] W. S. Zhan (詹文山), B. G. Shen (沈保根), H. Y. Lo (罗海英) and B. L. Yu (俞伯良), *Proc. 4th Int. Conf. on Rapidly Quenched Metals* (Sendai, 1981), ed. T. Masumoto and K. Suzuki, II (1982), 1137.
- [6] 詹文山, 沈保根, 赵见高, 张圣华, 物理学报, (待发表).
- [7] 潘孝硕, 詹文山, 沈保根, 赵见高, 金属学报, (待发表).
- [8] C. W. Chen, *Magnetism and Metallurgy of So Magnetic Materials*, North-Holl and publishing Company Amsterdam, New York, OXFORD (1977); P. 200.
- [9] J. Friedel, *Nuovo Cimento Supplement*, **7**(1958), 287.
- [10] R. W. Cochrane and G. S. Cargill, III, *Phys. Rev. Lett.*, **32**(1974), 476.
- [11] J. D. Axe, L. Passel and C. C. Tsuei, in *Magnetism and Magnetic Materials-1974*, ed. by C. D. Graham, Jr., G. H. Lander and J. J. Rhyne, AIP Conf. Proc., No. 24 (AIP, New York, 1975), P. 119.
- [12] C. C. Tsuei and H. Lilienthal, *Phys. Rev. B*, **13**(1976), 4899.
- [13] J. D. Axe, G. Shirane, T. Mizoguchi and K. Yamauchi, *Phys. Rev. B*, **15** (1977), 2763.
- [14] S. N. Kaul, *Phys. Rev. B*, **24** (1981), 6550.
- [15] B. E. Argyle, S. H. Charap and E. W. Pugh, *Phys. Rev.*, **132**(1963), 2051.

12949

CSO: 4009/1090

AUTHOR: ZHENG Jiaqi [6774 1367 4388]
 LI Ming [2621 2494]
 GAO Jie [7559 2212]
 et al.

ORG: Institute of Physics, Academia Sinica, Beijing

TITLE: "Preparation of Thin V Films and Their Superconducting Transition Temperatures"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 259-263

TEXT OF ENGLISH ABSTRACT:

Thin V films are deposited on the crystallite-glass and the fused quartz substrates at the temperature greater than 150°C under the vacuum of 1×10^{-5} torr in the general vacuum system with an electron gun source. The analyses of Auger electron spectra show that V films contain a greater amount of oxygen and carbon and that the oxygen peak in the interior of the V film is much lower than that at the surface. The superconducting transition temperatures of V films, T_c , have been measured and the maximum T_c is 4.35 K. The transition temperatures of V films are proportional to the ratio of the resistances, $(\rho_{300} - \rho_r) / \rho_{300}$. In this paper we emphasize that there are two important factors for preparing V films with T_c greater than 4K even if the vacuum is as poor as 1×10^{-5} torr during the deposition. One is keeping the substrate temperature at higher temperature. The other is that before the deposition the pre-evaporation should be done for several times to reduce the partial pressure of the residual gas O₂ in the vacuum chamber.

References

- [1] L. R. Testardi, J. H. Wernick and W. A. Royer, *Solid state Commun.*, 15 (1974), 1.
- [2] J. Zasadzinski, D. M. Burnell and E. L. Wolf, *Phys. Rev.*, B25 (1982), 1622.
- [3] L. Y. L. Shen, *Phys. Rev. Lett.*, 24 (1970), 1104.
- [4] C. A. Neugebauer and R. A. Echvall, *J. Appl. Phys.*, 35 (1964), 547.
- [5] H. Seifarth and W. Rentsch, *Phys. Stat. Sol.*, A18 (1973), 135.
- [6] R. J. Noer, *Phys. Rev.*, B12 (1975), 4882.
- [7] I. K. Yanson and L. F. Rybalchenko, *Phys. Stat. Sol.*, A28 (1975), 663.
- [8] S. I. Vedenev and A. V. Pogrebuyakov, *Sov. Phys. Solid State*, 20 (1978), 1223.
- [9] P. M. Tedrow and R. Meservey, *Phys. Lett.*, 69A (1978), 285.
- [10] Shigeyoshi Watanabe, Masashi Nishioka, Kiyomi Okamoto and Mitsuru Awano, *Phys. Lett.*, 74 A (1979), 441.
- [11] H. Q. Yang and J. B. Ketterson, Private Communication.
- [12] V. M. Kuzmenko, V. G. Lararev, V. I. Melnikov and A. I. Sudovtsov, *Sov. Phys. JETP*, 40 (1975), 398.
- [13] H. L. Caswell, *J. Appl. Phys.*, 32 (1961), 105.
- [14] H. L. Caswell, *IBM Res Develop.*, 4 (1960), 130.
- [15] H. Van Beelen, R. De Bruynoutbater, I. I. Meenakker and K. W. Taconis, *Proc. 8th Int. Conf. Low Temp. Phys.*, (1962), p. 378.

12949

CSO: 4009/1090

Cryogenics

AUTHOR: HAN Hanmin [7281 3352 3046]
JIAO Zhengkuan [3542 2973 1401]
BI Yanfang [3968 1693 5364]

ORG: Institute of Plasma Physics, Academia Sinica, Hefei

TITLE: "Protection of Superconducting Magnets with the Secondary-Short-Circuit"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 264-270

TEXT OF ENGLISH ABSTRACT:

Studies have been made on the difficulties in large superconducting magnet protection against its melt and high voltage, and the principle of protection with a secondary short-circuit. A Nb-Ti superconducting magnet with a secondary short-circuit made of high purity aluminium wire has been used for test. The experimental observations show that when the power supply is switched off, and when the magnet is still in superconducting state, the stored energy of the magnet is essentially transferred into the secondary winding. When the magnet was quenched by heating a part of the magnet current is transferred into the secondary-short-circuit. The greater the initial current of magnet, the greater is the transfer rate. We have also observed that the secondary winding apparently decreases the end voltage of magnet when the power supply is cut off.

References

- [1] 宋胜年、张其瑞、焦正宽, 物理, 12(1983), 538.
- [2] M. A. Green, *IEEE Trans on mag*, MAG-17 (1981), 1793.
- [3] 焦正宽、王金星等, 低温物理, 5(1983).
- [4] P. H. Eberhard et al. *Nuc Instru and methods*, 158 (1979).
- [5] M. A. Green. The Development of large high Current Density Superconducting Solenoid for use in High Energy Physics experiments (ph. D. Thesis) May (1977).

12949

CSO: 4009/1090

Cryogenics

AUTHOR: WEI Chongde [5898 1504 1795]

ORG: Department of Physics, Beijing University

TITLE: "The Influences of Nonequilibrium Quasiparticle Recombination Time on the Inhomogeneous Threshold of Superconducting Thin Film"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 282-285

TEXT OF ENGLISH ABSTRACT:

According to Scalapino-Huberman equation, it is suggested that the influence of nonequilibrium quasiparticle number on the quasiparticle recombination time should bring about changes in the long wave parts of the S - H results and that the time period solutions should be obtained.

References

- [1] C. S. Owen, D. J. Scalapino, *Phys. Rev. Lett.*, **28**(1972), 1559.
- [2] J. J. Chang, D. J. Scalapino, *Phys. Rev.*, **B 10** (1974), 4047.
- [3] D. J. Scalapino, B. A. Huberman, *Phys. Rev. Lett.*, **39** (1977), 1365.
- [4] K. Hida, *J. Low Temp. Phys.*, **32** (1978), 881.
- [5] J. J. Chang, D. J. Scalapino, in "Superconductor Application: SQUIDS and Machines", edited by B. B. Schwartz, S. Four., (1977), p. 447.
- [6] B. П. Семиноженко., *ФТТ*, **15** (1973), 2913.
- [7] C. 基泰尔: 固体物理导论(中译本).
- [8] S. B. Kaplan., et al., *Phys. Rev.*, **B 14** (1976), 4854.
- [9] A. L. Fetter, J. D. Walecka., *Quantum Theory of many-partile systems* (1971)
- [10] I. Iguchi, et al. *Phys. Rev.*, **B 24** (1981).
- [11] 卫崇德等, *Physica*, **107B**(1981), 589.
- [12] 卫崇德等, *物理学报* **32**(1983), 1069.

12949

CSO: 4009/1090

Cryogenics

AUTHOR: ZHOU Wensheng [0719 2429 3932]
W.P. Halperin

ORG: ZHOU of the Department of Physics, Beijing University and HALPERIN of the Department of Physics, Northwestern University, U.S.

TITLE: "Frequency Dependence of the Freezing Temperature in CoGa Spin Glasses"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 282-285

TEXT OF ENGLISH ABSTRACT:

Temperature dependence of low-field-ac-susceptibility (temperature range: 1:8—40K, frequency range: 15—1000 or 5000Hz) and that of low-field-dc-magnetization on $\text{Co}_x\text{Ga}_{1-x}$ slow-cooled spin glasses ($0.52 \leq x \leq 0.56$) are shown in this paper. The experimental results obey the Fulcher law: $\tau = \tau_0 \exp[E_s/k(T_f - T_f^0)]$. A phenomenological interpretation has been made, suggesting that the freezing of the local magnetic moments in spin cluster glasses at T_f^0 is the phase transition and this freezing in the temperature range of $T \gtrsim T_f^0$ exhibits relaxation behavior.

References

- [1] M. W. Meisel, Wensheng Zhou, J. R. Owers-Bradley, Y. Ochiai, J. O. Brittain and W. P. Halperin, *J. Phys. F.*, **12**(1982), 317.
- [2] K. Binder, *Z. Phys. B.*, **48**(1982), 319.
- [3] E. D. Dahlberg, M. Hardiman, R. Orbach, J. Souletie, *Phys. Rev. Lett.*, **42**(1979), 401.
- [4] J. L. Tholence, *Solid State Commun.*, **35**(1980), 113.
- [5] G. Zibold, *J. Phys. F*, **8**(1978), L229.
- [6] H. Maletta and W. Felsch, *Phys. Rev. B*, **20**(1979), 1245.
- [7] J. R. Owers-Bradley, Wen-sheng Zhou, W. P. Halperin, *Rev. Sci. Instrum.*, **52**(1981), 1106.
- [8] G. I. Fulcher, *J. Am. Ceram. Soc.*, **8**(1925), 339, 789.
- [9] A. P. Malozemoff and Y. Imry, *Phys. Rev. B*, **24**(1981), 489.
- [10] K. Binder, *Z. Phys. B*, **26**(1977), 339.
- [11] S. F. Edwards, P. W. Anderson, *J. Phys. F*, **5**(1975), 965.
- [12] Wen-Sheng Zhou, M. W. Meisel, J. R. Owers-Bradley, W. P. Halperin, *Phys. Rev. B*, **27**(1983), 3119.

12949

CSO: 4009/1090

Cryogenics

AUTHOR: PENG Jianbang [1756 1696 6721]
RUAN Yaozhong [7086 5069 6988]
HE Pingsheng [0149 1627 4563]
TANG Hong [3608 3163]

ORG: University of Science and Technology of China, Hefei

TITLE: "Thermoelectric Power PTS Single Crystal at Low Temperatures"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 317-318

TEXT OF ENGLISH ABSTRACT: The thermoelectric power of PTS has been measured in terms of differential method in the range from 77 to 273 K. The results show the thermoelectric power of PTS increases linearly with temperature. There is a jump in the thermoelectric power near 114 K. At about 150 K and 220 K the thermoelectric power decreases rapidly and two drop-peaks of the power curve occur respectively.

References

- [1] P. Robin et al., *J. Physique*, 41(1980), 417.
- [2] P. Robin et al., *Chem. Phys. Lett.*, 71 (1980), 217.
- [3] M. Mertault, A. Collet, and M. Schott, *J. Physique-Lett.*, 42 (1981), 131.
- [4] D. Q. Xiao et al., *Chem. Phys. Lett.*, 90(1982), 247.
- [5] Peng Jianbang, He Pingsheng et al., Proceedings of Bilateral Symposium on the Synthesis and Materials Science of Polymers (1984, Beijing, China).
- [6] G. Wegner, *Makromolek.*, 145(1971), 85.
- [7] J. Chaussy, A. Guessous, and J. Mazuer, *Rev. Sci. Instrum.*, 52 (1981), 1721.
- [8] 阮耀钟, 林鹏, 王敬, 姚陵, 低温物理(待发表).
- [9] 何平笙, 江志坚, 朱志伟, 中国科学技术大学学报, 14(1984), 371.

12949

CSO: 4009/1090

Cryogenics

AUTHOR: YAN Jialie [7346 1367 3525]
XU Jianjian [1776 0256 0256]
SHAO Huimin [6730 1920 3046]
et al.

ORG: Department of Physics, Nanjing University

TITLE: "A Simple Apparatus for Measuring Susceptibility of Superconducting Materials"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 299-302

TEXT OF ENGLISH ABSTRACT:

A simple apparatus to obtain direct and continuous recordings of the variation of the imaginary χ'' and the real part χ' of the susceptibility of superconducting materials is reported in this paper. This apparatus is inexpensive. In addition its construction presents no difficulty and it is quickly operational. The whole performance of the measuring system was examined by using Pb direct reading of χ' and χ'' are given.

References

- [1] C. A. M. Van Der Klein et al., *Physica*, 49(1970), 98.
- [2] T. Ishida, H. Mazaki, *Phys. Rev.*, B 20 (1979), 131.
- [3] T. Aomine, *J. Phys. Soc. Japan*, 25 (1968), 1585.
- [4] E. Maxwell, et al., *Phys. Rev. Letters*, 10 (1963), 212.
- [5] H. Fink, *Phys. Rev. Letters*, 16 (1966), 447.
- [6] 南京大学低温物理电磁测试组, 物理学报, 23(1975), 307.

12949

CSO: 4009/1090

Cryogenics

AUTHOR: SHEN Jialin [3088 0857 7792]
ZHUANG Guoxuan [8369 0948 6693]
WU Yong [0702 0516]
CAI Wujuan [5591 2477 0239]

ORG: SHEN, ZHUANG and WU of Zhejiang Institute of Computing Technology; CAI of Yuanan Institute of Thermal Meters

TITLE: "The Application of Microcomputers to the Measuring Technology of Platinum Resistance"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 309-314

TEXT OF ENGLISH ABSTRACT:

The platinum resistance thermometer is a standard interpolating instrument of the international practical temperature scale of 1968 (IPTS-68). But the formula for resistance-temperature stipulated by IPTS-68 is very complex and has given rise to problems in calculation and measurement of low temperature. This paper, from the viewpoint of software, gives an account of how to solve the above-mentioned problems by using the technology of microcomputers and illustrates with examples the possibility to solve them.

References

- [1] 庄国选、沈嘉麟、吴勇, 计算技术通讯, 1 (1983), 19.
- [2] 蔡无倦, 云仪技报, 4 (1982), 15.

12949
CSO: 4009/1090

Cryogenics

AUTHOR: HUANG Huizhi [7806 1920 2535]
LUO Kunlun [5012 2494 0178]
YAN Shijian [7346 1102 0256]

ORG: Institute of Electrical Engineering, Academia Sinica, Beijing

TITLE: "Experimental Investigation of the 7.22 T NbTi Pulse Superconducting Magnet"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 295-298

TEXT OF ENGLISH ABSTRACT:

This paper describes the experimental results of a superconducting coil with a d.c. central field 7.22 T, maximum field 7.94 T and pulse operating peak field 6.99 T. The peak field is 96.6 per cent as large as d.c. critical field.

12949
CSO: 4009/1090

Cryogenics

AUTHOR: HE Mu [0149 3668]
LI Chuanyi [2621 0278 5030]
GAO Ruifen [7559 3843 5358]
et al.

ORG: HE of Shanghai Institute of Metallurgy, Academia Sinica; LI of the Department of Physics, Beijing University; and GAO of the Department of Physics, University of Science and Technology of China, Hefei

TITLE: "Effect of In, Ga, on the Diffusion Process and Superconducting Properties of Nb₃Sn Composites Formed from High-Tin Content Cu-Sn Alloys"

SOURCE: Beijing DIWEN WULI [ACTA PHYSICA TEMPERATURAE HUMILIS SINICA] in Chinese Vol 6, No 4, Dec 84 pp 286-294

TEXT OF ENGLISH ABSTRACT:

This paper presents the preliminary experimental results of the effect of In, Ga additives on the diffusion process and superconducting critical properties of Nb₃Sn multifilamentary composites formed from high-tin-content Cu-Sn alloy.

References

- [1] S. Murasa et al., *IEEE Trans. Magn.*, MAG-15(1979), 83.
- [2] H. Yamasaki et al., "Multifilamentary Nb₃Sn by the Solid-Liquid Diffusion Method-The Mechanism and the Superconducting Properties" ICEC9-1CMC Preprints, Kyoto, 1982.
- [3] 何牧等, 低温物理, 3(1982), 17.
- [4] M. Suenaga, "Metallurgy of Continuous Filamentary Al₅ Superconductors" *Superconductor Materials Science-Metallurgy, Fabrication and Applications* Edited by S. Foner and B. B. Schwarz (Plenum, New York) Chapter 4.
- [5] S. Kwon et al., *J. Appl. Phys.*, 54(1983), 1008.

12949
CSO: 4009/1090

AUTHOR: HU Guoan [5170 0948 1344]
CHEN Xiexiong [7115 0253 7160]

ORG: Hangzhou University

TITLE: "Research of the CMOS Circuits for Optimal Universal-Logic-Gate"

SOURCE: Hangzhou HANGZHOU DAXUE XUEBAO (ZIRAN KEXUE BAN) [JOURNAL OF HANGZHOU UNIVERSITY (NATURAL SCIENCES EDITION)] in Chinese Vol 11, No 3 Jul 84 pp 316-324

TEXT OF ENGLISH ABSTRACT: Two CMOS practical circuits for the optimal Universal-Logic-Gate (ULG.2) are presented. Through theoretical analysis, experiments and comparison with traditional CMOS gates, it is considered that either of the two practical circuits for ULG.2 may be adopted as a standard cell for LSI uncommitted logic arrays.

12949
CSO: 4009/1028

AUTHOR: WANG Fuzhen [3769 4395 6297]
JIAO Wenlai [3542 2429 0171]
ZHANG Jianhua [1728 1696 5478]
et al.

ORG: Department of Metallic Materials and Engineering, Beijing Polytechnic University

TITLE: "The V-P Structure Model for Ion Plated Aluminum"

SOURCE: Beijing ZHENKONG KEXUE YU JISHU [VACUUM SCIENCE AND TECHNOLOGY]
in Chinese Vol 4 No 5, Sep 84 pp 297-305

TEXT OF ENGLISH ABSTRACT: The effects of different argon pressures and substrate biases on the Al-film structure have been systematically studied with a 240° e-type electron beam gun used as the source of the vapor. A model, named the Al-Film V-P Structure Model by Ion Plating (V-P Model), is established with two variables, argon pressure and substrate bias. It is shown from the model that at the different argon pressures needed to eliminate conical and columnar grains, different substrate biases are needed. If the argon pressure is higher than 5×10^{-3} torr, the bias needed to eliminate the above grains decreases with the increase of argon pressure. If the pressure is lower than 5×10^{-3} torr, this bias decreases with the decrease of the pressure. This bias value reaches its maximum at 5×10^{-3} torr.

It is suggested that this three-dimensional V-P structure model is a result of the combination of the effects of different pressures and biases on Al-film structure during deposition.

References

- [1] D.M. Mattox and J.E. Macdonald, J. Appl. Phys., 34(1963)2493.
- [2] B.A. Movchan and A.V. Demchishin, Fiz Met. Metallurg., 28 (1969) 653.
- [3] 難波義捷, 毛利敏男, 真空, 16 (1973) 96.
- [4] J.A. Thornton, J. Vac. Sci. Technol., 11 (1974) 66.
- [5] 小宮宗治, 金属材料, 15, 10 (1978) 27.
- [6] 難波義捷, 应用物理, 38 (1969) 11.
- [7] D.G. Teer and B.L. Delced, Thin Solid Films., 54 (1977) 295.
- [8] R.F. Bunshan and R.S. Tuntty J. Vac. Sci. Technol., 9 (1972) 1402.
- [9] 網沢栄二, 中山久参, 金属表面技术, 32, 10 (1981) 575.
- [10] M. Lardon, R. Bunl, H. Signer, E. Moll and H.K. Pulker, Thin Solid Films, 54 (1978) 317
- [11] 柏木邦宏, 金属表面技术, 35 (1979) 5.
- [12] C.T. Wan, D.L. Chambers and D.G. Carmicheal, Proc. 4th Intern. Congr. Vac. Metallurgy, Tokyo, (1973) 231.
- [13] J.D. Combine, Gaseous Conductors, Dover Publications, Inc, New York, 1958.
- [14] D.G. Teer, J. Adhesion, 8 (1977) 289.

AUTHOR: ZHANG Zhuangjian [4545 1104 0256]
YANG Xiliang [2799 6932 5328]
SUN Yunlong [1327 0061 7893]

ORG: Fudan University, Shanghai

TITLE: "Nitrogen Spectrum Leak Detector"

SOURCE: Beijing ZHENKONG KEXUE YU JISHU [VACUUM SCIENCE AND TECHNOLOGY]
in Chinese Vol 4 No 5, Sep 84 pp 306-310

TEXT OF ENGLISH ABSTRACT: Some experimental results of the nitrogen spectrum leak detector are described. The spectra excited in a Penning ionization gauge can be used for quick monitoring of the pressure in a vacuum system and for leak detection.

Discharge spectra for various gases at a pressure of about 10^{-4} Torr were obtained and compared. Three strong spectral lines in the visible region have been found for nitrogen. Computational results indicate that these lines are due to the transitions from $v' = 0$ of the electronic excited state to $v'' = 0, 1$ and 2 of the electronic ground state for N_2^+ respectively.

The $4278 \text{ \AA}$ nitrogen ion spectral line was chosen as a working reference for leak detection. In a vacuum system consisting of an oil diffusion pump and a mechanical pump, the ratios between the photocurrent at $4278 \text{ \AA}$ to the total photocurrent were obtained under different conditions.

Using oxygen as the probing gas, under the present experimental conditions the lowest detectable leakage rate is less than 3×10^{-7} Torr·liter/sec with a response of several seconds.

References

- [1] 华中一, 高真空技术与设备 (第二版), P.162 (1962)
- [2] W.Knauer, J.Appl,phys,33,2093 (1962)
- [3] G.Herzberg, Spectra of Diatomic molecules, 2nd edition, P.151 (D. Van Nostrand Company, New York)

AUTHOR: LI Shenglin [2621 0524 2651]
SHAO Shumin [6730 3219 2404]
ZHOU Zhiqiang [0719 1807 1730]
et al.

ORG: A Glass Apparatus of Molecular Beam for Investigating Gas-Surface Interactions"

SOURCE: Beijing ZHENKONG KEXUE YU JISHU [VACUUM SCIENCE AND TECHNOLOGY]
in Chinese Vol 4 No 5, Sep 84 pp 319-323

TEXT OF ENGLISH ABSTRACT: A molecular beam glass apparatus for investigating gas-surface interactions is described. It was designed and manufactured in light of specific conditions at our laboratory. Its advantages are low cost and ease in manufacturing. In this apparatus a molecular beam study of catalytic oxidation of CO on Pt (polycrystalline) has been performed. Experimental results reveal that this apparatus can characterize different processes of gas-surface reactions (heterocatalysis).

References

- [1] S.L. Bernasek, et al., Prog. Surf. Sci., 5, No. 4 (1975) 377
- [2] 席光康, 真空科学与技术, 1, No. 6 (1981) 385
- [3] R.L. Palmer, et al., J. Chem. Phys., 60, No. 4 (1974) 1453
- [4] C.T. Campbell, et al., J. Chem. Phys., 73, No. 11 (1980) 5862
- [5] B. Poelsema, et al., J. Vac. Sci. Technol. A 1 No. 2 (1983) 1078
- [6] 王君荣等, 真空科学与技术, 2, No. 6 (1982) 347
- [7] L. Valyi, Atom and Ion Sources, (1977) 84
- [8] W.L. Winterbottom, Surf. Sci., 37 (1973) 205

AUTHOR: XU Zhizhong [1776 5267 0022]
DAI Daoxuan [2071 6670 1357]
ZOU Huiliang [6760 1920 5328]

ORG: XU and DAI of the Modern Physics Research Institute, Fudan University;
ZOU of the Measuring Technique Research Institute, Shanghai Metrology Bureau

TITLE: "A Line Shape Analysis of $\text{SiL}_{2,3}\text{VV}$ Auger Spectrum on the Cleaved (111) Surface"

SOURCE: Beijing ZHENKONG KEXUE YU JISHU [VACUUM SCIENCE AND TECHNOLOGY]
in Chinese Vol 4 No 5, Sep 84 pp 332-334

TEXT OF ENGLISH ABSTRACT: The $\text{SiL}_{2,3}\text{VV}$ Auger spectrum on a cleaved (111) surface was measured. The local transition density of state on this surface has been obtained by digital integration, back subtraction and self-deconvolution techniques. The results agree well with the optical density of state measured by UPS on the Si (111) 2×1 surface.

AUTHOR: LIU Youying [0491 0645 1305]
CAO Jiagui [2580 1367 2710]
LI Wang [2621 2598]
ZHAN Zhenzong [1455 2182 1350]

ORG: LIU and CAO of the Physics Department, Nankai University, Tianjin;
LI and ZHAN of North China Research Institute No 3, Tianjin

TITLE: "On Mg Enrichment of the Surfaces of Alloys Ni-W-Mg and Ni-Mg"

SOURCE: Beijing ZHENKONG KEXUE YU JISHU [VACUUM SCIENCE AND TECHNOLOGY]
in Chinese Vol 4 No 5, Sep 84 pp 335-338

TEXT OF ENGLISH ABSTRACT: The base metals of oxide-coated cathodes, an alloy of Ni-W-Mg and the Ni-Mg alloy containing a high concentration of Mg which have not been heat treated, were cleaved by low energy argon ions (2 keV) and analyzed by an Auger electron spectrometer (PHI 550). It can be seen from the Auger electron spectra of the elements that there were enrichment layers of Mg on the surfaces of the specimens.

The experiments relative to the reasons for forming Mg enrichment have been carried out and the related reasons are discussed.

References

- [1] 严申生等, 真空科学与技术, 6期(1982年)P.401
- [2] 刘友婴等, Ni-Mg, Ni-W-Mg 合金的二次离子质谱研究 (待发表)
- [3] W.M.H.Sachtler, et al. Applications of Surface Science, 3, (1979) P.350
- [4] R.Bouwman, et al. Journal of Catalysis, 25(1972)p.350
- [5] R.A.van Santen, et al. Surface Science 47(1975)p.64
- [6] 吉林大学等编, 物理化学基本原理, 下册
- [7] I.S.T.Tsong, et al. Journal of Materials Science 8(1973)p.123
- [8] O.Aimen, et al. Nuclear Instruments and Methods 11(1961)p.257

9717

CSO: 4009/1069

AUTHOR: XU Zhiwei [1776 1807 5898]
 LU Renjie [7120 0088 2638]
 CHEN Minheng [7115 2404 1854]

JPRS-CST-85-029
 3 September 1985

ORG: East China Institute of Chemical Technology

TITLE: "Effect of Micromixing upon Selectivity of a Homogeneous Instantaneous Complex Reaction. (I) Dual-sphere Model"

SOURCE: Beijing HUAGONG XUEBAO [JOURNAL OF CHEMICAL INDUSTRY AND ENGINEERING (CHINA)] in Chinese No 1, Mar 85 pp 11-19

TEXT OF ENGLISH ABSTRACT: An instantaneous homogeneous complex reaction is essentially an unsteady-state diffusion-reaction process, in which product distribution depends upon the degree of micromixing of the reactants. A dual-sphere model is developed here. By taking a competitive second-order reaction system as an example and using an appropriate computational method, the influences of different parameters on the reaction results have been simulated and discussed. (Received on 14 March 1983 and finalized on 28 May 1984.)

References

- (1) 陈敏恒, 翁元恒等, "化学反应工程基本原理" 化学工业出版社, 北京, 18(1982)。
- (2) Hinze, J. O., "Turbulence", McGraw-Hill, New York(1959)。
- (3) Brodkey, R. S., "Turbulence in Mixing Operation", Academic Press Inc., New York, (1975)。
- (4) Zoulalier, A. and Villermaux, J., Advances in Chemistry Series, No133, 348, Am. Chem. Soc., Washington, (1974)。
- (5) Bourne, J. R., Rys, P. and Suter, K., *Chem. Eng. Sci.*, 32, 711(1977)。
- (6) Paul, E. L. and Treybal, R. E., *AIChE J.*, 17, 718(1971)。
- (7) 华东化工学院化机系, "化学反应器数学模拟放大", 上海科学技术情报研究所, (1974)。
- (8) 陈敏恒, 陆仁杰, 石油化工, (10)634, (1981)。
- (9) Ott, R. J. and Rys, P., *Helvetica Chimica Acta*, 58, 2074(1975)。
- (10) Nabbolz, F., Ott, R. J. and Rys, P., *ibid.* 60, 2926(1977)。
- (11) Bourne, J. R., Kozicki, F. and Rys, P., *Chem. Eng. Sci.*, 36, 1643(1981)。
- (12) Caldin, E. F., "Fast Reaction in Solution", Blackwell Scientific Publications, Oxford, (1964)。
- (13) 中国科学院沈阳计算技术研究所等, "电子计算机常用算法", 科学出版社 (1976)。
- (14) 祝楚恒, 计算数学, (4)396(1980)。
- (15) 徐志卫, 华东化工学院硕士研究生毕业论文(1982)。

AUTHOR: CAO Zhiqiang [2580 1807 1730]
XU Xi [1776 0296]

ORG: Polymer Research Institute, Chengdu University of Science and Technology

TITLE: "Ultrasonic Degradation and Copolymerization of Polyvinyl Acetate with Partially Hydrolyzed Polyacrylamide"

SOURCE: Beijing HUAGONG XUEBAO [JOURNAL OF CHEMICAL INDUSTRY AND ENGINEERING (CHINA)] in Chinese No 1, Mar 85 pp 56-64

TEXT OF ENGLISH ABSTRACT: The ultrasonic degradation and copolymerization of polyvinyl acetate (PVAc) with partially hydrolyzed polyacrylamide (HPAM) in ethanol/water (55/45) have been studied. The experimental results show that the rate of degradation of PVAc follows Ovenall's equation approximately and that of HPAM deviates from the equation. The effects of the ultrasonic intensity and reaction temperature on the rates of degradation are the same. By irradiating 0.50 percent PVAc/HPAM (1/1 by weight) at 25°C with ultrasound of 18.2 kHz and 2.4 A input current on a reversed main circuit for 10 minutes, the copolymer yield was 4.3 percent. Its structure was identified by means of a solubility test, IR, NMR, element analysis, electron microscope and phase contrast microscope, and the copolymer was proved to be mainly a block one. (Received on 27 January 1983, and finalized on 2 April 1984.)

References

- (1) Goring, G. E., Curran, G. P., Tarbox, R. P. and Gorin, E., *Ind. Eng. Chem.* 44 (5) 1057 (1952).
- (2) Figueiredo, J. L. and Trimm, D. L., *J. Catal.* 40, (2) 154 (1975).
- (3) Bernardo, C. A. and Trimm, D. L., *Carbon* 17, (2) 115 (1979).
- (4) 华东石油学院物化科研组, 《石油科技通讯》, (2) 17 (1976).
- (5) 山东胜利石油化工总厂科研所, 《石油化工》, (3) 170 (1980).
- (6) Trimm, D. L., *Trans. Inst. Chem. Eng.* 54, (2) 119 (1976).

AUTHOR: SUN Zaichun [1327 0961 2504]
CHEN Tingrui [7115 1694 5624]
YANG Jitao [2799 4949 3447]
et al.

ORG: East China Petroleum Institute

TITLE: "Kinetic Study of Carbon Gasification on Nickel Catalysts with Steam-Hydrogen Mixture"

SOURCE: Beijing HUAGONG XUEBAO [JOURNAL OF CHEMICAL INDUSTRY AND ENGINEERING (CHINA)] in Chinese No 1, Mar 85 pp 29-36

TEXT OF ENGLISH ABSTRACT: The kinetic features of the gasification with a H_2O-H_2 mixture of carbon deposited on the nickel catalysts for steam reforming of naphth are reported in the temperature range of 723-973K. Investigations were mainly carried out in a TG-monitored flow reactor system. Two kinds of industrial nickel catalysts, the domestic Z402 and the British ICI46-1, were selected for study.

Empirical rate equations of carbon gasification with H_2O-H_2 mixture were obtained for the lower and higher temperature ranges respectively. Empirical rate equations of carbon gasification with steam alone were also given for comparison.

A TG-scan of the carbon gasification process revealed that steam alone does have an oxidizing effect on the nickel catalyst and that, with a H_2O-H_2 mixture of a suitable H_2O/H_2 ratio, this effect can be eliminated. This will prevent the catalyst from deteriorating due to repeated oxidation and reduction.

It was shown that H_2 in the H_2O-H_2 mixture has two opposite functions. It has an inhibiting effect through its negative reaction order, but can also have an accelerating effect by keeping the Ni catalyst from being oxidized by steam. This is significant for the lower temperature region where the rate of carbon gasification is usually low. (Received on 26 February 1983, and finalized on 17 September 1983.)

References

- [1] 波川尚, 中島章夫, 高分子化学 (日本), 11, 142 (1954).
- [2] Klein, J. and Conrad, K. D., *Die Makromolekulare Chemie*, 179, 1635 (1979).
- [3] 胡星琪, 徐德, 化工学报, (4) 319 (1982).
- [4] Ovenall, D. W., Hasting, G. W. and Allen, P. E. M., *J. Polym. Sci.*, 33, 207 (1958).
- [5] Ovenall, D. W., *J. Polym. Sci.*, 42, 458 (1960).

AUTHOR: BAO Qinai [7637 0366 7845]

ORG: Research Laboratory, Anqing Petrochemical Works

TITLE: "A Model for Predicting Fouling Behavior of Cooling Water"

SOURCE: Beijing HUAGONG XUEBAO [JOURNAL OF CHEMICAL INDUSTRY AND ENGINEERING (CHINA)] in Chinese No 1, Mar 85 pp 78-84

TEXT OF ENGLISH ABSTRACT: Extensive experimentation on a simulated fouling testing facility showed that cooling water initially fouled quite rapidly, but ultimately the rate of fouling diminished to some constant, asymptotic values. Frequently it was observed that an induction period existed before the formation of any deposit, and an implicit solution of the Kern-Seaton equation could therefore not be obtained satisfactorily by trial-and-error.

Based on a large set of data, a new model was postulated to show the above mechanism of fouling:

$$R_f = R_f^* \exp(-A/(t-t_0))$$

This exponential model involves an induction period, and linearized regression could be used to solve for the parameters R_f and A .

Results of regression analysis of 60 runs with a TI-59 programmable calculator indicate that most correlation coefficients for the new model are greater than 0.9. With this new equation, the asymptotic fouling resistance can be estimated directly from experimental data. (Received on 22 March 1983, and finalized on 10 December 1983.)

References

- [1] Taborek, J., Aoki, T., Ritter, R. B., Palen, J. W. & Knudsen, J. G., *Chem. Eng. Prog.*, 68(2)59 (1972).
- [2] Kern, D. Q. & Seaton, R. E., *Chem. Prog.*, 55(6)71(1959).
- [3] Kern, D. Q., "Proc. 3rd Int. Heat Transfer Conf.", Vol. I, Chicago, U. S. A. (August 1966).
- [4] 南京化工学院防腐专业委员会, 石油化工给排水, (2)3(1976).
- [5] Morse, R. W. & Knudsen, J. G., *Can. J. Chem. Eng.*, 55(6)272(1977).
- [6] 谢舜韶、龙荷云, 南京化工学院院报, (1)50(1981).
- [7] Taborek, J., Aoki, T., Ritter, R. B., Palen, J. W., & Knudsen, J. G., *Chem. Eng. Prog.*, 68(7)69 (1972).
- [8] Knudsen, J. G., "Proc. 7th Int. Heat Transfer Conf.", RK11, p.269, Munich, West Germany (Sept. 1982).

9717

CSO: 4009/1072

AUTHOR: HAN Guangyao [7281 0342 5069]
ZHANG Yuchang [1728 3022 2490]
Yi Ming [2496 2494]
et al.

ORG: Physics Department, Nanjing University

TITLE: "Double Grating Frequency Shift Effect of Laser Beam and Its Application"

SOURCE: Shanghai ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] in Chinese
Vol 12, No 6, 20 Jun 85 pp 343-345, 329

TEXT OF ENGLISH ABSTRACT: Frequency shifts of the double grating is considered and confirmed by our experiment. Using this effect we determine the value of velocity or small displacement. It is simpler than the method of Michelson's instrument or the intensity modulating method and has been successfully tested on Mossbauer spectrometer to determine the velocity of vibration. Satisfactory results have been obtained.

12949
CSO: 4009/265

Lasers

AUTHOR: FENG Xiqi [7458 6932 3217]
TANG Yuanfen [0781 0337 3083]
WU Huifa [0702 1920 3127]
et al.

ORG: Shanghai Institute of Ceramics, Academia Sinica

TITLE: "Investigation on the Barium Sodium Niobate Acoustic-optic Modulator/Frequency Doubler for Nd: YAG Lasers"

SOURCE: Shanghai ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] in Chinese Vol 12, No 6, 20 Jun 85 pp 350-352, 342

TEXT OF ENGLISH ABSTRACT: We have achieved the acoustic-optic modulation and the second harmonic generation for Nd: YAG lasers simultaneously in the same barium sodium niobate crystal. In this paper, the structure and fabrication of this complex functional device are described. Its central frequency is 129 MHz and total diffraction efficiency is higher than 50 percent (6328 Å) at a driving voltage of 3 volts.

12949

CSO: 4009/265

Lasers

AUTHOR: GUO Chu [6753 4342]
ZHANG Xingkang [1728 5281 1660]
SHAO Ziwen [6730 1311 2429]
YUE Chuanhua [1471 0278 5478]

ORG: GUO and ZHANG of the Institute of Chemistry, Academia Sinica, Beijing;
SHAO and YUE of the Shanghai Institute of Laser Technology

TITLE: "Photophysical Parameters and Lasing Characteristics of DCM--Propylene Carbonate System"

SOURCE: Shanghai ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] in Chinese
Vol 12, No 6, 20 Jun 85 pp 358-362

TEXT OF ENGLISH ABSTRACT: Based on our study of photophysics of DCM in different solvents, it has been suggested that propylene carbonate can be used as a more attractive solvent for DCM lasing medium. This prediction has been demonstrated by the experimental results reported in this paper.

12949

CSO: 4009/265

Lasers

AUTHOR: LOU Qihong [2869 4388 3163]
LIU Bo [0491 3134]
CAO Hongmin [2580 1738 2404]
et al.

ORG: Shanghai Institute of Optics and Fine Mechanics, Academia Sinica

TITLE: "Experimental Research on the Multichannel Rail Gap for Transverse Discharge Gas Lasers"

SOURCE: Shanghai ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] in Chinese
Vol 12, No 6, 20 Jun 85 pp 363-365

TEXT OF ENGLISH ABSTRACT: The multichannel rail gap for transverse discharge gas laser has been developed. The effects of trigger voltage and trigger electrode configuration on the characteristics of the rail gap were studied, and 29 channels per meter in a rail gap of 38cm long was obtained.

12949
CSO: 4009/265

Lasers

AUTHOR: ZHANG Guoxuan [1728 0948 6513]
LIU Yupu [0491 3768 3877]
ZHANG Yinghua [1728 1758 5478]
et al.

ORG: Shanghai Institute of Optics and Fine Mechanics, Academia Sinica

TITLE: "Design and Analysis of Resonators for the CW Dye Laser Pumped by an Ar⁺ Laser"

SOURCE: Shanghai ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] in Chinese
Vol 12, No 6, 20 Jun 85 pp 366-369

TEXT OF ENGLISH ABSTRACT: The design of the folded three-mirror cavity and four-mirror ring cavity is described. The effects of the cavity adjustment on the properties of laser resonators have been emphasized. The analyses are important for the correct design and alignment of the cavity.

12949

CSO: 4009/265

JPRS-CST-85-029
3 September 1985

AUTHOR: WU Zonghan [6762 1350 3352]
LIU Xiaolin [0491 1321 7792]
ZHU Yungui [2612 0061 2710]
GAO Tong [7559 1749]

ORG: Zhejiang Provincial Weather Bureau

TITLE: "The Nested and Relaying Grid Model Used for Typhoon Track Numerical Forecasting"

SOURCE: Hangzhou HANGZHOU DAXUE XUEBAO (ZIRAN KEXUE BAN) [JOURNAL OF HANGZHOU UNIVERSITY (NATURAL SCIENCES EDITION)] in Chinese Vol 11, No 3 Jul 84 pp 363-368

TEXT OF ENGLISH ABSTRACT: Based on large-scale numerical forecast, the model can provide more accurate forecasting with smaller computers. The primitive equations in this model are divided into two parts: advective process and adjustment process. The split explicit integrating scheme is used in time integration. The spline function is employed in space finite difference. There are two kinds of horizontal grid spacing: coarse mesh and fine mesh, the fine mesh can be moved with typhoon. Initial field comes from large scale forecast provided by national or regional meteorologycenter. The results show that this model is efficient, more accurate, and more economical. It is suitable for the use in operational forecasting.

12949
CSO: 4009/1028

AUTHOR: HAN Daokang* [7281 6670 1660]

ORG: Beijing Institute of Aeronautics and Astronautics

TITLE: "An Interpolating Spline Curve With Keeping Convexity"

SOURCE: Beijing SHUZHJ JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL METHODS AND COMPUTER APPLICATIONS] in Chinese Vol 6, No 2, Jun 85 pp 65-71

TEXT OF ENGLISH ABSTRACT: A type of cubic interpolating spline curves is constructed through joining each two successive points on the plane with three pieces of cubic uniform B-Spline curves. Its keeping convexity is similar to that of the cubic B-Spline curve when parameter λ is properly selected. Moreover, it has continuous derivative of second order and explicit form. (Paper received on 15 Sep 82)

*Now at the Institute No 304 of the Ministry of Astronautics Industry

References

- [1] W. J. Gordon, R. F. Riesenfeld, B-Spline Curves and Surface, CAGD 1974.
- [2] 苏步青, 刘鼎元, 计算几何, 上海科学技术出版社, 1981, 44-100.
- [3] 施法中, 北京航空学院硕士论文, 1981.
- [4] 国外航空编辑部, 计算机辅助几何设计, 北京, 1978. p 6.
- [5] 韩道康, 三次非均匀 B 样条的保凸性定理, 北京航空学院硕士论文, 1981.
- [6] 李岳生, 齐东旭, 样条函数方法, 科学出版社, 北京, 1979, 110-114.

12949

CSO: 4009/1084

AUTHOR: XU Chengxian [1776 2052 6343]

ORG: Xian Jiaotong University

TITLE: "A New Direct Search Algorithm With Decreasing Dimensions"

SOURCE: Beijing SHUZHJ JISUAN YU JISUANJI YINGYONG [JOURNAL ON NUMERICAL METHODS AND COMPUTER APPLICATIONS] in Chinese Vol 6, No 2, Jun 85 pp 98-105

TEXT OF ENGLISH ABSTRACT: A new direct search algorithm with successively decreasing dimensions of search spaces is presented to determine the optimal point of f on R^n , and its quadratic convergence is proved. The line search times needed in direct search algorithms are proved to be $1/2n(n+1)$'s. (Paper received on 6 Oct 82)

References

- [1] M. J. D. Powell, An efficient method for finding the minimum of a function of several variables without calculating derivatives. Computer J. Vol. 7, (1964), p. 155-162.
- [2] M. R. Hestenes, Optimization Theory, 1975.
- [3] D. M. 希梅尔布劳, 实用非线性规划张义桑等译, 科学出版社, 1981.

12949

CSO: 4009/1084

Optics

JPRS-CST-85-029
3 September 1985

AUTHOR: CHU Cheng [5969 2052]
HU Yu [5170 3558]

ORG: Shanghai Institute of Optics and Fine Mechanics, Academia Sinica

TITLE: "Design of a Diode of FEL"

SOURCE: Shanghai ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] in Chinese
Vol 12, No 6, 20 Jun 85 pp 330-334

TEXT OF ENGLISH ABSTRACT: The design method of a low emittance diode, the key component of a Raman-scattering FEL is presented. The space-charge-limited diode is immersed in a strong guiding magnetic field; the profile of its cathode can be evaluated numerically from the required e-beam parameters and anode profile.

12949
CSO: 4009/265

JPRS-CST-85-029
3 September 1985

AUTHOR: LIU Rongguang [0491 2837 0342]
WU Jianwu [0702 1017 2976]
XIE Peipei [6200 0160 0160]
DONG Xueseng [5516 7185 3932]

ORG: Institute of High Energy Physics, Chinese Academy of Sciences

TITLE: "The Performance Test of 1m x 1m Drift Chambers with On-line Microcomputer"

SOURCE: Beijing GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA NUCLEARIS] in Chinese Vol 9 No 3, May 85 pp 257-262

TEXT OF ENGLISH ABSTRACT: The performance of a 1m x 1m drift chamber system has been measured with an on-line microcomputer using cosmic rays. The time resolution is 4.26 ns, the spatial resolution is 132 μ m and the efficiency is above 96 percent. The experimental set-up includes five 1m x 1m adjustable field drift chambers, a scintillation counter trigger system, read-out electronics and a TRS-80 microcomputer. The data acquisition and processing have been performed with an on-line microcomputer and off-line data analysis.

AUTHOR: MA Jimao [7456 1015 5399]
WANG Yunyong [3769 6663 3057]
MAO Zepu [3029 3419 2528]
et al.

ORG: Institute of High Energy Physics, Chinese Academy of Sciences

TITLE: "Preliminary Test for Aging Effect of Drift Chambers"

SOURCE: Beijing GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA
NUCLEARIS] in Chinese Vol 9 No 3, May 85 pp 273-277

TEXT OF ENGLISH ABSTRACT: The degradation of some performances of the drift
chambers irradiated with a 5 MeV electron beam has been tested. The gas
mixtures filled were Ar/CO₂, Ar/CH₄ and Ar/iC₄H₁₀ in proportion.

The dark current, pulse height, energy resolution and counting rate plateau
were measured during the irradiation.

AUTHOR: LIU Yuan [0491 3220]
LI Yangguo [2621 2254 0948]

ORG: Institute of High Energy Physics, Chinese Academy of Sciences

TITLE: "Nucleus-Nucleus Inelastic Scattering and the Influence of
Projectile Nuclei Structure at High Energies"

SOURCE: Beijing GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA
NUCLEARIS] in Chinese Vol 9 No 3, May 85 pp 283-290

TEXT OF ENGLISH ABSTRACT: Based on Glauber's theory, nuclei-nuclei inelastic scattering amplitudes are given using the rigid projectile approximation. Inelastic scattering differential cross sections of $\alpha + C^{12}$ at 1.37 GeV with $2^+(4.43 \text{ MeV})$ and $3^-(9.64 \text{ MeV})$ of C^{12} in the final state are calculated. The influence of the different density distributions of the projectile nuclei on nuclei-nuclei inelastic scattering is discussed.

AUTHOR: LI Yangguo [2621 2254 0948]
MA Weixing [7456 4850 5281]

ORG: Institute of High Energy Physics, Chinese Academy of Sciences

TITLE: "S-Wave πN Interaction in (π^+, d) Reaction"

SOURCE: Beijing GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA NUCLEARIS] in Chinese Vol 9 No 3, May 85 pp 291-299

TEXT OF ENGLISH ABSTRACT: Based on the two nucleon pion absorption mechanism, the reaction (π^+, d) is studied. The formula for the differential cross section of the (π^+, d) reaction is obtained for S-wave πN interaction. A calculation is also performed for $^{12}\text{C}(\pi^+, d) ^{10}\text{C}(0^+, 2^+)$ at the incident energy of 49.3 MeV by using the plane wave approximation. The results indicate that the effect of the D-wave component in the deuteron wave function is quite important. The antisymmetric space structure of the neutron pair participating in the process is as important as the symmetric one.

AUTHOR: REN Wenbin [0117 2429 1755]
LI Guanglin [2621 1639 2651]
YAN Binshan [7346 2430 1472]

ORG: Institute of High Energy Physics, Chinese Academy of Sciences

TITLE: "Energy Doubler"

SOURCE: Beijing GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA NUCLEARIS] in Chinese Vol 9 No 3, May 85 pp 313-320

TEXT OF ENGLISH ABSTRACT: The energy doubler (ED) multiplication factor and the energy spectrum caused by the instantaneous beam loading compensated for by the inherent energy spectrum of ED in the electron Linac are derived under the linear variation condition for the top of the klystron output pulse.

AUTHOR: LIU Shaoxiang [0491 4801 3276]

ORG: Lanzhou University

TITLE: "Single Proton Transfer Reaction Induced by Heavy Ion ^{40}Ar (^{11}B , ^{10}Be) ^{41}K "

SOURCE: Beijing GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA NUCLEARIS] in Chinese Vol 9 No 3, May 85 pp 321-326

TEXT OF ENGLISH ABSTRACT: The angular distribution has been measured for elastic scattering on ^{40}Ar with ^{11}B and for the single proton transfer reaction $^{40}\text{Ar}({}^{11}\text{B}, {}^{10}\text{Be})^{41}\text{K}$ at the incident beam energy of 50 MeV. The elastic scattering cross section has been fitted in terms of the optical model. The EFR-DWBA approach with recoil effect has been used to analyze the differential cross section. The spectroscopic factor was extracted.

AUTHOR: SHEN Wenqing [3088 2429 1987]
YIN Shuzhi [1438 3219 5695]
GUO Zhongyan [6753 1813 6056]
JIANG Chenglie [1203 2110 3525]
et al.

ORG: SHEN, YIN, GUO, et al., of the Institute of Modern Physics, Chinese Academy of Sciences, Lanzhou; JIANG of the Institute of Atomic Energy, Chinese Academy of Sciences, Beijing

TITLE: "Measurement of Projectile-like Fragments Produced by 80.6 MeV ^{16}O on ^{27}Al "

SOURCE: Beijing GAONENG WULI YU HE WULI [PHYSICA ENERGIAE FORTIS ET PHYSICA NUCLEARIS] in Chinese Vol 9 No 3, May 85 pp 332-340

TEXT OF ENGLISH ABSTRACT: The projectile-like fragments produced by 80.6 MeV ^{16}O on ^{27}Al were measured using the large area position sensitive ionization chamber. The energy spectra, angular distributions, contour plots of $d^2\sigma/d\Omega E$ in the E - θ plane of the reaction products from Li to Na and the Z-distribution were obtained. The cross sections of the quasi and deep inelastic scattering were introduced. A brief discussion of the experimental results is also given.

9717

CSO: 4009/268

JPRS-CST-85-029
3 September 1985

AUTHOR: HU Gang [5170 1511]

ORG: Department of Physics, Beijing Normal University

TITLE: "Time Dependent Solution of Fokker-Planck Equation with Non-linear Drift Force"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5, May 85 pp 573-580

TEXT OF ENGLISH ABSTRACT: A new approach to the Ω -expansion of Green's function is employed to study the time dependent problem of the Fokker-Planck equation. The scaling region and final region in the scaling theory are unified to a single region. As $t \rightarrow \infty$, the time dependent solution approaches the stationary solution of the Fokker-Planck equation. The difficulty in matching the last two time regions in the scaling theory is then avoided.

AUTHOR: WANG Pengye [3769 7720 2814]
DAI Jianhua [2071 1696 5478]
ZHANG Hongjun [1728 3163 6874]

ORG: Institute of Physics, Chinese Academy of Sciences

TITLE: "Bifurcation, Chaos and Transient Behavior in Liquid Crystal Hybrid Optical Bistable Devices"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5,
May 85 pp 581-587

TEXT OF ENGLISH ABSTRACT: Bifurcation and chaotic behavior in liquid crystal hybrid optical bistable devices are calculated and analyzed based on the relaxation equation with time-delayed feedback. We also find that there is a transient oscillation with period t_R within the bistable region.

AUTHOR: HU Shuqin [5170 3219 3830]
LIAN Zhongxiang [6647 6988 4382]

ORG: Institute of Physics, Chinese Academy of Sciences

TITLE: "An Experiment of 90° Thomson Scattering on CT-6B Tokamak Device
by Using a Ruby Laser as Light Source"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5,
May 85 pp 594-602

TEXT OF ENGLISH ABSTRACT: In this paper we describe briefly the 90° Thomson scattering system of Tokamak CT-6B, using a ruby laser as the light source. The measurements of the 90° Thomson scattering spectra, electron temperature T_e and density n_e are discussed, and the results are given. The results of electron density measurement agree with those obtained by 2 mm microwave interferometer diagnosis.

AUTHOR: SU Fang [5685 2499]
YU Weizhong [6735 0251 0022]
DAI Daoyang [2071 6670 2254]
ZHAO Zongyuan [5392 1350 3293]

ORG: SU of the Fundamental Physics Center, University of Science and Technology of China, Hefei; YU of the Department of Physics, Qinghua University; DAI and ZHAO of the Institute of Physics, Chinese Academy of Sciences

TITLE: "Positron Lifetime Spectra and Scanning Electron Microscope Investigations During the Crystallization Process of Amorphous Ionic Conductor $B_2O_3-0.7Li_2O-0.7LiCl-xAl_2O_3$ "

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5, May 85 pp 622-627

TEXT OF ENGLISH ABSTRACT: The traditional pressed powder samples seriously spoil the accuracy and reproducibility in measuring positron lifetime spectra and scanning electron microscopy. This paper describes overcoming the above difficulties by preparing large amorphous disk samples and obtaining new results of positron lifetime spectra and scanning electron microscopy during the crystallization process.

According to our experiments on the amorphous ionic conductor $B_2O_3-0.7Li_2O-0.7LiCl-xAl_2O_3$, we find that the mean lifetime of a positron at room temperature is not affected by content variation of Al_2O_3 , with the mean lifetime of the positron decreasing greatly after full crystallization. Moreover, during the beginning of the crystallization process, the mean lifetime of the positron of the sample $x = 0.15$ exhibits a notable anomalous enhancement which occurs within the same temperature range as does the anomalous enhancement of ionic conductivity.

AUTHOR: TONG Litai [4547 5461 3141]
ZHOU Zengjun [0719 1073 0971]
WANG Guizhi [3769 2710 0037]

ORG: Department of Physics, Beijing University

TITLE: "Low Temperature Thermoelectric Power of Amorphous $(\text{Fe}_{1-x}\text{Cr}_x)_{84}\text{B}_{16}$ Alloys"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5,
May 85 pp 628-633

TEXT OF ENGLISH ABSTRACT: The absolute thermoelectric power S of amorphous metallic alloys $(\text{Fe}_{1-x}\text{Cr}_x)_{84}\text{B}_{16}$ has been measured as a function of temperature in the range of 80 to 380 K for $0.01 \leq x \leq 0.46$. It is found that the behavior of $S(T)$ for the magnetic alloys does not always follow a nonlinear variation law with a shallow minimum. The addition of a small amount of Cr ($x \leq 0.05$) is shown to lower the absolute value of S and wash out the minimum. With a larger Cr content, the alloys are weakly magnetic and the behavior of $S(T)$ changes from nonlinear, typical of magnetic amorphous alloys, to nearly linear, similar to that of nonmagnetic alloys. A value of x of 0.15 and 0.25 is not found to have any effect on the value of S at the Curie temperature T_C , which happened to be in our working temperature region.

AUTHOR: DING Xunmin [0002 6064 3046]
DONG Guosheng [5516 0948 0524]
YANG Shu [2799 2562]
et al.

ORG: Modern Physics Institute, Fudan University, Shanghai

TITLE: "An Electron Spectroscopy Study of the In/GaAs (111) Interface Formation Process"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5, May 85 pp 634-639

TEXT OF ENGLISH ABSTRACT: The interface formation process for In deposited on noncleaved GaAs (111) plane has been studied by means of photoemission spectroscopy combined with LEED pattern analysis. It is shown that the growth of three-dimensional In clusters dominates in this process. The surface Fermi level is found at 0.75 ± 0.05 eV above VBM for all the investigated n-type samples prior to the deposition of In: these include both Ga-terminated GaAs (111)-A and As-terminated GaAs (111)-B faces. The Fermi level rapidly shifts to 0.90 ± 0.05 eV above VBM during the deposition of In.

AUTHOR: ZHANG Yuheng [1728 5940 1854]
LIU Hongbao [0491 1347 1405]
YUAN Songliu [5913 2646 2692]
CAO Xiaowen [2580 2400 2429]

ORG: ZHANG, LIU and YUAN of the Department of Physics, University of Science and Technology of China, Hefei; CAO of the Institute of Plasma Physics, Chinese Academy of Sciences, Hefei

TITLE: "The Mechanism of Conductivity and the Superconducting Transition Anomalies in Metastable Intermediate Phase"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5, May 85 pp 640-651

TEXT OF ENGLISH ABSTRACT: The relationship between conductivity $\sigma(T_a)$ and temperature T has been investigated experimentally for samples with different structures under phase transition. We have found anomalous phenomena on superconducting transition $R(T)$ curves corresponding to some special phase transition zones as the samples crystallize into a metastable intermediate phase.

In this paper, a mixed state model is suggested in which the metastable metal-phase and the quasi-semiconducting phases are mixed. Based on this model, the anomalous phenomenon can be explained and the theoretical calculations carried out. The theory is in agreement with experimental data.

AUTHOR: CAO Zhongsheng [2580 1813 0524]
ZHAO Zhongxian [6392 1813 6343]
FENG Benzhen [7458 2609 2398]

ORG: CAO and ZHAO of the Institute of Physics, Chinese Academy of Sciences;
FENG of the Institute of Noble Metals, Kunming

TITLE: "Resistivity of Metallic Glass CuTi"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34 No 5,
May 85 pp 652-662

TEXT OF ENGLISH ABSTRACT: We choose the typical metallic glass $\text{Cu}_{1-x}\text{Ti}_x$ alloys with two concentrations ($x = 0.300$ and $x = 0.325$) made by a melt-spinning technique for the sample. The X-ray diffraction, DTA and DSC analyses show that the samples exhibit typical amorphous characteristics. In the wide temperature of 2-700 K, the resistivity is in accordance with the Mooij rule. Based on the Nagel nearly free electron model, Mott s-d scattering model, quasi-particles excitation by disorder configuration model and two-level tunnelling model for the electrical transport properties of amorphous alloys, the results are analyzed. The theoretical results of the two-level tunnelling model agree the best with the experimental data.

9717
CSO: 4009/273

Physics

JPRS-CST-85-029
3 September 1985

AUTHOR: CHEN Guicong [7115 2710 0654]
SHAN Qizhe [0830 0796 5832]

ORG: Department of Physics, Shandong College of Oceanography

TITLE: "Use of Multiple Exposure Synthetic Slit in Rainbow Holography of Diffuse 3-D Objects"

SOURCE: Shanghai ZHONGGUO JIGUANG [CHINESE JOURNAL OF LASERS] in Chinese
Vol 12, No 6, 20 Jun 85 pp 324-329

TEXT OF ENGLISH ABSTRACT: Extending the synthetic slit method in rainbow holography of diffuse 3-D objects ^{1,2}, a quasi-monochromatic reconstructed image is obtained by means of multiple exposure under white light illumination. A theory of multiple exposure synthetic slit is described and the effects of exposure times and object displacement for synthetic slit are discussed. Experimental results are also included.

12949

CSO: 4009/265

AUTHOR: ZHUANG Jiejia [1413 2638 0163]
ZHAO Runqiao [6392 3387 0829]
YE Guimu [0673 2710 2606]
et al.

ORG: ZHUANG of the Institute of High Energy Physics, Academia Sinica; ZHAO and YE of the Institute of Electronics, Academia Sinica

TITLE: "Theoretical Analysis and Experimental Demonstration of the Radially Polarized Laser Field"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 6, Jun 85 pp 752-759

TEXT OF ENGLISH ABSTRACT: The phase-adjusted focusing laser accelerator requires a laser field with special polarized distribution---a radial polarization. The theoretical work shows, by properly transforming the TEM00 mode, such a laser field can be obtained and propagate stably in the free space. The experimental result agrees with the theoretical analysis.

12949
CSO: 4009/284

Physics

AUTHOR: YAN Shousheng [7051 1343 0524]
GAO Liming [7559 0448 2494]
WAN Junzuo [8001 0689 0146]
et al.

ORG: Department of Physics, Beijing University

TITLE: "Anomalous Behavior of the Low Temperature Phonon Conductivity of an FeMnAl Alloy"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 6, Jun 85 pp 809-812

TEXT OF ENGLISH ABSTRACT: Measurements have been made at 4.2--30 K for the thermal conductivity of a polycrystalline Fe-25Mn-5Al-0.2C sample with negative temperature coefficient of resistivity. It is found that the phonon conductivity is anomalously proportional to T . The suggested explanation is that this phenomenon results from the noneffectiveness of the scattering of phonons by electrons, when electrons have short mean free path caused by the addition of Al.

12949
CSO: 4009/284

Physics

AUTHOR: FAN Yongnian [2868 3057 1628]

ORG: Institute of Metal Research, Academia Sinica

TITLE: "The Ordered Structure Formed on Mo (001) and Mo (110) Surfaces by Bombardment of Nitrogen Ions"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 6, Jun 85 pp 813-819

TEXT OF ENGLISH ABSTRACT:

After bombarding the Mo(001) and Mo(110) surfaces contained trace amount of carbon and oxygen with nitrogen ions of the energy of 1 keV and the beam current of 6 μ A for 10—15 min, a very strong Auger peak of nitrogen appeared in AES.

The LEED observation showed that surface structure was disordered from room temperature to 350°C annealing. When the sample was heated to the temperature range 530—650°C, three types of LEED pattern, i. e., $c(2 \times 2)$ -N, $p(2 \times 2)$ -N and $(4\sqrt{2} \times \sqrt{2}) R45^\circ$ -N, O formed on Mo(001). In the case of Mo (110) only one type LEED pattern of $c(7 \times 3)$ -N was observed.

The fact that the LEED structure of the surface is related to thermal desorption indicates that ordered structure depends on coverage of nitrogen and temperature and provides some information about phase transformation on the surface.

12949

CSO: 4009/284

AUTHOR: YANG Yuan [2799 0626]
YU Wenhai [0205 2429 3189]

ORG: Department of Physics, University of Science and Technology of China,
Hefei

TITLE: "Study of the Conducting Behavior of an Amorphous Li^+ Conductor in the Isothermal Treatment Process"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 7,
Jul 85 pp 925-932

TEXT OF ENGLISH ABSTRACT: The conducting behavior of an amorphous Li^+ conductor $\text{B}_2\text{O}_3\text{-}0.7\text{Li}_2\text{O-}0.7\text{LiCl-}0.1\text{Al}_2\text{O}_3$ has been measured continuously and automatically by using the a.c. Volt-Ampere method in the isothermal treatment process at a certain temperature below its transition temperature. It was found that the conductivities of the specimens increased at the initial stage and decreased monotonically after passing a maximum point, and then two flat steps appeared. Comparing these results with that obtained by DSC and XRD analysis, we confirmed that the presence of the maximum point of the conductivities is principally due to the amorphous phase separation, and the flat steps on the diagram of the conductivities are due to the amorphous crystallization. These results were discussed preliminarily in the view of the interface effects between different phases.

12949
CSO: 4009/285

Physics

AUTHOR: XU Yongnian [1776 3057 1628]
XU Jianhua [1776 1696 5478]
XIE Leiming [6200 7191 7686]

ORG: XU of the Institute of Modern Physics, Fudan University; XU and XIE of the Shanghai Institute of Metallurgy, Academia Sinica

TITLE: "Band Structure of CoSi_2 "

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 7, Jul 85 pp 860-865

TEXT OF ENGLISH ABSTRACT: The band structure and the density of states of CoSi_2 were calculated by means of the self-consistent LMTO method. The peak positions of the calculated DOS were in reasonable agreement with the corresponding peak positions of the synchrotron radiation photoemission studies. Our calculated results showed that the main characteristic of the electronic structure of the silicides CoSi_2 and NiSi_2 were dominated by the hybridization between the transition metal-3d orbitals and the silicon-3d orbitals. The bonding in CoSi_2 and NiSi_2 was different from that of bulk Si, where the bonding was due to the sp^3 hybridization of Si atom orbitals.

12949

CSO: 4009/285

Physics

AUTHOR: GU Biao [7357 1753]

ORG: Southwestern Institute of Physics, Leshan, Sichuan, China

TITLE: "Suppression of Cold Plasma Wavebreaking by Random Frequency Modulation"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 7, Jul 85 pp 873-881

TEXT OF ENGLISH ABSTRACT: In this paper, the Kubo-Anderson process has been adopted to describe the random frequency modulation of a driven field. Its suppression effect on inhomogeneous cold plasma wavebreaking has been analyzed. The expressions of wavebreaking time, fast electron energy and the average square of maximum localized electric field have been derived, which can be applied in any band width of the frequency modulation while the Bogoliubov's nonlinear frequency shift is not taken into account. The agreement between the theoretical predictions and the experimental results is fair. Thus we show that the random frequency modulation is an effective method to suppress the wavebreaking and fast electron energy.

12949

CSO: 4009/285

Physics

AUTHOR: ZHANG Yufeng [1728 3768 5762]
WENG Shifu [5040 6108 3940]
MENG Xiangti [1322 4382 2251]
et al.

ORG: ZHANG of the Department of Physics, Beijing University; WENG of the Department of Chemistry, Beijing University; MENG of the Institute of Energy Technique, Xinhua University

TITLE: "Infrared Absorption of Neutron-Irradiated FZ-Si Grown in Hydrogen Atmosphere"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 7, Jul 85 pp 849-859

TEXT OF ENGLISH ABSTRACT: Infrared absorption spectra of neutron irradiated FZ-Si grown in hydrogen atmosphere have been measured in wave-number ranges 1800-2300 cm^{-1} and 400-1200 cm^{-1} by FTIR. The annealing behavior of stronger absorption bands has been shown. By comparing with spectral results of proton implanted silicon measured by IR and neutron irradiated FZ-Si grown in hydrogen atmosphere measured by DLTS, the possible constructions of H-related centers are discussed.

12949
CSO: 4009/285

Physics

AUTHOR: PU Huanshun [3450 3562 7311]
ZHONG Yuanyuan [6988 0337 0377]
JIANG Jianhua [5592 1696 5478]
et al.

ORG: Institute of High Energy Physics, Academia Sinica

TITLE: "Preliminary Experimental Results of the β -Particle Detection with Superconducting Tunnel Junction Using D. C. Josephson Effect"

SOURCE: Beijing WULI XUEBAO [ACTA PHYSICA SINICA] in Chinese Vol 34, No 7, Jul 85 pp 941-945

TEXT OF ENGLISH ABSTRACT: The detection of nuclear particles with superconducting tunnel junctions using the D.C. Josephson effect is expected to have the merits of good energy resolution and fast time response. It was the first time that such an experiment to detect Sr90-Y90 β -particles by the Nb-NbO_x-Pb superconducting tunnel junctions has been performed. The results showed that, under the β -particles irradiation, not only the critical current and energy gap voltage of the superconducting tunnel junctions increased, but the voltage pulse signals at both ends of the superconducting tunnel junctions were produced as well. In this paper some phenomena observed on β -particle detection with superconducting tunnel junctions using the D.C. Josephson effect are discussed.

12949
CSO: 4009/285

JPRS-CST-85-029
3 September 1985

AUTHOR: LI Deping [2621 1795 1627]
CHEN Mingjun [7115 2494 3537]

ORG: Institute for Radiation Protection, Ministry of Nuclear Industry

TITLE: "Safety Considerations in Design and Operation of Installations
Using Sealed Sources"

SOURCE: Taiyuan FUSHE FANGHU [RADIATION PROTECTION] in Chinese Vol 5 No 3,
1985 pp 161-168

TEXT OF ENGLISH ABSTRACT: In the development and application of nuclear technology, it is necessary to pay sufficient attention to radiation safety to prevent radiation accidents. In this article some principles and measures which are important for the design and operation of installations with sealed sources are discussed in detail. The design of safety features and the quality of sources are strongly emphasized.

AUTHOR: XIA Yihua [1115 4135 5478]
LIU Yulian [0491 3768 5571]
JIN Ronghua [6855 2837 5478]
et al.

ORG: Institute of Atomic Energy

TITLE: "Development of a Large Area Alpha Gridded Ionization Chamber"

SOURCE: Taiyuan FUSHE FANGHU [RADIATION PROTECTION] in Chinese Vol 5 No 3,
1985 pp 176-183, 195

TEXT OF ENGLISH ABSTRACT: A gridded ionization chamber with low background and large area (1500 cm²) has been developed. It is filled with P₁₀ gas of 1.8 atmospheres, and the capacity between its collector and ground is 20pF. Contributions from several main factors to spectrum width are: electronic noise--20 keV; ionization straggling--16 keV; grid inefficiency factor--11.3 keV; electron collection time variation--3.5 keV; self-absorption of source thickness--30 keV. The sum is approximately 41.2 keV.

The background is about 6.1 cph (4-6 MeV) and 0.1 cph (over spectral line width of 50 keV at 5 MeV). A newly developed zirconium oxide pump was used to clear negatively charged gases. Therefore, long-term stable work is ensured. The minimum detectable activity is 10⁻¹⁴ - 10⁻¹⁵ Ci.

AUTHOR: ZHAO Yamin [6392 0068 3046]
ZHOU Hongjie [0719 3163 2638]
ZHAO Guanghui [6392 0342 6540]

ORG: Institute for Application of Atomic Energy, Chinese Academy of
Agriculture Sciences

TITLE: "Monitoring and Protection of Contamination Caused by Tritium Targets
Used for Accelerator"

SOURCE: Taiyuan FUSHE FANGHU [RADIATION PROTECTION] in Chinese Vol 5 No 3,
1985 pp 219-223

TEXT OF ENGLISH ABSTRACT: The surface and air contamination by tritium
targets used for an accelerator and the release rate of tritium from the
target into the air have been determined. Experimental results show that
contamination at the area near the tritium target is very serious. However,
the contamination caused by tritium targets may be greatly reduced if the
targets are stored in a vacuum desiccator.

9717
CSO: 4009/278

JPRS-CST-85-029
3 September 1985

AUTHOR: WANG Shouwu [3769 1343 2976]
XIA Yongwei [1115 3057 0251]
KONG Lingkun [1313 0109 0981]
et al.

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "Thin Bulk Effects in SOI Structure"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS] in
Chinese Vol 6 No 3, May 85 pp 225-235

TEXT OF ENGLISH ABSTRACT: The potential and carrier distribution in different parts of an SOI [silicon on insulator] structure are studied by using computer simulation. The results show that thin bulk effects occur in the SOI structure with uniformly doped P-type recrystallization silicon film when the thickness of the film is less than the maximum thickness of the depletion layer. The higher the threshold voltage the thicker the recrystallization film when the thickness of the inner dioxide is constant, whereas the lower the threshold voltage the thicker the inner dioxide when the film thickness is constant. The threshold voltage decreases as the inner dioxide thickness increases and finally becomes a constant value not dependent on the thickness of inner dioxide. The interface states with positive charges in the SOI structure further decrease the threshold voltage. Simulation analysis shows that the principle design rule to prevent thin bulk effects in an SOI structure is to make the thickness of the recrystallization film exceed the maximum thickness of the depletion layer, and to use low doping density silicon films and thick inner dioxide so as to decrease the influence of thin bulk effects when the film thickness is less than the maximum thickness of the depletion layer. The simulation presupposes that it is possible to develop new MOS thin film transistors with crystal silicon substrate and lower threshold voltage. The simulation shows that the expression of threshold voltage for the SOI structure, using depletion approximation, is very simple and more accurate.

AUTHOR: GAO Jilin [7559 1323 2651]
WU Ronghan [0702 2837 3352]
LI Zhaoyin [2621 3564 6892]
et al.

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "Deep Levels in (Ga, Al)As/GaAs and GaInAsP/InP Lasers"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 245-249

TEXT OF ENGLISH ABSTRACT: By using Deep Level Transient Spectroscopy (DLTS), the deep levels in (Ga, Al)As/GaAs and GaInAsP/InP lasers with broad and proton-bombarded stripe contacts have been detected. The laser wafers with four layers are grown by the LPE technique. A preliminary discussion is given of the laser degradation caused by these deep levels.

AUTHOR: CHEN Keming [7115 0344 6900]
QIU Lanhua [0092 5695 5478]
WANG Sen [3769 2773]
CHEN Weide [7115 4850 1795]

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "Effects of Chemical Compositional Deviation with Respect to n-GaAs Surface on Performances of Schottky Barrier Diodes"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 257-267

TEXT OF ENGLISH ABSTRACT: AES analysis is used to investigate the chemical compositional differences on the n-GaAs surface caused by different chemicals and C-V, I-V and G-V measurements are made on the main physical parameters of the Ni/n-GaAs Schottky diode formed by electroplating on n-GaAs surfaces with different chemical compositions and also made on interface state density and captured cross sections. Experimental results show that the chemical compositions on the n-GaAs surface have a direct influence on the height of the Schottky barrier, the interface gradient, the ideal factor, the saturated current density and carrier concentration profile in the neighborhood of the junction, etc. The optimum etching conditions are gained and a nearly ideal Schottky junction is obtained. In addition, it has been found that there are two kinds of interface states in the Ni/n-GaAs interface: one has a low interface state density, a larger capture cross section and a lower time constant, and the other has a high interface state density, a small captured cross section and a higher time constant. These are related to the performance of the Schottky barrier or Fermi-level pinning at the interface. However, the position of Fermi-level pinning at the interface of the above-mentioned three different Ni/n-GaAs is nearly the same as that in the bandgap.

AUTHOR: LI Yungang [2621 0061 1511]
LIN Yu [2651 7183]

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "Research on Microprocessor Test Pattern Generation"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 258-274

TEXT OF ENGLISH ABSTRACT: A new method of composing a microprocessor test program, the T-classifying method, is proposed. This method has been used for composing the 8080 μ P test program, of which parts have been tested. Compared with instruction function classifying, this method can save 78.5 percent of the content of the pattern memory, has better adaptability and analyzes faults more easily.

Semi-automatic pattern generation on the MDR-Z80 microcomputer by establishment of the standard pattern element storeroom has been realized. The feasibility of fully automatic pattern generation is discussed.

AUTHOR: ZHENG Yiyang [6774 0001 7122]

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "Stationary Domain Originating from Cathode Deep Recess Doping Distribution in GaAs Transferred Electron Devices"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS] in Chinese Vol 6 No 3, May 85 pp 281-288

TEXT OF ENGLISH ABSTRACT: The effect of different cathode deep recess doping distributions in GaAs transferred electron devices on the domain state is discussed. It is pointed out that stationary domain is formed when the cathode recess doping distribution is rather deep. The growth and features of this kind of stationary domain are discussed.

AUTHOR: WANG Shouwu [3769 1343 2976]
WANG Zhongming [3769 0112 2494]

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "On the Rate Equation of the Photon Density in Semiconductor Lasers"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 304-306

TEXT OF ENGLISH ABSTRACT: The rate equation of the photon density in semiconductor lasers usually does not include the coherent enhancement effect of the Fabry-Perot resonator. This coherent enhancement effect has been considered and a modified rate equation is obtained which is a nonlinear differential equation of photon density. When the photon density in the cavity is very low, the modified rate equation is essentially the same as usual; when the photon density in the cavity is rather high, the modification is not negligible.

AUTHOR: PAN Shihong [3382 1102 1347]
Nathan Newman
T. Kendelewicz
W.G. Petro

ORG: PAN of the Department of Physics, Nankai University; Newman,
Kendelewicz and Petro of Stanford Electronics Laboratories, Stanford
University

TITLE: "Determination of the Interfacial Fermi Level Position for Noble
Metals on GaAs (110)"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 307-310

TEXT OF ENGLISH ABSTRACT: The I-V method has been used to measure the barrier height of Schottky diodes for Cu, Ag and Au on GaAs (110) cleaved surfaces prepared in an ultrahigh vacuum, and soft X-ray photoelectron spectroscopy with synchrotron radiation has been carried out to determine the interfacial Fermi level position at the Cu-n-GaAs (110) interface. The results obtained by both methods are quite consistent. The interfacial Fermi level position for noble metals on n-type GaAs (110) is located at 0.9 ± 0.05 eV below the conduction band minimum, corresponding to the same value of the Schottky barrier height and to the donor level defined by the defect model.

AUTHOR: PENG Shaojin [1756 1421 6602]
LU Wenhong [4151 2429 1347]
ZHENG Guoxian [6774 0948 2009]

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "A Control Technology of Compositional Repeatability for the Growth of $\text{In}_{1-x}\text{Ga}_x\text{As}$ Epilayers by LPE"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 311-316

TEXT OF ENGLISH ABSTRACT: $\text{In}_{1-x}\text{Ga}_x\text{As}$ ($x \approx 0.47$) epilayers grown by LPE with gradual deduction in the starting growth temperature T_g have been investigated by use of Electron Probe Micro Zone Analysis and Cathodoluminescence. The results show that with this method the growth solution can be used many times repeatedly.

AUTHOR: WU Zhongchi [0702 0112 1062]
ZHAO Youyuan [6392 2589 3293]
GAO Rufang [7559 1172 5364]
et al.

ORG: Fudan University

TITLE: "Correlation Between Optical Absorption Coefficient at 10.6 μm and the Resistivity of Crystalline Silicon"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 317-319

TEXT OF ENGLISH ABSTRACT: The correlation between the optical absorption coefficient at a wavelength of 10.6 μm and the corresponding electrical resistivity of single crystalline silicon is determined experimentally. The resulting calibration curves are considered to be applicable in the contactless and non-destructive characterization of silicon wafers for resistivity less than 1 $\Omega\text{-cm}$ and its radial profiles. The influence of surface roughness and high oxygen and carbon contents on the absorption-resistivity relationship has been observed and discussed.

AUTHOR: PAN Ji [3382 1213]
QI Jianhua [7871 1696 5478]
ZHAO Honglin [6392 7703 7792]
et al.

ORG: Department of Electronical Engineering, Tianjin University

TITLE: "Correlation of Ar⁺ Gettering Efficiency with Doses"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 320-322

TEXT OF ENGLISH ABSTRACT: The removal of heavy metallic elements from the active region of a silicon wafer has been studied through the implantation of high energy Ar⁺ into the backside of the wafer. The measurement of the gettering effect is based on the measurements of the minority carrier's lifetime. The experimental results show that the optimized doses are about $7.5 \times 10^{14} \text{ cm}^{-2}$ and $7.5 \times 10^{15} \text{ cm}^{-2}$. Finally, the relationship between gettering efficiency and residual defect density is mentioned.

AUTHOR: ZHANG Fangqing [1728 0119 3237]
ZHANG Nanping [1728 0589 1456]
YU Guangming [0151 0342 2494]
et al.

ORG: Lanzhou University

TITLE: "Effect of High Temperature Annealing on Crystallized Characteristics of GD $a\text{-Si}_x\text{C}_{1-x}\text{:H}$ Films"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 323-325

TEXT OF ENGLISH ABSTRACT: Experimental results show that when the annealing temperature is $\sim 550^\circ\text{C}$, the crystallization of $a\text{-Si}_x\text{C}_{1-x}\text{:H}$ is initiated and the size of the grain and crystallized region increases with the rise of the annealing temperature. The absorption coefficient, band gap and activation energy of these crystallized $a\text{-Si}_x\text{C}_{1-x}\text{:H}$ films decrease while the dark conductivity increases.

AUTHOR: LU Huiyun [0712 1920 0061]
WU Jinhua [2976 6930 5478]
YIN Enhua [1438 1869 5478]
et al.

ORG: Institute of Semiconductors, Chinese Academy of Sciences

TITLE: "Determination of Hydrogen Content in a-Si Film by Gas Chromatographic Method"

SOURCE: Beijing BANDAOTI XUEBAO [CHINESE JOURNAL OF SEMICONDUCTORS]
in Chinese Vol 6 No 3, May 85 pp 326-328

TEXT OF ENGLISH ABSTRACT: For the first time, the total hydrogen content in an amorphous Si film and the hydrogen effusion rate from it at different temperatures are determined by gas chromatographic technology. This method is found to be more reliable than the pressure measurement adopted in the hydrogen effusion experiment.

9717

CSO: 4009/1050

END